

To our customers,

Old Company Name in Catalogs and Other Documents

On April 1st, 2010, NEC Electronics Corporation merged with Renesas Technology Corporation, and Renesas Electronics Corporation took over all the business of both companies. Therefore, although the old company name remains in this document, it is a valid Renesas Electronics document. We appreciate your understanding.

Renesas Electronics website: <http://www.renesas.com>

April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (<http://www.renesas.com>)

Send any inquiries to <http://www.renesas.com/inquiry>.

Notice

1. All information included in this document is current as of the date this document is issued. Such information, however, is subject to change without any prior notice. Before purchasing or using any Renesas Electronics products listed herein, please confirm the latest product information with a Renesas Electronics sales office. Also, please pay regular and careful attention to additional and different information to be disclosed by Renesas Electronics such as that disclosed through our website.
2. Renesas Electronics does not assume any liability for infringement of patents, copyrights, or other intellectual property rights of third parties by or arising from the use of Renesas Electronics products or technical information described in this document. No license, express, implied or otherwise, is granted hereby under any patents, copyrights or other intellectual property rights of Renesas Electronics or others.
3. You should not alter, modify, copy, or otherwise misappropriate any Renesas Electronics product, whether in whole or in part.
4. Descriptions of circuits, software and other related information in this document are provided only to illustrate the operation of semiconductor products and application examples. You are fully responsible for the incorporation of these circuits, software, and information in the design of your equipment. Renesas Electronics assumes no responsibility for any losses incurred by you or third parties arising from the use of these circuits, software, or information.
5. When exporting the products or technology described in this document, you should comply with the applicable export control laws and regulations and follow the procedures required by such laws and regulations. You should not use Renesas Electronics products or the technology described in this document for any purpose relating to military applications or use by the military, including but not limited to the development of weapons of mass destruction. Renesas Electronics products and technology may not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any applicable domestic or foreign laws or regulations.
6. Renesas Electronics has used reasonable care in preparing the information included in this document, but Renesas Electronics does not warrant that such information is error free. Renesas Electronics assumes no liability whatsoever for any damages incurred by you resulting from errors in or omissions from the information included herein.
7. Renesas Electronics products are classified according to the following three quality grades: “Standard”, “High Quality”, and “Specific”. The recommended applications for each Renesas Electronics product depends on the product’s quality grade, as indicated below. You must check the quality grade of each Renesas Electronics product before using it in a particular application. You may not use any Renesas Electronics product for any application categorized as “Specific” without the prior written consent of Renesas Electronics. Further, you may not use any Renesas Electronics product for any application for which it is not intended without the prior written consent of Renesas Electronics. Renesas Electronics shall not be in any way liable for any damages or losses incurred by you or third parties arising from the use of any Renesas Electronics product for an application categorized as “Specific” or for which the product is not intended where you have failed to obtain the prior written consent of Renesas Electronics. The quality grade of each Renesas Electronics product is “Standard” unless otherwise expressly specified in a Renesas Electronics data sheets or data books, etc.
 - “Standard”: Computers; office equipment; communications equipment; test and measurement equipment; audio and visual equipment; home electronic appliances; machine tools; personal electronic equipment; and industrial robots.
 - “High Quality”: Transportation equipment (automobiles, trains, ships, etc.); traffic control systems; anti-disaster systems; anti-crime systems; safety equipment; and medical equipment not specifically designed for life support.
 - “Specific”: Aircraft; aerospace equipment; submersible repeaters; nuclear reactor control systems; medical equipment or systems for life support (e.g. artificial life support devices or systems), surgical implantations, or healthcare intervention (e.g. excision, etc.), and any other applications or purposes that pose a direct threat to human life.
8. You should use the Renesas Electronics products described in this document within the range specified by Renesas Electronics, especially with respect to the maximum rating, operating supply voltage range, movement power voltage range, heat radiation characteristics, installation and other product characteristics. Renesas Electronics shall have no liability for malfunctions or damages arising out of the use of Renesas Electronics products beyond such specified ranges.
9. Although Renesas Electronics endeavors to improve the quality and reliability of its products, semiconductor products have specific characteristics such as the occurrence of failure at a certain rate and malfunctions under certain use conditions. Further, Renesas Electronics products are not subject to radiation resistance design. Please be sure to implement safety measures to guard them against the possibility of physical injury, and injury or damage caused by fire in the event of the failure of a Renesas Electronics product, such as safety design for hardware and software including but not limited to redundancy, fire control and malfunction prevention, appropriate treatment for aging degradation or any other appropriate measures. Because the evaluation of microcomputer software alone is very difficult, please evaluate the safety of the final products or system manufactured by you.
10. Please contact a Renesas Electronics sales office for details as to environmental matters such as the environmental compatibility of each Renesas Electronics product. Please use Renesas Electronics products in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive. Renesas Electronics assumes no liability for damages or losses occurring as a result of your noncompliance with applicable laws and regulations.
11. This document may not be reproduced or duplicated, in any form, in whole or in part, without prior written consent of Renesas Electronics.
12. Please contact a Renesas Electronics sales office if you have any questions regarding the information contained in this document or Renesas Electronics products, or if you have any other inquiries.

(Note 1) “Renesas Electronics” as used in this document means Renesas Electronics Corporation and also includes its majority-owned subsidiaries.

(Note 2) “Renesas Electronics product(s)” means any product developed or manufactured by or for Renesas Electronics.

Phase-out/Discontinued

V25™

16/8-BIT SINGLE-CHIP MICROCONTROLLER

The μPD70320 (V25) is a single-chip microcontroller on which 16-bit CPU, RAM, serial interface, timer, DMA controller, interrupt controller, etc. are all integrated. The μPD70320 is compatible with the 8/16-bit microprocessor μPD70108/70116 (V20™/V30™) on the software level.

The details of the functions are described in the following User's Manuals. Be sure to read it before starting design.

- V25, V35™ User's Manual — Hardware : IEM-1220
- V25, V35 Family User's Manual — Instructions : U12120J (Japanese version)

FEATURES

- Internal 16-bit architecture and external 8-bit data bus
- Compatible with μPD70108/70116 (in native mode) on software level (some instructions added)
- Minimum instruction cycle : 400 ns/5 MHz (μPD70320)
250 ns/8 MHz (μPD70320-8)
- On-chip RAM : 256 words × 8 bits
- Input port (port T) with comparator : 8 bits
- I/O lines (input port : 4 bits, input/output port : 20 bits)
- Serial interface (internal dedicated baud rate generator) : 2 channels
Asynchronous mode and I/O interface mode
- Interrupt controller
 - Programmable priority (8 levels)
 - Vectored interrupt function
 - Register bank switching function
 - Macro service function
- DRAM and pseudo SRAM refreshing functions
- DMA controller : 2 channels
- 16-bit timer : 2 channels
- Time base counter
- On-chip clock generator
- Programmable wait function
- Standby function (STOP/HALT)

The information in this document is subject to change without notice.

★ ORDERING INFORMATION

Part Number	Package	Max. Operating Frequency (MHz)
μPD70320L	84-pin plastic QFJ (1150 × 1150 mils)	5
μPD70320L-8	84-pin plastic QFJ (1150 × 1150 mils)	8
μPD70320GJ-5BG	94-pin plastic QFP (20 × 20 mm)	5
μPD70320GJ-8-5BG	94-pin plastic QFP (20 × 20 mm)	8

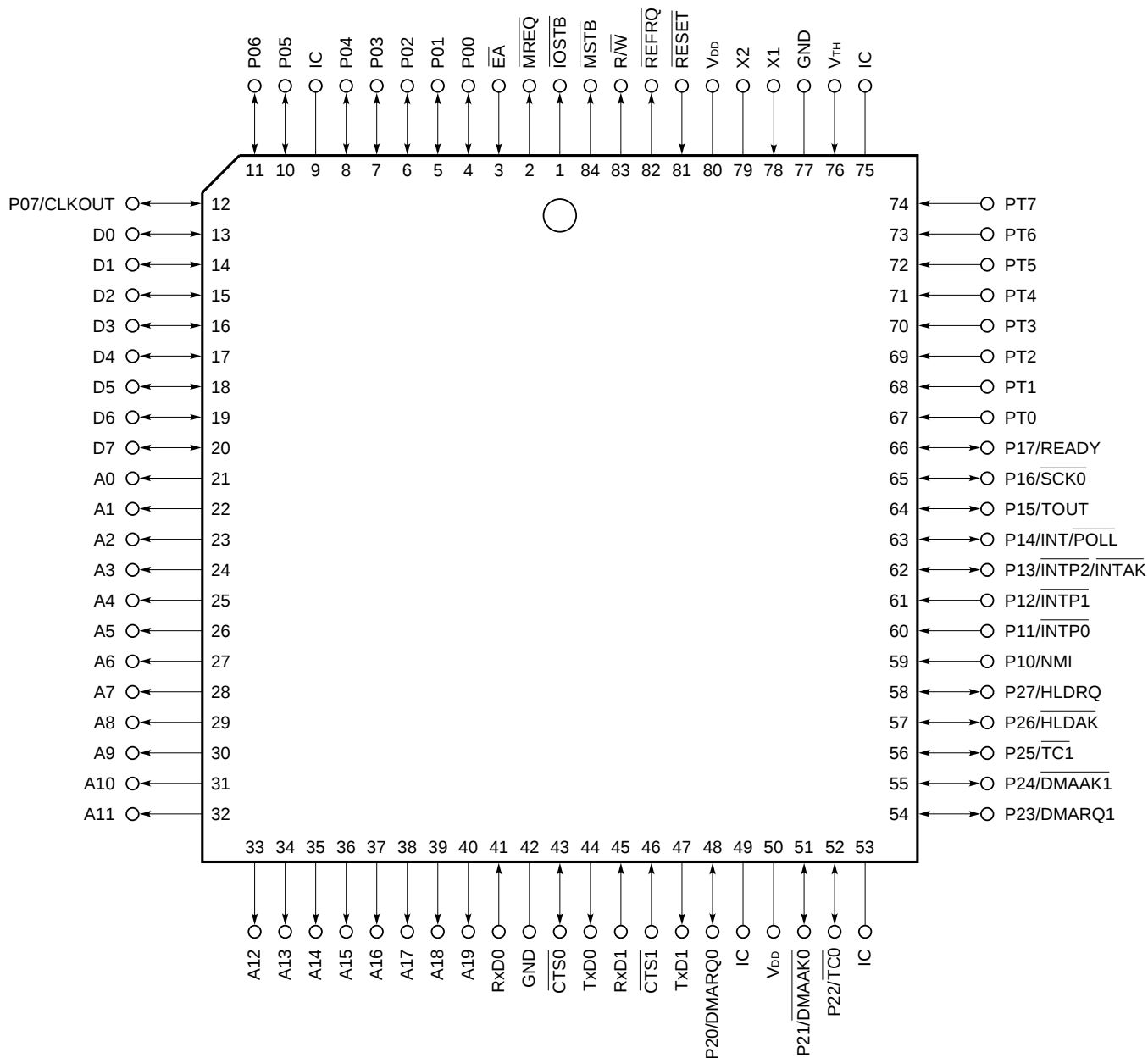
Remark The plastic QFJ is a new name of the PLCC.

PIN CONFIGURATION (Top View)

84-Pin Plastic QFJ (1150 × 1150 mils)

μPD70320L

μPD70320L-8



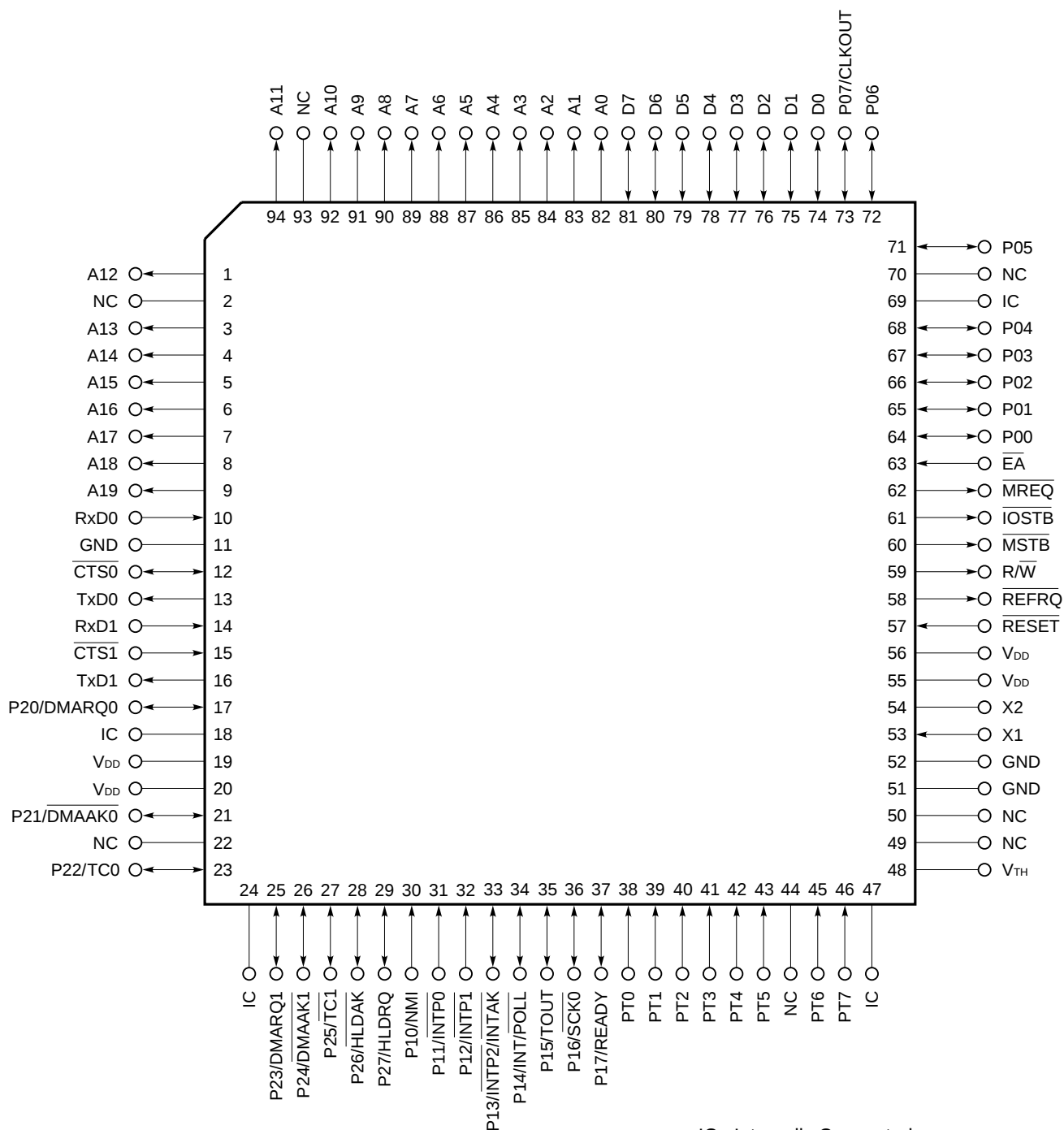
IC: Internally Connected

- Cautions**
1. Connect IC pin individually to VDD via a resistor (3 to 10 kΩ).
 2. Connect EA pin to GND via a resistor (3 to 10 kΩ).

★ 94-Pin Plastic QFP (20 × 20 mm)

μPD70320GJ-5BG

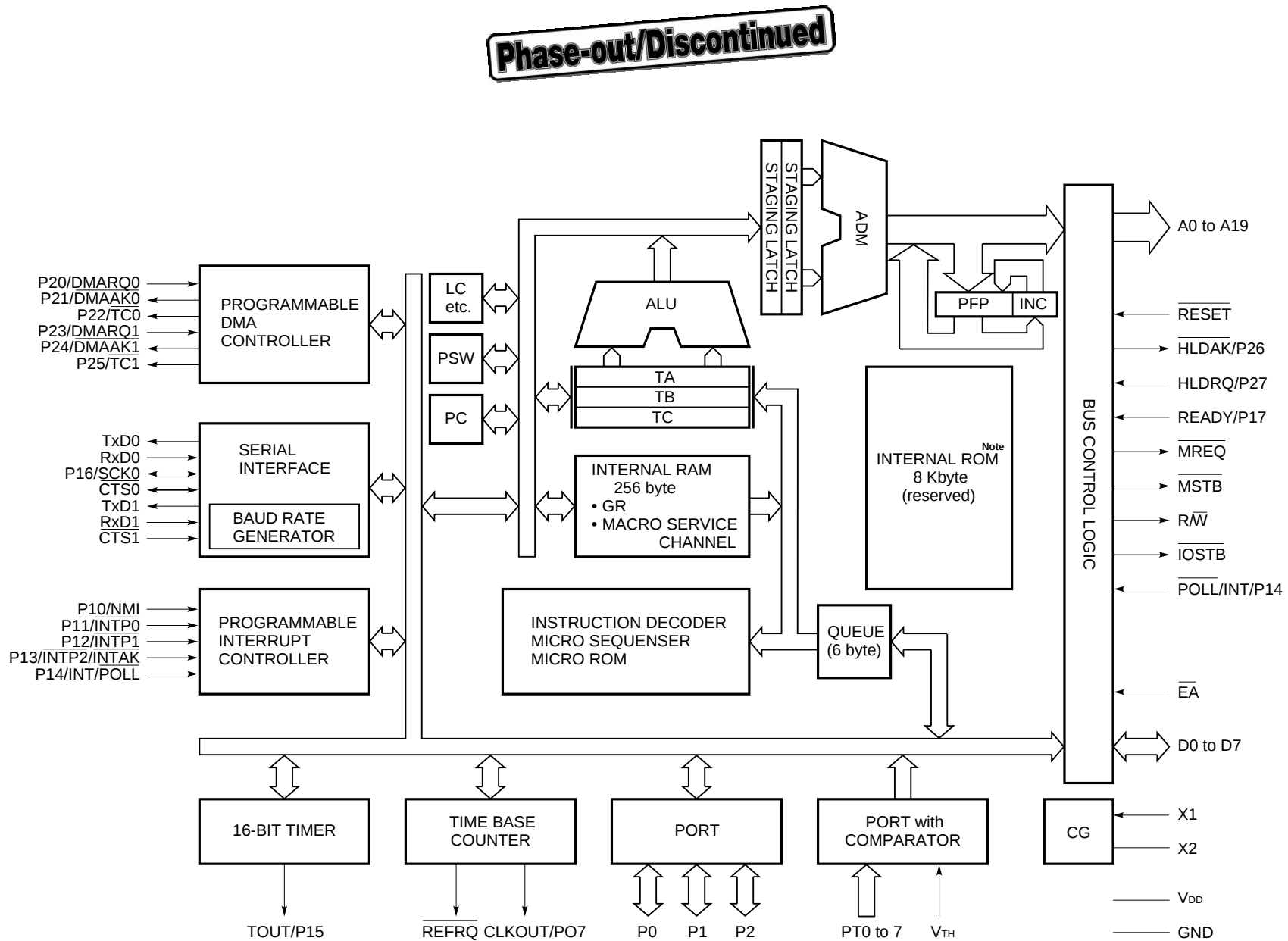
μPD70320GJ-8-5BG



IC: Internally Connected
NC: Non-Connection

- Cautions**
1. Connect IC pin individually to V_{DD} via a resistor (3 to 10 kΩ).
 2. Connect EA pin to GND via a resistor (3 to 10 kΩ).

INTERNAL BLOCK DIAGRAM



Note Not user-accessible.

CONTENTS

1. PIN FUNCTIONS 7

1.1 Port Pins 7

1.2 Non-port Pins 8

2. INSTRUCTION SETS 9

2.1 Instructions Added to μ PD70108/70116 9

2.2 Instruction Set Operation 11

2.3 Instruction Set Table 15

3. ELECTRICAL SPECIFICATIONS 47

4. CHARACTERISTIC CURVES 66

5. PACKAGE DRAWINGS 69

6. RECOMMENDED SOLDERING CONDITIONS 71

1. PIN FUNCTIONS

1.1 Port Pins

Pin Name	Input/Output	Port Function	Control Function
P00 to P06	Input & output	8-bit input/output ports, each to be specified bit-by-bit	—
P07/CLKOUT	Input & output/output		System clock output
P10/NMI	Input	Used as non-maskable interrupt request input (input port)	—
P11/ $\overline{\text{INTP0}}$		Used as both external interrupt request input and input port	
P12/ $\overline{\text{INTP1}}$			
P13/ $\overline{\text{INTP2}}/\overline{\text{INTAK}}$			
P14/ $\overline{\text{POLL}}/\overline{\text{INT}}$	Input & output/input/input	Used as both specifiable input/output port and POLL input	External interrupt request input
P15/TOUT	Input & output/output	Input/output port specifiable bit-by-bit	Timer output
P16/ $\overline{\text{SCK0}}$			Serial clock output
P17/READY			READY input
P20/DMARQ0	Input & output/input	8-bit input/output port specifiable bit-by-bit	DMA request input (CH0)
P21/ $\overline{\text{DMAAK0}}$	Input & output/output		DMA acknowledge output (CH0)
P22/ $\overline{\text{TC0}}$			DMA end output (CH0)
P23/DMARQ1	Input & output/input		DMA request input (CH1)
P24/ $\overline{\text{DMAAK1}}$	Input & output/output		DMA acknowledge output (CH1)
P25/ $\overline{\text{TC1}}$			DMA end output (CH1)
P26/ $\overline{\text{HLD}}\overline{\text{AK}}$	Input & output/output		HOLD acknowledge output
P27/ $\overline{\text{HLD}}\overline{\text{RQ}}$	Input & output/input		HOLD input
PT0 to PT7	Input	8-bit input port with comparator	—

Remark All port pins become input ports after reset is released.

When using P13/ $\overline{\text{INTP2}}/\overline{\text{INTAK}}$ as a $\overline{\text{INTAK}}$ pin, be sure to pull up the pin to avoid a malfunction of external interrupt controller after reset is released.

1.2 Non-port Pins

Pin Name	Input/Output	Function
TxD0	Output	Serial data output
TxD1		
RxD0	Input	Serial data input
RxD1		
CTS0	Input & output	CTS input in asynchronous mode, receive clock input/output in I/O interface mode
CTS1	Input	CTS input
REFRQ	Output	DRAM refresh pulse output
V _{TH}	Input	Comparator reference voltage input
RESET		Reset signal input
EA		External memory access (connect to GND via a resistor (3 to 10 kΩ))
X1	Input	Used to connect crystal resonator/ceramic resonator for oscillating system clock.
X2		External clock is entered by entering reverse phase clock to both X1 and X2 pins.
D0 to D7	Input & output	8-bit data bus
A0 to A19	Output	20-bit address output
MREQ		Output used to indicate that memory bus cycle has been started
MSTB		Memory read/memory write strobe output
R/W		Read cycle/write cycle ID signal output
IOSTB		I/O read/I/O write strobe output
V _{DD}		Positive power supply pins (all pins should be connected)
GND		GND pins (all pins should be connected)
IC		Internally connected (connect individually to V _{DD} via a resistor (3 to 10 kΩ))

2. INSTRUCTION SETS

The μPD70320 instruction sets are upward-compatible with those of μPD70108/70116 in native mode.

2.1 Instructions Added to μPD70108/70116

The following instructions are newly added to the μPD70108/70116.

(1) Conditional branch instruction

- BTCLR Bit test instruction used for special function registers

If, when this BTCLR is executed, the target special function register bit status is "1", the bit is reset (0) and the program is branched to short-label described in the operand. If the target bit status is "0", the program is moved to the next instruction. PSW is not changed in this instruction.

(Descriptive format)

Mnemonic	Operand		
	Special Function Register Address	Special Function Register Bit	Branch Address
BTCLR	sfr	imm3	short-label

(2) Interrupt instructions

- RETRBI Return instruction used for register banks

This instruction is used to return the program from the interrupt service routine in which the register bank switching function is used. It cannot be used for returning from vectored interrupt servicing.

(Descriptive format)

Mnemonic	Operand
RETRBI	None

- FINT This instruction is used to report the interrupt controller that interrupt servicing has ended. If an interrupt other than NMI, INT, and software interrupt is used, this instruction must be executed prior to the instruction for returning from interrupt servicing. It should not be used for NMI, INT and software interrupts.

(Descriptive format)

Mnemonic	Operand
FINT	None

(3) CPU instruction

- STOP Instruction for transition to STOP state

(Descriptive format)

Mnemonic	Operand
STOP	None

(4) Register bank switch instructions

- BRKCS Used to switch register banks

A register bank is switched to the register bank indicated by the lower 3 bits in the 16-bit register described in the operand. The program is also branched with this instruction to the address obtained from the PS stored in advance in the new register bank and the vector PC. The RETRBI instruction is used to return the program from the new register bank.

(Descriptive format)

Mnemonic	Operand
BRKCS	reg16

- TSKSW Used to switch register banks

Just like the BRKCS instruction, this instruction is also executed to select a register bank. The program is branched to the address obtained from the PS stored in advance in the new register bank and the address obtained from the PC save area.

(Descriptive format)

Mnemonic	Operand
TSKSW	reg16

(5) Data transfer instructions

- MOVSPA ... Used to transfer SS and SP values

This instruction is executed to transfer both SS and SP values before the register bank is switched to SS and SP of the current (post-switching) register bank.

(Descriptive format)

Mnemonic	Operand
MOVSPA	None

- MOVSPB ... Used to transfer SS and SP values

This instruction is executed to transfer the SS and SP values of the current (pre-switching) register bank to the SS and SP of the new register bank indicated by the lower 3 bits in the 16-bit register described in the operand.

(Descriptive format)

Mnemonic	Operand
MOVSPB	reg16

Some μPD70108/70116 instructions should be much cared as shown below when used for the μPD70320.

- I/O instruction, primitive I/O instruction

If PSW $\overline{\text{IBRK}}$ flag is reset (0), an interrupt is generated without executing this instruction. Be sure to set (1) the $\overline{\text{IBRK}}$ flag when using the I/O instruction.

- FPO instruction

An interrupt is generated without executing this instruction.

2.2 Instruction Set Operation

Table 2-1. Operand Identifier

Identifier	Description
reg	8-/16-bit general register
reg8	8-bit general register
reg16	16-bit general register
dmem	8-/16-bit memory location
mem	8-/16-bit memory location
mem8	8-bit memory location
mem16	16-bit memory location
mem32	32-bit memory location
sfr	8-bit special function register location
imm	Constant within 0 to FFFFH
imm3	Constant within 0 to 7
imm4	Constant within 0 to FH
imm8	Constant within 0 to FFH
imm16	Constant within 0 to FFFFH
acc	Register AW or AL
sreg	Segment register
src-table	256-byte conversion table name
src-block	Register IX-addressed block name
dst-block	Register IY-addressed block name
near-proc	Procedure in the current program segment
far-proc	Procedure in another program segment
near-label	Label in the current program segment
short-label	Label within end of instruction to -128 to +127 bytes
far-label	Label in another program segment
memptr16	Word including location offset in the current program segment to which control is to be passed
memptr32	Double-word including location offset in another program segment to which control is to be passed and segment base address
regptr16	16-bit general register including location offset in another program segment to which control is to be passed
pop-value	Number of bytes to be abandoned from stack (0 to 64K, normally even number)
fp-op	Immediate value to judge instruction code of external floating point operation chip
R	Register set

Table 2-2. Operation Code Identifier

Identifier	Description
W	Byte/word specification bit (0: byte, 1: word). However, when s = 1, the sign extended byte data should be 16-bit operand even when W is 1.
reg	Register field (000 to 111)
mem	Memory field (000 to 111)
mod	Mode field (00 to 10)
s	Sign extension specification bit (0: Sign is not extended, 1: Sign is extended)
X, XXX, YYY, ZZZ	Data used to judge instruction code of external floating-point operation chip

Table 2-3. Operation Identifier (1/2)

Identifier	Description
AW	Accumulator (16 bits)
AH	Accumulator (upper byte)
AL	Accumulator (lower byte)
BW	Register BW (16 bits)
CW	Register CW (16 bits)
CL	Register CW (lower byte)
DW	Register DW (16 bits)
SP	Stack pointer (16 bits)
PC	Program counter (16 bits)
PSW	Program status word (16 bits)
IX	Index register (source) (16 bits)
IY	Index register (destination) (16 bits)
PS	Program segment register (16 bits)
DS1	Data segment 1 register (16 bits)
DS0	Data segment 0 register (16 bits)
SS	Stack segment register (16 bits)
AC	Auxiliary carry flag
CY	Carry flag
P	Parity flag
S	Sign flag
Z	Zero flag
DIR	Direction flag
IE	Interrupt enable flag
V	Overflow flag
BRK	Break flag
MD	Mode flag
(...)	Contents in memory shown in ()
disp	Displacement (8/16 bits)
ext-disp8	16 bits obtained by extending sign of 8-bit displacement

Table 2-3. Operation Identifier (2/2)

Identifier	Description
temp	Temporary register (8/16/32 bits)
tmpcy	Temporary carry flag (1 bit)
seg	Immediate segment data (16 bits)
offset	Immediate offset data (16 bits)
←	Transfer direction
+	Addition
−	Subtraction
×	Multiplication
÷	Division
%	Modulo
^	AND
∨	OR
⊕	Exclusive OR
xxH	2-digit hexadecimal number
xxxxH	4-digit hexadecimal number

Table 2-4. Flag Operation Identifier

Identifier	Description
(Blank)	No change
0	Cleared to 0
1	Set to 1
×	Set or cleared according to the result
U	Not defined
R	The previously saved value is restored.

Table 2-5. 8/16-Bit General Register Selection

reg	W = 0	W = 1
000	AL	AW
001	CL	CW
010	DL	DW
011	BL	BW
100	AH	SP
101	CH	BP
110	DH	IX
111	BH	IY

Table 2-6. Segment Register Selection

sreg	
00	DS1
01	PS
10	SS
11	DS0

The number of clocks, for memory operand, differs among addressing modes. So, use the following values for “EA” items shown in **Table 2-8 Number of Clocks**.

Table 2-7. Number of Clocks for Each Memory Addressing

mod mem	00		01		10	
		Clocks		Clocks		Clocks
000	BW + IX	3	BW + IX + disp8	3	BW + IX + disp16	4
001	BW + IY	3	BW + IY + disp8	3	BW + IY + disp16	4
010	BP + IX	3	BP + IX + disp8	3	BP + IX + disp16	4
011	BP + IY	3	BP + IY + disp8	3	BP + IY + disp16	4
100	IX	3	IX + disp8	3	IX + disp16	4
101	IY	3	IY + disp8	3	IY + disp16	4
110	Direct address	3	BP + disp8	3	BP + disp16	4
111	BW	3	BW + disp8	3	BW + disp16	4

“T” indicates the number of wait states. Use any number of waits starting at “0” (no wait).

The instruction fetch cycle is not counted as the number of clocks.

There are some branch instructions for which such description as the example below is provided.

The description indicates as follows:

Example 15/8 ...15: the number of clock cycles when branched

8: the number of clock cycles when not branched

Phase-out/Discontinued

2.3 Instruction Set Table

Group	Mnemonic	Operand	Operation Code		Bytes	Operation	Flags					
			7 6 5 4 3 2 1 0	7 6 5 4 3 2 1 0			AC	CY	V	P	S	Z
Data transfer	MOV	reg,reg	1 0 0 0 1 0 1 W	1 1 reg reg	2	reg ← reg						
		mem,reg	1 0 0 0 1 0 0 W	mod reg mem	2 to 4	(mem) ← reg						
		reg,mem	1 0 0 0 1 0 1 W	mod reg mem	2 to 4	reg ← (mem)						
		mem,imm	1 1 0 0 0 1 1 W	mod 0 0 0 mem	3 to 6	(mem) ← imm						
		reg,imm	1 0 1 1 W reg		2 to 3	reg ← imm						
		acc,dmem	1 0 1 0 0 0 0 W		3	When W = 0, AL ← (dmem) When W = 1, AH ← (dmem + 1), AL ← (dmem)						
		dmem,acc	1 0 1 0 0 0 1 W		3	When W = 0, (dmem) ← AL When W = 1, (dmem + 1) ← AH, (dmem) ← AL						
		sreg,reg16	1 0 0 0 1 1 1 0	1 1 0 sreg reg	2	sreg ← reg16 sreg : SS, DS0, DS1						
		sreg,mem16	1 0 0 0 1 1 1 0	mod 0 sreg mem	2 to 4	sreg ← (mem16) sreg : SS, DS0, DS1						
		reg16,sreg	1 0 0 0 1 1 0 0	1 1 0 sreg reg	2	reg16 ← sreg						
		mem16,sreg	1 0 0 0 1 1 0 0	mod 0 sreg mem	2 to 4	(mem16) ← sreg						
		DS0,reg16, mem32	1 1 0 0 0 1 0 1	mod reg mem	2 to 4	reg16 ← (mem32) DS0 ← (mem32 + 2)						
		DS1,reg16, mem32	1 1 0 0 0 1 0 0	mod reg mem	2 to 4	reg16 ← (mem32) DS1 ← (mem32 + 2)						
		AH,PSW	1 0 0 1 1 1 1 1		1	AH ← S, Z, F1, AC, F0, P, $\overline{\text{IBRK}}$, CY						
		PSW,AH	1 0 0 1 1 1 1 0		1	S, Z, F1, AC, F0, P, $\overline{\text{IBRK}}$, CY ← AH	×	×		×	×	×
	LDEA	reg16,mem16	1 0 0 0 1 1 0 1	mod reg mem	2 to 4	reg16 ← mem16						
	TRANS	src-table	1 1 0 1 0 1 1 1		1	AL ← (BW + AL)						
	XCH	reg,reg	1 0 0 0 0 1 1 W	1 1 reg reg	2	reg ↔ reg						
		mem,reg reg,mem	1 0 0 0 0 1 1 W	mod reg mem	2 to 4	(mem) ↔ reg						
		AW,reg16 reg16,AW	1 0 0 1 0 reg		1	AW ↔ reg16						
	MOVSPA ^{Note}		0 0 0 0 1 1 1 1	0 0 1 0 0 1 0 1	2	New register bank SS and SP ← old register bank SS and SP						
	MOVSPB ^{Note}	reg16	0 0 0 0 1 1 1 1	1 0 0 1 0 1 0 1	3	SS and SP of reg16-indicated new register bank ← old register bank SS and SP						
			1 1 1 1 1 reg									

Note These instructions are newly added to the μPD70108/70116.

Group	Mnemonic	Operand	Operation		Bytes	Operation	Flags					
			7 6 5 4 3 2 1 0	7 6 5 4 3 2 1 0			AC	CY	V	P	S	Z
Repeat prefix	REPC		0 1 1 0 0 1 0 1		1	Executes the primitive block transfer instruction in the continued byte while CW ≠ 0, and decrements CW by one. If any interruption is held at this time, it is processed. The program exits the loop when CY ≠ 1.						
	REPNC		0 1 1 0 0 1 0 0		1	Same as above. The program exits the loop when CY ≠ 0.						
	REP		1 1 1 1 0 0 1 1		1	Executes the primitive block transfer instruction in the continued byte while CW ≠ 0, and decrements CW by one. If any interruption is held at this time, it is processed. The program exits the loop when the primitive block transfer instruction is CMPBK or CMPM, and when Z ≠ 1.						
	REPE											
	REPZ											
	REPNE		1 1 1 1 0 0 1 0		1	Same as above. The program exits the loop when Z ≠ 0.						
	REPZ											
Primitive block transfer	MOVBK	dst-block, src-block	1 0 1 0 0 1 0 W		1	When W = 0, (IY) ← (IX) DIR = 0: IX ← IX + 1, IY ← IY + 1 DIR = 1: IX ← IX - 1, IY ← IY - 1						
						When W = 1, (IY + 1, IY) ← (IX + 1, IX) DIR = 0: IX ← IX + 2, IY ← IY + 2 DIR = 1: IX ← IX - 2, IY ← IY - 2						
	CMPBK	src-block, dst-block	1 0 1 0 0 1 1 W		1	When W = 0, (IX) - (IY) DIR = 0: IX ← IX + 1, IY ← IY + 1 DIR = 1: IX ← IX - 1, IY ← IY - 1	×	×	×	×	×	×
						When W = 1, (IX + 1, IX) - (IY + 1, IY) DIR = 0: IX ← IX + 2, IY ← IY + 2 DIR = 1: IX ← IX - 2, IY ← IY - 2						
	CMPM	dst-block	1 0 1 0 1 1 1 W		1	When W = 0, AL - (IY) DIR = 0: IY ← IY + 1; DIR = 1: IY ← IY - 1	×	×	×	×	×	×
						When W = 1, AW - (IY + 1, IY) DIR = 0: IY ← IY + 2; DIR = 1: IY ← IY - 2						
	LDM	src-block	1 0 1 0 1 1 0 W		1	When W = 0, AL ← (IX) DIR = 0: IX ← IX + 1; DIR = 1: IX ← IX - 1						
						When W = 1, AW ← (IX + 1, IX) DIR = 0: IX + 2; DIR = 1: IX ← IX - 2						
	STM	dst-block	1 0 1 0 1 0 1 W		1	When W = 0, (IY) ← AL DIR = 0: IY ← IY + 1; DIR = 1: IY ← IY - 1						
						When W = 1, (IY + 1, IY) ← AW DIR = 0: IY ← IY + 2; DIR = 1: IY ← IY - 2						

Phase-out/Discontinued

Phase-out/Discontinued

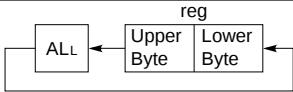
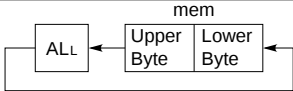
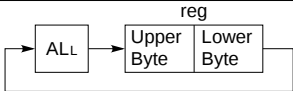
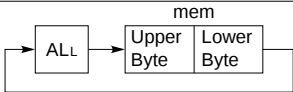
Group	Mnemonic	Operand	Operation Code		Bytes	Operation	Flags					
			7 6 5 4 3 2 1 0	7 6 5 4 3 2 1 0			AC	CY	V	P	S	Z
Bit field operation	INS	reg8,reg8	0 0 0 0 1 1 1 1	0 0 1 1 0 0 0 1	3	16-bit field $\leftarrow$ AW						
			1 1 reg reg									
		reg8,imm4	0 0 0 0 1 1 1 1	0 0 1 1 1 0 0 1	4	16-bit field $\leftarrow$ AW						
			1 1 0 0 0 reg									
	EXT	reg8,reg8	0 0 0 0 1 1 1 1	0 0 1 1 0 0 1 1	3	AW $\leftarrow$ 16-bit field						
			1 1 reg reg									
		reg8,imm4	0 0 0 0 1 1 1 1	0 0 1 1 1 0 1 1	4	AW $\leftarrow$ 16-bit field						
			1 1 0 0 0 reg									
I/O	IN ^{Note}	acc,imm8	1 1 1 0 0 1 0 W		2	When W = 0, AL $\leftarrow$ (imm8) When W = 1, AH $\leftarrow$ (imm8 + 1), AL $\leftarrow$ (imm8)						
		acc,DW	1 1 1 0 1 1 0 W		1	When W = 0, AL $\leftarrow$ (DW) When W = 1, AH $\leftarrow$ (DW + 1), AL $\leftarrow$ (DW)						
	OUT ^{Note}	imm8,acc	1 1 1 0 0 1 1 W		2	When W = 0, (imm8) $\leftarrow$ AL When W = 1, (imm8 + 1) $\leftarrow$ AH, (imm8) $\leftarrow$ AL						
		DW,acc	1 1 1 0 1 1 1 W		1	When W = 0, (DW) $\leftarrow$ AL When W = 1, (DW + 1) $\leftarrow$ AH, (DW) $\leftarrow$ AL						
Primitive I/O	INM ^{Note}	dst-block,DW	0 1 1 0 1 1 0 W		1	When W = 0, (IY) $\leftarrow$ (DW) DIR = 0: IY $\leftarrow$ IY + 1; DIR = 1: IY $\leftarrow$ IY - 1						
						When W = 1, (IY + 1, IY) $\leftarrow$ (DW + 1, DW) DIR = 0: IY $\leftarrow$ IY + 2; DIR = 1: IY $\leftarrow$ IY - 2						
	OUTM ^{Note}	DW,src-block	0 1 1 0 1 1 1 W		1	When W = 0, (DW) $\leftarrow$ (IX) DIR = 0: IX $\leftarrow$ IX + 1; DIR = 1: IX $\leftarrow$ IX - 1						
						When W = 1, (DW + 1, DW) $\leftarrow$ (IX + 1, IX) DIR = 0: IX $\leftarrow$ IX + 2; DIR = 1: IX $\leftarrow$ IX - 2						

Note When IBRK = 0, a software interrupt is generated automatically and the instruction is not executed.

Group	Mnemonic	Operand	Operation		Bytes	Operation	Flags					
			7 6 5 4 3 2 1 0	7 6 5 4 3 2 1 0			AC	CY	V	P	S	Z
Addition/ subtraction	ADD	reg,reg	0 0 0 0 0 0 1 W	1 1 reg reg	2	reg ← reg + reg	x	x	x	x	x	x
		mem,reg	0 0 0 0 0 0 0 W	mod reg mem	2 to 4	(mem) ← (mem) + reg	x	x	x	x	x	x
		reg,mem	0 0 0 0 0 0 1 W	mod reg mem	2 to 4	reg ← reg + (mem)	x	x	x	x	x	x
		reg,imm	1 0 0 0 0 0 s W	1 1 0 0 0 reg	3 to 4	reg ← reg + imm	x	x	x	x	x	x
		mem,imm	1 0 0 0 0 0 s W	mod 0 0 0 mem	3 to 6	(mem) ← (mem) + imm	x	x	x	x	x	x
		acc,imm	0 0 0 0 0 1 0 W		2 to 3	When W = 0, AL ← AL + imm When W = 1, AW ← AW + imm	x	x	x	x	x	x
	ADDC	reg,reg	0 0 0 1 0 0 1 W	1 1 reg reg	2	reg ← reg + reg + CY	x	x	x	x	x	x
		mem,reg	0 0 0 1 0 0 0 W	mod reg mem	2 to 4	(mem) ← (mem) + reg + CY	x	x	x	x	x	x
		reg,mem	0 0 0 1 0 0 1 W	mod reg mem	2 to 4	reg ← reg + (mem) + CY	x	x	x	x	x	x
		reg,imm	1 0 0 0 0 0 s W	1 1 0 1 0 reg	3 to 4	reg ← reg + imm + CY	x	x	x	x	x	x
		mem,imm	1 0 0 0 0 0 s W	mod 0 1 0 mem	3 to 6	(mem) ← (mem) + imm + CY	x	x	x	x	x	x
		acc,imm	0 0 0 1 0 1 0 W		2 to 3	When W = 0, AL ← AL + imm + CY When W = 1, AW ← AW + imm + CY	x	x	x	x	x	x
	SUB	reg,reg	0 0 1 0 1 0 1 W	1 1 reg reg	2	reg ← reg – reg	x	x	x	x	x	x
		mem,reg	0 0 1 0 1 0 0 W	mod reg mem	2 to 4	(mem) ← (mem) – reg	x	x	x	x	x	x
		reg,mem	0 0 1 0 1 0 1 W	mod reg mem	2 to 4	reg ← reg – (mem)	x	x	x	x	x	x
		reg,imm	1 0 0 0 0 0 s W	1 1 1 0 1 reg	3 to 4	reg ← reg – imm	x	x	x	x	x	x
		mem,imm	1 0 0 0 0 0 s W	mod 1 0 1 mem	3 to 6	(mem) ← (mem) – imm	x	x	x	x	x	x
		acc,imm	0 0 1 0 1 1 0 W		2 to 3	When W = 0, AL ← AL – imm When W = 1, AW ← AW – imm	x	x	x	x	x	x
	SUBC	reg,reg	0 0 0 1 1 0 1 W	1 1 reg reg	2	reg ← reg – reg – CY	x	x	x	x	x	x
		mem,reg	0 0 0 1 1 0 0 W	mod reg mem	2 to 4	(mem) ← (mem) – reg – CY	x	x	x	x	x	x
		reg,mem	0 0 0 1 1 0 1 W	mod reg mem	2 to 4	reg ← reg – (mem) – CY	x	x	x	x	x	x
		reg,imm	1 0 0 0 0 0 s W	1 1 0 1 1 reg	3 to 4	reg ← reg – imm – CY	x	x	x	x	x	x
		mem,imm	1 0 0 0 0 0 s W	mod 0 1 1 mem	3 to 6	(mem) ← (mem) – imm – CY	x	x	x	x	x	x
		acc,imm	0 0 0 1 1 1 0 W		2 to 3	When W = 0, AL ← AL – imm – CY When W = 1, AW ← AW – imm – CY	x	x	x	x	x	x

Phase-out/Discontinued

Phase-out/Discontinued

Group	Mnemonic	Operand	Operation Code		Bytes	Operation	Flags					
			7 6 5 4 3 2 1 0	7 6 5 4 3 2 1 0			AC	CY	V	P	S	Z
BCD operation	ADD4S		0 0 0 0 1 1 1 1	0 0 1 0 0 0 0 0	2	dst BCD string $\leftarrow$ dst BCD string + src BCD string Note	U	×	U	U	U	×
	SUB4S		0 0 0 0 1 1 1 1	0 0 1 0 0 0 1 0	2	dst BCD string $\leftarrow$ dst BCD string – src BCD string Note	U	×	U	U	U	×
	CMP4S		0 0 0 0 1 1 1 1	0 0 1 0 0 1 1 0	2	dst BCD string – src BCD string Note	U	×	U	U	U	×
	ROL4	reg8	0 0 0 0 1 1 1 1 1 1 0 0 0 reg	0 0 1 0 1 0 0 0	3							
		mem8	0 0 0 0 1 1 1 1 mod 0 0 0 mem	0 0 1 0 1 0 0 0	3 to 5							
	ROR4	reg8	0 0 0 0 1 1 1 1 1 1 0 0 0 reg	0 0 1 0 1 0 1 0	3							
		mem8	0 0 0 0 1 1 1 1 mod 0 0 0 mem	0 0 1 0 1 0 1 0	3 to 5							
Increment/decrement	INC	reg8	1 1 1 1 1 1 1 0	1 1 0 0 0 reg	2	reg8 $\leftarrow$ reg8 + 1	×		×	×	×	×
		mem	1 1 1 1 1 1 1 W	mod 0 0 0 mem	2 to 4	(mem) $\leftarrow$ (mem) + 1	×		×	×	×	×
		reg16	0 1 0 0 0 reg		1	reg16 $\leftarrow$ reg16 + 1	×		×	×	×	×
	DEC	reg8	1 1 1 1 1 1 1 0	1 1 0 0 1 reg	2	reg8 $\leftarrow$ reg8 – 1	×		×	×	×	×
		mem	1 1 1 1 1 1 1 W	mod 0 0 1 mem	2 to 4	(mem) $\leftarrow$ (mem) – 1	×		×	×	×	×
		reg16	0 1 0 0 1 reg		1	reg16 $\leftarrow$ reg16 – 1	×		×	×	×	×

n: 1/2 of the number of BCD digits

Note The number of BCD digits is given in the CL register. The value can be set within 1 to 254.

Group	Mnemonic	Operand	Operands		Bytes	Operation	Flags					
			7 6 5 4 3 2 1 0	7 6 5 4 3 2 1 0			AC	CY	V	P	S	Z
Multipli- cation	MULU	reg8	1 1 1 1 0 1 1 0	1 1 1 0 0 reg	2	AW ← AL × reg8 AH = 0: CY ← 0, V ← 0 AH ≠ 0: CY ← 1, V ← 1	U	×	×	U	U	U
		mem8	1 1 1 1 0 1 1 0	mod 1 0 0 mem	2 to 4	AW ← AL × (mem8) AH = 0: CY ← 0, V ← 0 AH ≠ 0: CY ← 1, V ← 1	U	×	×	U	U	U
		reg16	1 1 1 1 0 1 1 1	1 1 1 0 0 reg	2	DW, AW ← AW × reg16 DW = 0: CY ← 0, V ← 0 DW = 1: CY ← 1, V ← 1	U	×	×	U	U	U
		mem16	1 1 1 1 0 1 1 1	mod 1 0 0 mem	2 to 4	DW, AW ← AW × (mem16) DW = 0: CY ← 0, V ← 0 DW = 1: CY ← 1, V ← 1	U	×	×	U	U	U
	MUL	reg8	1 1 1 1 0 1 1 0	1 1 1 0 1 reg	2	AW ← AL × reg8 Extension of AH = AL sign: CY ← 0, V ← 0 Extension of AH ≠ AL sign: CY ← 1, V ← 1	U	×	×	U	U	U
		mem8	1 1 1 1 0 1 1 0	mod 1 0 1 mem	2 to 4	AW ← AL × (mem8) Extension of AH = AL sign: CY ← 0, V ← 0 Extension of AH ≠ AL sign: CY ← 1, V ← 1	U	×	×	U	U	U
		reg16	1 1 1 1 0 1 1 1	1 1 1 0 1 reg	2	DW, AW ← AW × reg16 Extension of DW = AW sign: CY ← 0, V ← 0 Extension of DW ≠ AW sign: CY ← 1, V ← 1	U	×	×	U	U	U
		mem16	1 1 1 1 0 1 1 1	mod 1 0 1 mem	2 to 4	DW, AW ← AW × (mem16) Extension of DW = AW sign: CY ← 0, V ← 0 Extension of DW ≠ AW sign: CY ← 1, V ← 1	U	×	×	U	U	U
		reg16, (reg16,) ^{Note} imm8	0 1 1 0 1 0 1 1	1 1 reg reg	3	reg16 ← reg16 × imm8 Product ≤ 16 bits: CY ← 0, V ← 0 Product > 16 bits: CY ← 1, V ← 1	U	×	×	U	U	U
		reg16, mem16, imm8	0 1 1 0 1 0 1 1	mod reg mem	3 to 5	reg16 ← (mem16) × imm8 Product ≤ 16 bits: CY ← 0, V ← 0 Product > 16 bits: CY ← 1, V ← 1	U	×	×	U	U	U
		reg16, (reg16,) ^{Note} imm16	0 1 1 0 1 0 0 1	1 1 reg reg	4	reg16 ← reg16 × imm16 Product ≤ 16 bits: CY ← 0, V ← 0 Product > 16 bits: CY ← 1, V ← 1	U	×	×	U	U	U
		reg16, mem16, imm16	0 1 1 0 1 0 0 1	mod reg mem	4 to 6	reg16 ← (mem16) × imm16 Product ≤ 16 bits: CY ← 0, V ← 0 Product > 16 bits: CY ← 1, V ← 1	U	×	×	U	U	U

Note The 2nd operand is omissible. If omitted, the 1st operand is assumed.

Phase-out/Discontinued

Phase-out/Discontinued

Group	Mnemonic	Operand	Operation Code		Bytes	Operation	Flags					
			7 6 5 4 3 2 1 0	7 6 5 4 3 2 1 0			AC	CY	V	P	S	Z
Unsign- ed division	DIVU	reg8	1 1 1 1 0 1 1 0	1 1 1 1 0 reg	2	temp ← AW When temp + reg8 ≤ FFH AH ← temp%reg8, AL ← temp + reg8 When temp + reg8 > FFH (SP - 1, SP - 2) ← PSW, (SP - 3, SP - 4) ← PS (SP - 5, SP - 6) ← PC, SP ← SP - 6 IE ← 0, BRK ← 0, PS ← (3, 2), PC ← (1, 0)	U	U	U	U	U	U
		mem8	1 1 1 1 0 1 1 0	mod 1 1 0 mem	2 to 4	temp ← AW When temp + (mem8) ≤ FFH AH ← temp%(mem8), AL ← temp + (mem8) When temp + (mem8) > FFH (SP - 1, SP - 2) ← PSW, (SP - 3, SP - 4) ← PS (SP - 5, SP - 6) ← PC, SP ← SP - 6 IE ← 0, BRK ← 0, PS ← (3, 2), PC ← (1, 0)	U	U	U	U	U	U
		reg16	1 1 1 1 0 1 1 1	1 1 1 1 0 reg	2	temp ← DW, AW When temp + reg16 ≤ FFFFH DW ← temp%reg16, AW ← temp + reg16 When temp + reg16 > FFFFH (SP - 1, SP - 2) ← PSW, (SP - 3, SP - 4) ← PS (SP - 5, SP - 6) ← PC, SP ← SP - 6 IE ← 0, BRK ← 0, PS ← (3, 2), PC ← (1, 0)	U	U	U	U	U	U
		mem16	1 1 1 1 0 1 1 1	mod 1 1 0 mem	2 to 4	temp ← DW, AW When temp + (mem16) ≤ FFFFH DW ← temp%(mem16), AW ← temp + (mem16) When temp + (mem16) > FFFFH (SP - 1, SP - 2) ← PSW, (SP - 3, SP - 4) ← PS (SP - 5, SP - 6) ← PC, SP ← SP - 6 IE ← 0, BRK ← 0, PS ← (3, 2), PC ← (1, 0)	U	U	U	U	U	U

Group	Mnemonic	Operand	Operation														Flags											
			7	6	5	4	3	2	1	0	7	6	5	4	3	2	1	0	Bytes	Operation						AC	CY	V
Signed division	DIV	reg8	1	1	1	1	0	1	1	0	1	1	1	1	reg	2	temp ← AW When temp + reg8 > 0 and temp + reg8 ≤ 7FH or temp + reg8 < 0 and temp + reg8 > 0 – 7FH – 1 AH ← temp%reg8, AL ← temp + reg8 When temp + reg8 > 0 and temp + reg8 > 7FH or temp + reg8 > 0 and temp + reg8 < 0 – 7FH – 1 (SP – 1, SP – 2) ← PSW, (SP – 3, SP – 4) ← PS (SP – 5, SP – 6) ← PC, SP ← SP – 6 IE ← 0, BRK ← 0, PS ← (3, 2), PC ← (1, 0)		U	U	U	U	U	U	U	U		
		mem8	1	1	1	1	0	1	1	0	mod 1 1 1 mem	2 to 4	temp ← AW When temp + (mem8) > 0 and temp + (mem8) ≤ 7FH or temp + (mem8) < 0 and temp + (mem8) > 0 – 7FH – 1 AH ← temp%(mem8), AL ← temp + (mem8) When temp + (mem8) > 0 and temp + (mem8) > 7FH or temp + (mem8) > 0 and temp + (mem8) < 0 – 7FH – 1 (SP – 1, SP – 2) ← PSW, (SP – 3, SP – 4) ← PS (SP – 5, SP – 6) ← PC, SP ← SP – 6 IE ← 0, BRK ← 0, PS ← (3, 2), PC ← (1, 0)		U	U	U	U	U	U	U	U						
		reg16	1	1	1	1	0	1	1	1	1 1 1 1 1 reg	2	temp ← DW, AW When temp + reg16 > 0 and temp + reg16 ≤ 7FFFH or temp + reg16 < 0 and temp + reg16 > 0 – 7FFFH – 1 DW ← temp%reg16, AW ← temp + reg16 When temp + reg16 > 0 and temp + reg16 > 7FFFH or temp + reg16 > 0 and temp + reg16 < 0 – 7FFFH – 1 (SP – 1, SP – 2) ← PSW, (SP – 3, SP – 4) ← PS (SP – 5, SP – 6) ← PC, SP ← SP – 6 IE ← 0, BRK ← 0, PS ← (3, 2), PC ← (1, 0)		U	U	U	U	U	U	U	U						
		mem16	1	1	1	1	0	1	1	1	1 mod 1 1 1 mem	2 to 4	temp ← DW, AW When temp + (mem16) > 0 and temp + (mem16) ≤ 7FFFH or temp + (mem16) < 0 and temp + (mem16) > 0 – 7FFFH – 1 DW ← temp%(mem16), AW ← temp + (mem16) When temp + (mem16) > 0 and temp + (mem16) > 7FFFH or temp + (mem16) > 0 and temp + (mem16) < 0 – 7FFFH – 1 (SP – 1, SP – 2) ← PSW, (SP – 3, SP – 4) ← PS (SP – 5, SP – 6) ← PC, SP ← SP – 6 IE ← 0, BRK ← 0, PS ← (3, 2), PC ← (1, 0)		U	U	U	U	U	U	U	U						

Phase-out/Discontinued

Phase-out/Discontinued

Group	Mnemonic	Operand	Operation Code		Bytes	Operation	Flags					
			7 6 5 4 3 2 1 0	7 6 5 4 3 2 1 0			AC	CY	V	P	S	Z
BCD adjust-ment	ADJBA		0 0 1 1 0 1 1 1		1	When $AL \wedge 0FH > 9$ or $AC = 1$, $AL \leftarrow AL + 6$ $AH \leftarrow AH + 1$, $AC \leftarrow 1$, $CY \leftarrow AC$, $AL \leftarrow AL \wedge 0FH$	×	×	U	U	U	U
	ADJ4A		0 0 1 0 0 1 1 1		1	When $AL \wedge 0FH > 9$ or $AC = 1$, $AL \leftarrow AL + 6$, $AC \leftarrow 1$ When $AL > 9FH$ or $CY = 1$, $AL \leftarrow AL + 60H$, $CY \leftarrow 1$	×	×	U	×	×	×
	ADJBS		0 0 1 1 1 1 1 1		1	When $AL \wedge 0FH > 9$ or $AC = 1$, $AL \leftarrow AL - 6$, $AH \leftarrow AH - 1$, $AC \leftarrow 1$ $CY \leftarrow AC$, $AL \leftarrow AL \wedge 0FH$	×	×	U	U	U	U
	ADJ4S		0 0 1 0 1 1 1 1		1	When $AL \wedge 0FH > 9$ or $AC = 1$, $AL \leftarrow AL - 6$, $AC \leftarrow 1$ When $AL > 9FH$ or $CY = 1$, $AL \leftarrow AL - 60H$, $CY \leftarrow 1$	×	×	U	×	×	×
Data conver-sion	CVTBD		1 1 0 1 0 1 0 0	0 0 0 0 1 0 1 0	2	$AH \leftarrow AL + 0AH$, $AL \leftarrow AL \% 0AH$	U	U	U	×	×	×
	CVTDB		1 1 0 1 0 1 0 1	0 0 0 0 1 0 1 0	2	$AL \leftarrow AH \times 0AH + AL$, $AH \leftarrow 0$	U	U	U	×	×	×
	CVTBW		1 0 0 1 1 0 0 0		1	When $AL < 80H$, $AH \leftarrow 0$. In other cases, $AH \leftarrow FFH$.						
	CVTWL		1 0 0 1 1 0 0 1		1	When $AW < 8000H$, $DW \leftarrow 0$. In other cases, $DW \leftarrow FFFFH$.						
Compare	CMP	reg,reg	0 0 1 1 1 0 1 W	1 1 reg reg	2	$reg - reg$	×	×	×	×	×	×
		mem,reg	0 0 1 1 1 0 0 W	mod reg mem	2 to 4	$(mem) - reg$	×	×	×	×	×	×
		reg,mem	0 0 1 1 1 0 1 W	mod reg mem	2 to 4	$reg - (mem)$	×	×	×	×	×	×
		reg,imm	1 0 0 0 0 0 s W	1 1 1 1 1 reg	3 to 4	$reg - imm$	×	×	×	×	×	×
		mem,imm	1 0 0 0 0 0 s W	mod 1 1 1 mem	3 to 6	$(mem) - imm$	×	×	×	×	×	×
		acc,imm	0 0 1 1 1 1 0 W		2 to 3	When $W = 0$, $AL - imm$ When $W = 1$, $AW - imm$	×	×	×	×	×	×
Comple-ment operation	NOT	reg	1 1 1 1 0 1 1 W	1 1 0 1 0 reg	2	$reg \leftarrow \overline{reg}$						
		mem	1 1 1 1 0 1 1 W	mod 0 1 0 mem	2 to 4	$(mem) \leftarrow \overline{(mem)}$						
	NEG	reg	1 1 1 1 0 1 1 W	1 1 0 1 1 reg	2	$reg \leftarrow \overline{reg} + 1$	×	×	×	×	×	×
		mem	1 1 1 1 0 1 1 W	mod 0 1 1 mem	2 to 4	$(mem) \leftarrow \overline{(mem)} + 1$	×	×	×	×	×	×

Group	Mnemonic	Operand	Operation		Operation	Flags						
			7 6 5 4 3 2 1 0	7 6 5 4 3 2 1 0		AC	CY	V	P	S	Z	
Logical operation	TEST	reg,reg	1 0 0 0 0 1 0 W	1 1 reg reg	2	reg $\wedge$ reg	U	0	0	$\times$	$\times$	$\times$
		mem,reg reg,mem	1 0 0 0 0 1 0 W	mod reg mem	2 to 4	(mem) $\wedge$ reg	U	0	0	$\times$	$\times$	$\times$
		reg,imm	1 1 1 1 0 1 1 W	1 1 0 0 0 reg	3 to 4	reg $\wedge$ imm	U	0	0	$\times$	$\times$	$\times$
		mem,imm	1 1 1 1 0 1 1 W	mod 0 0 0 mem	3 to 6	(mem) $\wedge$ imm	U	0	0	$\times$	$\times$	$\times$
		acc,imm	1 0 1 0 1 0 0 W		2 to 3	When W = 0, AL $\wedge$ imm8 When W = 1, AW $\wedge$ imm16	U	0	0	$\times$	$\times$	$\times$
	AND	reg,reg	0 0 1 0 0 0 1 W	1 1 reg reg	2	reg $\leftarrow$ reg $\wedge$ reg	U	0	0	$\times$	$\times$	$\times$
		mem,reg	0 0 1 0 0 0 0 W	mod reg mem	2 to 4	(mem) $\leftarrow$ (mem) $\wedge$ reg	U	0	0	$\times$	$\times$	$\times$
		reg,mem	0 0 1 0 0 0 1 W	mod reg mem	2 to 4	reg $\leftarrow$ reg $\wedge$ (mem)	U	0	0	$\times$	$\times$	$\times$
		reg,imm	1 0 0 0 0 0 0 W	1 1 1 0 0 reg	3 to 4	reg $\leftarrow$ reg $\wedge$ imm	U	0	0	$\times$	$\times$	$\times$
		mem,imm	1 0 0 0 0 0 0 W	mod 1 0 0 mem	3 to 6	(mem) $\leftarrow$ (mem) $\wedge$ imm	U	0	0	$\times$	$\times$	$\times$
		acc,imm	0 0 1 0 0 1 0 W		2 to 3	When W = 0, AL $\leftarrow$ AL $\wedge$ imm8 When W = 1, AW $\leftarrow$ AW $\wedge$ imm16	U	0	0	$\times$	$\times$	$\times$
	OR	reg,reg	0 0 0 0 1 0 1 W	1 1 reg reg	2	reg $\leftarrow$ reg $\vee$ reg	U	0	0	$\times$	$\times$	$\times$
		mem,reg	0 0 0 0 1 0 0 W	mod reg mem	2 to 4	(mem) $\leftarrow$ (mem) $\vee$ reg	U	0	0	$\times$	$\times$	$\times$
		reg,mem	0 0 0 0 1 0 1 W	mod reg mem	2 to 4	reg $\leftarrow$ reg $\vee$ (mem)	U	0	0	$\times$	$\times$	$\times$
		reg,imm	1 0 0 0 0 0 0 W	1 1 0 0 1 reg	3 to 4	reg $\leftarrow$ reg $\vee$ imm	U	0	0	$\times$	$\times$	$\times$
		mem,imm	1 0 0 0 0 0 0 W	mod 0 0 1 mem	3 to 6	(mem) $\leftarrow$ (mem) $\vee$ imm	U	0	0	$\times$	$\times$	$\times$
		acc,imm	0 0 0 0 1 1 0 W		2 to 3	When W = 0, AL $\leftarrow$ AL $\vee$ imm8 When W = 1, AW $\leftarrow$ AW $\vee$ imm16	U	0	0	$\times$	$\times$	$\times$
	XOR	reg,reg	0 0 1 1 0 0 1 W	1 1 reg reg	2	reg $\leftarrow$ reg ∇ reg	U	0	0	$\times$	$\times$	$\times$
		mem,reg	0 0 1 1 0 0 0 W	mod reg mem	2 to 4	(mem) $\leftarrow$ (mem) ∇ reg	U	0	0	$\times$	$\times$	$\times$
		reg,mem	0 0 1 1 0 0 1 W	mod reg mem	2 to 4	reg $\leftarrow$ reg ∇ (mem)	U	0	0	$\times$	$\times$	$\times$
		reg,imm	1 0 0 0 0 0 0 W	1 1 1 1 0 reg	3 to 4	reg $\leftarrow$ reg ∇ imm	U	0	0	$\times$	$\times$	$\times$
		mem,imm	1 0 0 0 0 0 0 W	mod 1 1 0 mem	3 to 6	(mem) $\leftarrow$ (mem) ∇ imm	U	0	0	$\times$	$\times$	$\times$
		acc,imm	0 0 1 1 0 1 0 W		2 to 3	When W = 0, AL $\leftarrow$ AL ∇ imm8 When W = 1, AW $\leftarrow$ AW ∇ imm16	U	0	0	$\times$	$\times$	$\times$

Phase-out/Discontinued

Phase-out/Discontinued

Group	Mnemonic	Operand	Operation Code		Bytes	Operation	Flags					
			7 6 5 4 3 2 1 0	7 6 5 4 3 2 1 0			AC	CY	V	P	S	Z
Bit manipulation	TEST1	reg8,CL	0 0 0 1 0 0 0 0	1 1 0 0 0 0 reg	3	reg8 bit No. CL = 0: $Z \leftarrow 1$ reg8 bit No. CL = 1: $Z \leftarrow 0$	U	0	0	U	U	×
		mem8,CL	0 0 0 0	mod 0 0 0 0 mem	3 to 5	(mem8) bit No. CL = 0: $Z \leftarrow 1$ (mem8) bit No. CL = 1: $Z \leftarrow 0$	U	0	0	U	U	×
		reg16,CL	0 0 0 1	1 1 0 0 0 0 reg	3	reg16 bit No. CL = 0: $Z \leftarrow 1$ reg16 bit No. CL = 1: $Z \leftarrow 0$	U	0	0	U	U	×
		mem16,CL	0 0 0 1	mod 0 0 0 0 mem	3 to 5	(mem16) bit No. CL = 0: $Z \leftarrow 1$ (mem16) bit No. CL = 1: $Z \leftarrow 0$	U	0	0	U	U	×
		reg8,imm3	1 0 0 0	1 1 0 0 0 0 reg	4	reg8 bit No. imm3 = 0: $Z \leftarrow 1$ reg8 bit No. imm3 = 1: $Z \leftarrow 0$	U	0	0	U	U	×
		mem8,imm3	1 0 0 0	mod 0 0 0 0 mem	4 to 6	(mem8) bit No. imm3 = 0: $Z \leftarrow 1$ (mem8) bit No. imm3 = 1: $Z \leftarrow 0$	U	0	0	U	U	×
		reg16,imm4	1 0 0 1	1 1 0 0 0 0 reg	4	reg16 bit No. imm4 = 0: $Z \leftarrow 1$ reg16 bit No. imm4 = 1: $Z \leftarrow 0$	U	0	0	U	U	×
		mem16,imm4	1 0 0 1	mod 0 0 0 0 mem	4 to 6	(mem16) bit No. imm4 = 0: $Z \leftarrow 1$ (mem16) bit No. imm4 = 1: $Z \leftarrow 0$	U	0	0	U	U	×
	NOT1	reg8,CL	0 1 1 0	1 1 0 0 0 0 reg	3	reg8 bit No. CL $\leftarrow \overline{\text{reg8 bit No. CL}}$						
		mem8,CL	0 1 1 0	mod 0 0 0 0 mem	3 to 5	(mem8) bit No. CL $\leftarrow \overline{(\text{mem8}) \text{ bit No. CL}}$						
		reg16,CL	0 1 1 1	1 1 0 0 0 0 reg	3	reg16 bit No. CL $\leftarrow \overline{\text{reg16 bit No. CL}}$						
		mem16,CL	0 1 1 1	mod 0 0 0 0 mem	3 to 5	(mem16) bit No. CL $\leftarrow \overline{(\text{mem16}) \text{ bit No. CL}}$						
		reg8,imm3	1 1 1 0	1 1 0 0 0 0 reg	4	reg8 bit No. imm3 $\leftarrow \overline{\text{reg8 bit No. imm3}}$						
		mem8,imm3	1 1 1 0	mod 0 0 0 0 mem	4 to 6	(mem8) bit No. imm3 $\leftarrow \overline{(\text{mem8}) \text{ bit No. imm3}}$						
		reg16,imm4	1 1 1 1	1 1 0 0 0 0 reg	4	reg16 bit No. imm4 $\leftarrow \overline{\text{reg16 bit No. imm4}}$						
		mem16,imm4	1 1 1 1	mod 0 0 0 0 mem	4 to 6	(mem16) bit No. imm4 $\leftarrow \overline{(\text{mem16}) \text{ bit No. imm4}}$						

2nd byte ^{Note}

3rd byte ^{Note}

Note 1st byte = 0FH

	NOT1	CY	1 1 1 1 0 1 0 1		1	$CY \leftarrow \overline{CY}$		×				
--	------	----	-----------------	--	---	-------------------------------	--	---	--	--	--	--

Group	Mnemonic	Operand	Operation		Operation	Flags					
			7 6 5 4 3 2 1 0	7 6 5 4 3 2 1 0		AC	CY	V	P	S	Z
Bit manipulation	CLR1	reg8,CL	0 0 0 1 0 0 1 0	1 1 0 0 0 reg	3	reg8 bit No. CL ← 0					
		mem8,CL	0 0 1 0	mod 0 0 0 mem	3 to 5	(mem8) bit No. CL ← 0					
		reg16,CL	0 0 1 1	1 1 0 0 0 reg	3	reg16 bit No. CL ← 0					
		mem16,CL	0 0 1 1	mod 0 0 0 mem	3 to 5	(mem16) bit No. CL ← 0					
		reg8,imm3	1 0 1 0	1 1 0 0 0 reg	4	reg8 bit No. imm3 ← 0					
		mem8,imm3	1 0 1 0	mod 0 0 0 mem	4 to 6	(mem8) bit No. imm3 ← 0					
		reg16,imm4	1 0 1 1	1 1 0 0 0 reg	4	reg16 bit No. imm4 ← 0					
		mem16,imm4	1 0 1 1	mod 0 0 0 mem	4 to 6	(mem16) bit No. imm4 ← 0					
	SET1	reg8,CL	0 1 0 0	1 1 0 0 0 reg	3	reg8 bit No. CL ← 1					
		mem8,CL	0 1 0 0	mod 0 0 0 mem	3 to 5	(mem8) bit No. CL ← 1					
		reg16,CL	0 1 0 1	1 1 0 0 0 reg	3	reg16 bit No. CL ← 1					
		mem16,CL	0 1 0 1	mod 0 0 0 mem	3 to 5	(mem16) bit No. CL ← 1					
		reg8,imm3	1 1 0 0	1 1 0 0 0 reg	4	reg8 bit No. imm3 ← 1					
		mem8,imm3	1 1 0 0	mod 0 0 0 mem	4 to 6	(mem8) bit No. imm3 ← 1					
		reg16,imm4	1 1 0 1	1 1 0 0 0 reg	4	reg16 bit No. imm4 ← 1					
		mem16,imm4	1 1 0 1	mod 0 0 0 mem	4 to 6	(mem16) bit No. imm4 ← 1					

2nd byte ^{Note}

3rd byte ^{Note}

Note 1st byte = 0FH

	CLR1	CY	1 1 1 1 1 0 0 0		1	CY ← 0	0				
		DIR	1 1 1 1 1 1 0 0		1	DIR ← 0					
	SET1	CY	1 1 1 1 1 0 0 1		1	CY ← 1	1				
		DIR	1 1 1 1 1 1 0 1		1	DIR ← 1					

Phase-out/Discontinued

Phase-out/Discontinued

Group	Mnemonic	Operand	Operation Code		Bytes	Operation	Flags					
			7 6 5 4 3 2 1 0	7 6 5 4 3 2 1 0			AC	CY	V	P	S	Z
Shift	SHL	reg,1	1 1 0 1 0 0 0 W	1 1 1 0 0 reg	2	CY ← reg MSB, reg ← reg × 2 When reg MSB ≠ CY, V ← 1 When reg MSB = CY, V ← 0	U	×	×	×	×	×
		mem,1	1 1 0 1 0 0 0 W	mod 1 0 0 mem	2 to 4	CY ← (mem) MSB, (mem) ← (mem) × 2 When (mem) MSB ≠ CY, V ← 1 When (mem) MSB = CY, V ← 0	U	×	×	×	×	×
		reg,CL	1 1 0 1 0 0 1 W	1 1 1 0 0 reg	2	The following operations are repeated while temp ← CL and temp ≠ 0. CY ← reg MSB, reg ← reg × 2 temp ← temp – 1	U	×	U	×	×	×
		mem,CL	1 1 0 1 0 0 1 W	mod 1 0 0 mem	2 to 4	The following operations are repeated while temp ← CL and temp ≠ 0. CY ← (mem) MSB, (mem) ← (mem) × 2 temp ← temp – 1	U	×	U	×	×	×
		reg,imm8	1 1 0 0 0 0 0 W	1 1 1 0 0 reg	3	The following operations are repeated while temp ← imm8 and temp ≠ 0. CY ← reg MSB, reg ← reg × 2 temp ← temp – 1	U	×	U	×	×	×
		mem,imm8	1 1 0 0 0 0 0 W	mod 1 0 0 mem	3 to 5	The following operations are repeated while temp ← imm8 and temp ≠ 0. CY ← (mem) MSB, (mem) ← (mem) × 2 temp ← temp – 1	U	×	U	×	×	×

Group	Mnemonic	Operand	Operands		Bytes	Operation	Flags					
			7 6 5 4 3 2 1 0	7 6 5 4 3 2 1 0			AC	CY	V	P	S	Z
Shift	SHR	reg,1	1 1 0 1 0 0 0 W	1 1 1 0 1 reg	2	CY ← reg LSB, reg ← reg ÷ 2 reg MSB ≠ bit following reg MSB: V ← 1 reg MSB = bit following reg MSB: V ← 0	U	×	×	×	×	×
		mem,1	1 1 0 1 0 0 0 W	mod 1 0 1 mem	2 to 4	CY ← (mem) LSB, (mem) ← (mem) ÷ 2 (mem) MSB ≠ bit following (mem) MSB: V ← 1 (mem) MSB = bit following (mem) MSB: V ← 0	U	×	×	×	×	×
		reg,CL	1 1 0 1 0 0 1 W	1 1 1 0 1 reg	2	The following operations are repeated while temp ← CL and temp ≠ 0. CY ← reg LSB, reg ← reg ÷ 2 temp ← temp – 1	U	×	U	×	×	×
		mem,CL	1 1 0 1 0 0 1 W	mod 1 0 1 mem	2 to 4	The following operations are repeated while temp ← CL and temp ≠ 0. CY ← (mem) LSB, (mem) ← (mem) ÷ 2 temp ← temp – 1	U	×	U	×	×	×
		reg,imm8	1 1 0 0 0 0 0 W	1 1 1 0 1 reg	3	The following operations are repeated while temp ← imm8 and temp ≠ 0. CY ← reg LSB, reg ← reg ÷ 2 temp ← temp – 1	U	×	U	×	×	×
		mem,imm8	1 1 0 0 0 0 0 W	mod 1 0 1 mem	3 to 5	The following operations are repeated while temp ← imm8 and temp ≠ 0. CY ← (mem) LSB, (mem) ← (mem) ÷ 2 temp ← temp – 1	U	×	U	×	×	×
	SHRA	reg,1	1 1 0 1 0 0 0 W	1 1 1 1 1 reg	2	CY ← reg LSB, reg ← reg ÷ 2, V ← 0 The operand MSB remains the same status.	U	×	0	×	×	×
		mem,1	1 1 0 1 0 0 0 W	mod 1 1 1 mem	2 to 4	CY ← (mem) LSB, (mem) ← (mem) ÷ 2, V ← 0 The operand MSB remains the same status.	U	×	0	×	×	×
		reg,CL	1 1 0 1 0 0 1 W	1 1 1 1 1 reg	2	The following operations are repeated while temp ← CL and temp ≠ 0. CY ← reg LSB, reg ← reg ÷ 2 temp ← temp – 1 The operand MSB remains the same status.	U	×	U	×	×	×
		mem,CL	1 1 0 1 0 0 1 W	mod 1 1 1 mem	2 to 4	The following operations are repeated while temp ← CL and temp ≠ 0. CY ← (mem) LSB, (mem) ← (mem) ÷ 2 temp ← temp – 1 The operand MSB remains the same status.	U	×	U	×	×	×
		reg,imm8	1 1 0 0 0 0 0 W	1 1 1 1 1 reg	3	The following operations are repeated while temp ← imm8 and temp ≠ 0. CY ← reg LSB, reg ← reg ÷ 2 temp ← temp – 1 The operand MSB remains the same status.	U	×	U	×	×	×
		mem,imm8	1 1 0 0 0 0 0 W	mod 1 1 1 mem	3 to 5	The following operations are repeated while temp ← imm8 and temp ≠ 0. CY ← (mem) LSB, (mem) ← (mem) ÷ 2 temp ← temp – 1 The operand MSB remains the same status.	U	×	U	×	×	×

Phase-out/Discontinued

Phase-out/Discontinued

Group	Mnemonic	Operand	Operation Code		Bytes	Operation	Flags					
			7 6 5 4 3 2 1 0	7 6 5 4 3 2 1 0			AC	CY	V	P	S	Z
Rotate	ROL	reg,1	1 1 0 1 0 0 0 W	1 1 0 0 0 reg	2	CY ← reg MSB, reg ← reg × 2 + CY reg MSB ≠ CY: V ← 1 reg MSB = CY: V ← 0		×	×			
		mem,1	1 1 0 1 0 0 0 W	mod 0 0 0 mem	2 to 4	CY ← (mem) MSB, (mem) ← (mem) × 2 + CY (mem) MSB ≠ CY: V ← 1 (mem) MSB = CY: V ← 0		×	×			
		reg,CL	1 1 0 1 0 0 1 W	1 1 0 0 0 reg	2	The following operations are repeated while temp ← CL and temp ≠ 0. CY ← reg MSB, reg ← reg × 2 + CY temp ← temp − 1		×	U			
		mem,CL	1 1 0 1 0 0 1 W	mod 0 0 0 mem	2 to 4	The following operations are repeated while temp ← CL and temp ≠ 0. CY ← (mem) MSB, (mem) ← (mem) × 2 + CY temp ← temp − 1		×	U			
		reg,imm8	1 1 0 0 0 0 0 W	1 1 0 0 0 reg	3	The following operations are repeated while temp ← imm8 and temp ≠ 0. CY ← reg MSB, reg ← reg × 2 + CY temp ← temp − 1		×	U			
		mem,imm8	1 1 0 0 0 0 0 W	mod 0 0 0 mem	3 to 5	The following operations are repeated while temp ← imm8 and temp ≠ 0. CY ← (mem) MSB, (mem) ← (mem) × 2 + CY temp ← temp − 1		×	U			
	ROR	reg,1	1 1 0 1 0 0 0 W	1 1 0 0 1 reg	2	CY ← reg LSB, reg ← reg ÷ 2 reg MSB ← CY reg MSB ≠ bit following reg MSB: V ← 1 reg MSB = bit following reg MSB: V ← 0		×	×			
		mem,1	1 1 0 1 0 0 0 W	mod 0 0 1 mem	2 to 4	CY ← (mem) LSB, (mem) ← (mem) ÷ 2 (mem) MSB ← CY (mem) MSB ≠ bit following (mem) MSB: V ← 1 (mem) MSB = bit following (mem) MSB: V ← 0		×	×			
		reg,CL	1 1 0 1 0 0 1 W	1 1 0 0 1 reg	2	The following operations are repeated while temp ← CL and temp ≠ 0. CY ← reg LSB, reg ← reg ÷ 2 reg MSB ← CY temp ← temp − 1		×	U			
		mem,CL	1 1 0 1 0 0 1 W	mod 0 0 1 mem	2 to 4	The following operations are repeated while temp ← CL and temp ≠ 0. CY ← (mem) LSB, (mem) ← (mem) ÷ 2 (mem) MSB ← CY temp ← temp − 1		×	U			
		reg,imm8	1 1 0 0 0 0 0 W	1 1 0 0 1 reg	3	The following operations are repeated while temp ← imm8 and temp ≠ 0. CY ← reg LSB, reg ← reg ÷ 2 reg MSB ← CY temp ← temp − 1		×	U			
		mem,imm8	1 1 0 0 0 0 0 W	mod 0 0 1 mem	3 to 5	The following operations are repeated while temp ← imm8 and temp ≠ 0. CY ← (mem) LSB, (mem) ← (mem) ÷ 2 (mem) MSB ← CY temp ← temp − 1		×	U			

Group	Mnemonic	Operand	Operation		Bytes	Operation	Flags					
			7 6 5 4 3 2 1 0	7 6 5 4 3 2 1 0			AC	CY	V	P	S	Z
Rotate	ROL	reg,1	1 1 0 1 0 0 0 W	1 1 0 1 0 reg	2	$tmpcy \leftarrow CY$, $CY \leftarrow reg\ MSB$ $reg \leftarrow reg \times 2 + tmpcy$ $reg\ MSB \neq CY: V \leftarrow 1$ $reg\ MSB = CY: V \leftarrow 0$		×	×			
		mem,1	1 1 0 1 0 0 0 W	mod 0 1 0 mem	2 to 4	$tmpcy \leftarrow CY$, $CY \leftarrow (mem)\ MSB$ $(mem) \leftarrow (mem) \times 2 + tmpcy$ $(mem)\ MSB \neq CY: V \leftarrow 1$ $(mem)\ MSB = CY: V \leftarrow 0$		×	×			
		reg,CL	1 1 0 1 0 0 1 W	1 1 0 1 0 reg	2	The following operations are repeated while $temp \leftarrow CL$ and $temp \neq 0$. $tmpcy \leftarrow CY$, $CY \leftarrow reg\ MSB$ $reg \leftarrow reg \times 2 + tmpcy$ $temp \leftarrow temp - 1$		×	U			
		mem,CL	1 1 0 1 0 0 1 W	mod 0 1 0 mem	2 to 4	The following operations are repeated while $temp \leftarrow CL$ and $temp \neq 0$. $tmpcy \leftarrow CY$, $CY \leftarrow (mem)\ MSB$ $(mem) \leftarrow (mem) \times 2 + tmpcy$ $temp \leftarrow temp - 1$		×	U			
		reg,imm8	1 1 0 0 0 0 0 W	1 1 0 1 0 reg	3	The following operations are repeated while $temp \leftarrow imm8$ and $temp \neq 0$. $tmpcy \leftarrow CY$, $CY \leftarrow reg\ MSB$ $reg \leftarrow reg \times 2 + tmpcy$ $temp \leftarrow temp - 1$		×	U			
		mem,imm8	1 1 0 0 0 0 0 W	mod 0 1 0 mem	3 to 5	The following operations are repeated while $temp \leftarrow imm8$ and $temp \neq 0$. $tmpcy \leftarrow CY$, $CY \leftarrow (mem)\ MSB$ $(mem) \leftarrow (mem) \times 2 + tmpcy$ $temp \leftarrow temp - 1$		×	U			

Phase-out/Discontinued

Phase-out/Discontinued

Group	Mnemonic	Operand	Operation Code		Bytes	Operation	Flags					
			7 6 5 4 3 2 1 0	7 6 5 4 3 2 1 0			AC	CY	V	P	S	Z
Rotate	RORC	reg,1	1 1 0 1 0 0 0 W	1 1 0 1 1 reg	2	tmpcy $\leftarrow$ CY, CY $\leftarrow$ reg LSB reg $\leftarrow$ reg $\div$ 2 reg MSB $\leftarrow$ tmpcy reg MSB $\neq$ bit following reg MSB: V $\leftarrow$ 1 reg MSB = bit following reg MSB: V $\leftarrow$ 0		×	×			
		mem,1	1 1 0 1 0 0 0 W	mod 0 1 1 mem	2 to 4	tmpcy $\leftarrow$ CY, CY $\leftarrow$ (mem) LSB (mem) $\leftarrow$ (mem) $\div$ 2 (mem) MSB $\leftarrow$ tmpcy (mem) MSB $\neq$ bit following (mem) MSB: V $\leftarrow$ 1 (mem) MSB = bit following (mem) MSB: V $\leftarrow$ 0		×	×			
		reg,CL	1 1 0 1 0 0 1 W	1 1 0 1 1 reg	2	The following operations are repeated while temp $\leftarrow$ CL and temp $\neq$ 0. tmpcy $\leftarrow$ CY, CY $\leftarrow$ reg LSB reg $\leftarrow$ reg $\div$ 2 reg MSB $\leftarrow$ tmpcy temp $\leftarrow$ temp $-$ 1		×	U			
		mem,CL	1 1 0 1 0 0 1 W	mod 0 1 1 mem	2 to 4	The following operations are repeated while temp $\leftarrow$ CL and temp $\neq$ 0. tmpcy $\leftarrow$ CY, CY $\leftarrow$ (mem) LSB (mem) $\leftarrow$ (mem) $\div$ 2 (mem) MSB $\leftarrow$ tmpcy temp $\leftarrow$ temp $-$ 1		×	U			
		reg,imm8	1 1 0 0 0 0 0 W	1 1 0 1 1 reg	3	The following operations are repeated while temp $\leftarrow$ imm8 and temp $\neq$ 0. tmpcy $\leftarrow$ CY, CY $\leftarrow$ reg LSB reg $\leftarrow$ reg $\div$ 2 reg MSB $\leftarrow$ tmpcy temp $\leftarrow$ temp $-$ 1		×	U			
		mem,imm8	1 1 0 0 0 0 0 W	mod 0 1 1 mem	3 to 5	The following operations are repeated while temp $\leftarrow$ imm8 and temp $\neq$ 0. tmpcy $\leftarrow$ CY, CY $\leftarrow$ (mem) LSB (mem) $\leftarrow$ (mem) $\div$ 2 (mem) MSB $\leftarrow$ tmpcy temp $\leftarrow$ temp $-$ 1		×	U			

Group	Mnemonic	Operand	Oper		Bytes	Operation	Flags					
			7 6 5 4 3 2 1 0	7 6 5 4 3 2 1 0			AC	CY	V	P	S	Z
Sub-routine control	CALL	near-proc	1 1 1 0 1 0 0 0		3	(SP - 1, SP - 2) ← PC, SP ← SP - 2 PC ← PC + disp						
		regptr16	1 1 1 1 1 1 1 1	1 1 0 1 0 reg	2	(SP - 1, SP - 2) ← PC, PC ← regptr16 SP ← SP - 2						
		memptr16	1 1 1 1 1 1 1 1	mod 0 1 0 mem	2 to 4	(SP - 1, SP - 2) ← PC, SP ← SP - 2 PC ← (memptr16)						
		far-proc	1 0 0 1 1 0 1 0		5	(SP - 1, SP - 2) ← PS, (SP - 3, SP - 4) ← PC SP ← SP - 4 PS ← seg, PC ← offset						
		memptr32	1 1 1 1 1 1 1 1	mod 0 1 1 mem	2 to 4	(SP - 1, SP - 2) ← PS, (SP - 3, SP - 4) ← PC SP ← SP - 4 PS ← (memptr32 + 2), PC ← (memptr32)						
	RET		1 1 0 0 0 0 1 1		1	PC ← (SP + 1, SP) SP ← SP + 2						
		pop-value	1 1 0 0 0 0 1 0		3	PC ← (SP + 1, SP) SP ← SP + 2, SP ← SP + pop-value						
			1 1 0 0 1 0 1 1		1	PC ← (SP + 1, SP) PS ← (SP + 3, SP + 2) SP ← SP + 4						
		pop-value	1 1 0 0 1 0 1 0		3	PC ← (SP + 1, SP) PS ← (SP + 3, SP + 2) SP ← SP + 4, SP ← SP + pop-value						

Phase-out/Discontinued

Phase-out/Discontinued

Group	Mnemonic	Operand	Operation Code		Bytes	Operation	Flags					
			7 6 5 4 3 2 1 0	7 6 5 4 3 2 1 0			AC	CY	V	P	S	Z
Stack manipulation	PUSH	mem16	1 1 1 1 1 1 1 1	mod 1 1 0 mem	2 to 4	(SP – 1, SP – 2) ← (mem16) SP ← SP – 2						
		reg16	0 1 0 1 0 reg		1	(SP – 1, SP – 2) ← reg16 SP ← SP – 2						
		sreg	0 0 0 sreg 1 1 0		1	(SP – 1, SP – 2) ← sreg SP ← SP – 2						
		PSW	1 0 0 1 1 1 0 0		1	(SP – 1, SP – 2) ← PSW SP ← SP – 2						
		R	0 1 1 0 0 0 0 0		1	Push registers on the stack						
		imm8	0 1 1 0 1 0 1 0		2	(SP – 1, SP – 2) ← imm8 sign extension SP ← SP – 2						
		imm16	0 1 1 0 1 0 0 0		3	(SP – 1, SP – 2) ← imm16 SP ← SP – 2						
	POP	mem16	1 0 0 0 1 1 1 1	mod 0 0 0 mem	2 to 4	SP ← SP + 2 (mem16) ← (SP – 1, SP – 2)						
		reg16	0 1 0 1 1 reg		1	SP ← SP + 2 reg16 ← (SP – 1, SP – 2)						
		sreg	0 0 0 sreg 1 1 1		1	SP ← SP + 2 sreg ← (SP – 1, SP – 2) sreg: SS, DS0, DS1						
		PSW	1 0 0 1 1 1 0 1		1	SP ← SP + 2 PSW ← (SP – 1, SP – 2)	R	R	R	R	R	R
		R	0 1 1 0 0 0 0 1		1	Pop registers from the stack						
	PREPARE	imm16,imm8	1 1 0 0 1 0 0 0		4	Prepare New Stack Frame						
	DISPOSE		1 1 0 0 1 0 0 1		1	Dispose of Stack Frame						
Branch	BR	near-label	1 1 1 0 1 0 0 1		3	PC ← PC + disp						
		short-label	1 1 1 0 1 0 1 1		2	PC ← PC + ext-disp8						
		regptr16	1 1 1 1 1 1 1 1	1 1 1 0 0 reg	2	PC ← regptr16						
		memptr16	1 1 1 1 1 1 1 1	mod 1 0 0 mem	2 to 4	PC ← (memptr16)						
		far-label	1 1 1 0 1 0 1 0		5	PS ← seg PC ← offset						
		memptr32	1 1 1 1 1 1 1 1	mod 1 0 1 mem	2 to 4	PS ← (memptr32 + 2) PC ← (memptr32)						

Group	Mnemonic	Operand	Operation										Flags													
			7	6	5	4	3	2	1	0	7	6	5	4	3	2	1	0	Bytes	Operation		AC	CY	V	P	S
Conditional branch	BV	short-label	0	1	1	1	0	0	0	0								2	if V = 1	PC ← PC + ext-disp8						
	BNV	short-label					0	0	0	1								2	if V = 0	PC ← PC + ext-disp8						
	BC BL	short-label					0	0	1	0								2	if CY = 1	PC ← PC + ext-disp8						
	BNC BNL	short-label					0	0	1	1								2	if CY = 0	PC ← PC + ext-disp8						
	BE BZ	short-label					0	1	0	0								2	if Z = 1	PC ← PC + ext-disp8						
	BNE BNZ	short-label					0	1	0	1								2	if Z = 0	PC ← PC + ext-disp8						
	BNH	short-label					0	1	1	0								2	if CY ∨ Z = 1	PC ← PC + ext-disp8						
	BH	short-label					0	1	1	1								2	if CY ∨ Z = 0	PC ← PC + ext-disp8						
	BN	short-label					1	0	0	0								2	if S = 1	PC ← PC + ext-disp8						
	BP	short-label					1	0	0	1								2	if S = 0	PC ← PC + ext-disp8						
	BPE	short-label					1	0	1	0								2	if P = 1	PC ← PC + ext-disp8						
	BPO	short-label					1	0	1	1								2	if P = 0	PC ← PC + ext-disp8						
	BLT	short-label					1	1	0	0								2	if S ∨ V = 1	PC ← PC + ext-disp8						
	BGE	short-label					1	1	0	1								2	if S ∨ V = 0	PC ← PC + ext-disp8						
	BLE	short-label					1	1	1	0								2	if (S ∨ V) ∨ Z = 1	PC ← PC + ext-disp8						
	BGT	short-label					1	1	1	1								2	if (S ∨ V) ∨ Z = 0	PC ← PC + ext-disp8						
	DBNZNE	short-label		1	1	1	0	0	0	0	0							2	CW = CW − 1 if Z = 0 and CW ≠ 0	PC ← PC + ext-disp8						
	DBNZE	short-label					0	0	0	1								2	CW = CW − 1 if Z = 1 and CW ≠ 0	PC ← PC + ext-disp8						
	DBNZ	short-label					0	0	1	0								2	CW = CW − 1 if CW ≠ 0	PC ← PC + ext-disp8						
	BCWZ	short-label					0	0	1	1								2	if CW = 0	PC ← PC + ext-disp8						
	BTCLR ^{Note}	sfr, imm3, short-label		0	0	0	0	1	1	1	1	1	0	0	1	1	1	0	5	When (sfr) bit No. imm3 = 1, PC ← PC + ext-disp8 and (sfr) bit No. imm3 ← 0.						

Note This instruction is newly added to the μPD70108/70116.

Phase-out/Discontinued

Phase-out/Discontinued

Group	Mnemonic	Operand	Operation Code		Bytes	Operation	Flags					
			7 6 5 4 3 2 1 0	7 6 5 4 3 2 1 0			AC	CY	V	P	S	Z
Interrupt	BRK	3	1 1 0 0 1 1 0 0		1	(SP - 1, SP - 2) ← PSW, (SP - 3, SP - 4) ← PS, (SP - 5, SP - 6) ← PC, SP ← SP - 6 IE ← 0, BRK ← 0 PS ← (15, 14), PC ← (13, 12)						
		imm8 (≠ 3)	1 1 0 0 1 1 0 1		2	(SP - 1, SP - 2) ← PSW, (SP - 3, SP - 4) ← PS, (SP - 5, SP - 6) ← PC, SP ← SP - 6 IE ← 0, BRK ← 0 PS ← (n × 4 + 3, n × 4 + 2), PC ← (n × 4 + 1, n × 4) n = imm8						
	BRKV		1 1 0 0 1 1 1 0		1	When V = 1, (SP - 1, SP - 2) ← PSW, (SP - 3, SP - 4) ← PS, (SP - 5, SP - 6) ← PC, SP ← SP - 6 IE ← 0, BRK ← 0 PS ← (19, 18), PC ← (17, 16)						
	RETI		1 1 0 0 1 1 1 1		1	PC ← (SP + 1, SP), PS ← (SP + 3, SP + 2), PSW ← (SP + 5, SP + 4), SP ← SP + 6	R	R	R	R	R	R
	RETRB ^{Note}		0 0 0 0 1 1 1 1	1 0 0 1 0 0 0 1	2	PC ← Save PC, PSW ← Save PSW	R	R	R	R	R	R
	FINT ^{Note}		0 0 0 0 1 1 1 1	1 0 0 1 0 0 1 0	2	Reports the CPU internal interrupt controller that interrupt service routine operation has ended.						
	CHKIND	reg16, mem32	0 1 1 0 0 0 1 0	mod reg mem	2 to 4	When (mem32) > reg16 or (mem32 + 2) < reg16, (SP - 1, SP - 2) ← PSW, (SP - 3, SP - 4) ← PS, (SP - 5, SP - 6) ← PC, SP ← SP - 6 IE ← 0, BRK ← 0 PS ← (23, 22), PC ← (21, 20)						
Register bank switch	BRKCS ^{Note}	reg16	0 0 0 0 1 1 1 1	0 0 1 0 1 1 0 1	3	RB2 - 0 ← lower 3 bits of reg16, IE ← 0, BRK ← 0 Save PSW ← PSW, Save PC ← PC, PC ← Vector PC						
			1 1 0 0 0 reg									
	TSKSW ^{Note}	reg16	0 0 0 0 1 1 1 1	1 0 0 1 0 1 0 0	3	RB2 - 0 ← lower 3 bits of reg16, Old register bank Save PSW and Save PC ← PSW and PC, PSW and PC ← New register bank Save PSW and Save PC	×	×	×	×	×	×
			1 1 1 1 1 reg									

Note These instructions are newly added to the μ PD70108/70116.

Group	Mnemonic	Operand	Operation		Bytes	Operation	Flags					
			7 6 5 4 3 2 1 0	7 6 5 4 3 2 1 0			AC	CY	V	P	S	Z
CPU control	HALT		1 1 1 1 0 1 0 0		1	CPU Halt						
	STOP Note 2		0 0 0 0 1 1 1 1	1 0 0 1 1 1 1 0	2	CPU Stop						
	POLL		1 0 0 1 1 0 1 1		1	Poll and wait						
	DI		1 1 1 1 1 0 1 0		1	IE ← 0						
	EI		1 1 1 1 1 0 1 1		1	IE ← 1						
	BUSLOCK		1 1 1 1 0 0 0 0		1	Bus Lock Prefix						
	FPO1	fp-op	1 1 0 1 1 X X X	1 1 Y Y Y Z Z Z	2	No Operation						
		Note 3 fp-op,mem	1 1 0 1 1 X X X	mod Y Y Y mem	2 to 4	data bus ← (mem)						
	FPO2	fp-op	0 1 1 0 0 1 1 X	1 1 Y Y Y Z Z Z	2	No Operation						
		Note 3 fp-op,mem	0 1 1 0 0 1 1 X	mod Y Y Y mem	2 to 4	data bus ← (mem)						
	NOP		1 0 0 1 0 0 0 0		1	No Operation						
	Note 1		0 0 1 sreg 1 1 0		1	Segment override prefix						

Notes 1. DS0:, DS1:, PS: and SS:

2. This instruction is newly added to the μ PD70108/70116.

3. In the μ PD70320, an interrupt is generated without executing these instructions.

Table 2-8. Number of Clocks (1/10)

Group	Mnemonic	Operands	Byte Processing		Word Processing	
			On-chip RAM Access Enable	On-chip RAM Access Disable	On-chip RAM Access Enable	On-chip RAM Access Disable
Data transfer	MOV	reg, reg	2	2	2	2
		mem, reg	$EA + 4 + T$	$EA + 2$	$EA + 6 + 2 \cdot T$	$EA + 2$
		reg, mem	$EA + 6 + T$	$EA + 6 + T$	$EA + 8 + 2 \cdot T$	$EA + 8 + 2 \cdot T$
		mem, imm	$EA + 5 + T$	$EA + 5 + T$	$EA + 5 + 2 \cdot T$	$EA + 5 + T$
		reg, imm	5	5	6	6
		acc, dmem	$9 + T$	$9 + T$	$11 + 2 \cdot T$	$11 + 2 \cdot T$
		dmem, acc	$7 + T$	5	$9 + 2 \cdot T$	5
		sreg, reg16	—	—	4	4
		sreg, mem16	—	—	$EA + 10 + 2 \cdot T$	$EA + 10 + 2 \cdot T$
		reg16, sreg	—	—	3	3
		mem16, sreg	—	—	$EA + 7 + 2 \cdot T$	$EA + 3$
		DS0, reg16, mem32	—	—	$EA + 19 + 4 \cdot T$	$EA + 19 + 4 \cdot T$
		DS1, reg16, mem32	—	—	$EA + 19 + 4 \cdot T$	$EA + 19 + 4 \cdot T$
		AH, PSW	2	2	—	—
		PSW, AH	3	3	—	—
	LDEA	reg16, mem16	—	—	$EA + 2$	$EA + 2$
	TRANS	src-table	$10 + T$	$10 + T$	—	—
	XCH	reg, reg	3	3	3	3
		mem, reg/ reg, mem	$EA + 10 + 2 \cdot T$	$EA + 8 + 2 \cdot T$	$EA + 14 + 2 \cdot T$	$EA + 10 + 2 \cdot T$
		AW, reg16/ reg16, AW	—	—	4	4
	MOVSPA		—	—	16	16
	MOVSPB	reg16	—	—	11	11
Repeat prefix	REPC		2	2	2	2
	REPNC		2	2	2	2
	REP/REPE/ REPZ		2	2	2	2
	REPNE/ REPNZ		2	2	2	2
Primitive block transfer	MOVKB ^{Note}	dst-block, src-block	$20 + 2 \cdot T$	$16 + T$	$24 + 4 \cdot T$	$20 + 2 \cdot T$
			$16 + (16 + 2 \cdot T) \cdot n$	$16 + (12 + T) \cdot n$	$16 + (20 + 4 \cdot T) \cdot n$	$16 + (12 + 2 \cdot T) \cdot n$
	CMPKB ^{Note}	dst-block, src-block	$23 + 2 \cdot T$	$19 + T$	$27 + 4 \cdot T$	$21 + 4 \cdot T$
			$16 + (21 + 2 \cdot T) \cdot n$	$16 + (21 + 2 \cdot T) \cdot n$	$16 + (25 + 4 \cdot T) \cdot n$	$16 + (25 + 2 \cdot T) \cdot n$

Note $n \geq 1$

Table 2-8. Number of Clocks (2/10)

Group	Mnemonic	Operands	Byte Processing		Word Processing	
			On-chip RAM Access Enable	On-chip RAM Access Disable	On-chip RAM Access Enable	On-chip RAM Access Disable
Primitive block transfer	CMPM ^{Note 1}	dst-block	$17 + T$	$17 + T$	$19 + 2 \cdot T$	$19 + 2 \cdot T$
		src-block	$16 + (15 + T) \cdot n$	$16 + (15 + T) \cdot n$	$16 + (17 + 2 \cdot T) \cdot n$	$16 + (17 + 2 \cdot T) \cdot n$
	LDM ^{Note 1}	src-block	$12 + T$	$12 + T$	$14 + 2 \cdot T$	$14 + 2 \cdot T$
			$16 + (10 + T) \cdot n$	$16 + (10 + T) \cdot n$	$16 + (12 + 2 \cdot T) \cdot n$	$16 + (12 + 2 \cdot T) \cdot n$
	STM ^{Note 1}	dst-block	$12 + T$	10	$14 + 2 \cdot T$	10
			$16 + (8 + T) \cdot n$	$16 + (6 + T) \cdot n$	$16 + (10 + 2 \cdot T) \cdot n$	$16 + (6 + 2 \cdot T) \cdot n$
Bit field manipula- tion	INS	reg8, reg8	63 to 155 (The processing differs among bit lengths.)			
		reg8, imm4	64 to 156 (The processing differs among bit lengths.)			
	EXT	reg8, reg8	41 to 121 (The processing differs among bit lengths.)			
		reg8, imm4	42 to 122 (The processing differs among bit lengths.)			
I/O	IN ^{Note 2}	acc, imm8	$14 + T$	$14 + T$	$16 + 2 \cdot T$	$16 + 2 \cdot T$
		acc, DW	$13 + T$	$13 + T$	$15 + 2 \cdot T$	$15 + 2 \cdot T$
	OUT ^{Note 2}	imm8, acc	$10 + T$	$10 + T$	$10 + 2 \cdot T$	$10 + 2 \cdot T$
		DW, acc	$9 + T$	$9 + T$	$9 + 2 \cdot T$	$9 + 2 \cdot T$
Primitive I/O	INM ^{Note 2}	dst-block, DW	$19 + 2 \cdot T$	$17 + 2 \cdot T$	$21 + 4 \cdot T$	$17 + 4 \cdot T$
			$18 + (13 + 2 \cdot T) \cdot n$	$18 + (11 + 2 \cdot T) \cdot n$	$18 + (15 + 4 \cdot T) \cdot n$	$18 + (11 + 4 \cdot T) \cdot n$
	OUTM ^{Note 2}	DW, src-block	$19 + 2 \cdot T$	$17 + 2 \cdot T$	$21 + 4 \cdot T$	$17 + 4 \cdot T$
			$18 + (13 + 2 \cdot T) \cdot n$	$18 + (11 + 2 \cdot T) \cdot n$	$18 + (15 + 4 \cdot T) \cdot n$	$18 + (11 + 4 \cdot T) \cdot n$
Addition/ subtraction	ADD	reg, reg	2	2	2	2
		mem, reg	$EA + 8 + 2 \cdot T$	$EA + 6 + T$	$EA + 12 + 4 \cdot T$	$EA + 8 + 2 \cdot T$
		reg, mem	$EA + 6 + T$	$EA + 6 + T$	$EA + 8 + 2 \cdot T$	$EA + 8 + 2 \cdot T$
		reg, imm	5	5	6	6
		mem, imm	$EA + 9 + 2 \cdot T$	$EA + 7 + 2 \cdot T$	$EA + 14 + 4 \cdot T$	$EA + 10 + 4 \cdot T$
		acc, imm	5	5	6	6
	ADDC	reg, reg	2	2	2	2
		mem, reg	$EA + 8 + 2 \cdot T$	$EA + 6 + T$	$EA + 12 + 4 \cdot T$	$EA + 8 + 2 \cdot T$
		reg, mem	$EA + 6 + T$	$EA + 6 + T$	$EA + 8 + 2 \cdot T$	$EA + 8 + 2 \cdot T$
		reg, imm	5	5	6	6
		mem, imm	$EA + 9 + 2 \cdot T$	$EA + 7 + 2 \cdot T$	$EA + 14 + 4 \cdot T$	$EA + 10 + 4 \cdot T$
		acc, imm	5	5	6	6

- Notes 1. $n \geq 1$
2. When $\overline{\text{IBRK}} = 1$

Table 2-8. Number of Clocks (3/10)

Group	Mnemonic	Operands	Byte Processing		Word Processing	
			On-chip RAM Access Enable	On-chip RAM Access Disable	On-chip RAM Access Enable	On-chip RAM Access Disable
Addition/ subtraction	SUB	reg, reg	2	2	2	2
		mem, reg	$EA + 8 + 2 \cdot T$	$EA + 6 + T$	$EA + 12 + 4 \cdot T$	$EA + 8 + 2 \cdot T$
		reg, mem	$EA + 6 + T$	$EA + 6 + T$	$EA + 8 + 2 \cdot T$	$EA + 8 + 2 \cdot T$
		reg, imm	5	5	6	6
		mem, imm	$EA + 9 + 2 \cdot T$	$EA + 7 + 2 \cdot T$	$EA + 14 + 4 \cdot T$	$EA + 10 + 4 \cdot T$
		acc, imm	5	5	6	6
	SUBC	reg, reg	2	2	2	2
		mem, reg	$EA + 8 + 2 \cdot T$	$EA + 6 + T$	$EA + 12 + 4 \cdot T$	$EA + 8 + 2 \cdot T$
		reg, mem	$EA + 6 + T$	$EA + 6 + T$	$EA + 8 + 2 \cdot T$	$EA + 8 + 2 \cdot T$
		reg, imm	5	5	6	6
		mem, imm	$EA + 9 + 2 \cdot T$	$EA + 7 + 2 \cdot T$	$EA + 14 + 4 \cdot T$	$EA + 10 + 4 \cdot T$
		acc, imm	5	5	6	6
BCD operation	ADD4S ^{Note}		$22 + (27 + 3 \cdot T) \cdot n$	$22 + (25 + 3 \cdot T) \cdot n$	—	—
	SUB4S ^{Note}		$22 + (27 + 3 \cdot T) \cdot n$	$22 + (25 + 3 \cdot T) \cdot n$	—	—
	CMP4S ^{Note}		$22 + (23 + 3 \cdot T) \cdot n$	$22 + (23 + 3 \cdot T) \cdot n$	—	—
	ROL4	reg8	17	17	—	—
		mem8	$EA + 18 + 2 \cdot T$	$EA + 16 + 2 \cdot T$	—	—
	ROR4	reg8	21	21	—	—
		mem8	$EA + 24 + 2 \cdot T$	$EA + 22 + 2 \cdot T$	—	—
Increment/ decrement	INC	reg8	5	5	—	—
		mem8	$EA + 11 + 2 \cdot T$	$EA + 9 + 2 \cdot T$	$EA + 15 + 4 \cdot T$	$EA + 11 + 4 \cdot T$
		reg16	—	—	2	2
	DEC	reg8	5	5	—	—
		mem8	$EA + 11 + 2 \cdot T$	$EA + 9 + 2 \cdot T$	$EA + 15 + 4 \cdot T$	$EA + 11 + 4 \cdot T$
		reg16	—	—	2	2
Multiplica- tion	MULU	reg8	24	24	—	—
		mem8	$EA + 26 + T$	$EA + 26 + T$	—	—
		reg16	—	—	32	32
		mem16	—	—	$EA + 34 + 2 \cdot T$	$EA + 34 + 2 \cdot T$

Note n: 1/2 of the number of BCD digits.

Table 2-8. Number of Clocks (4/10)

Group	Mnemonic	Operands	Byte Processing		Word Processing	
			On-chip RAM Access Enable	On-chip RAM Access Disable	On-chip RAM Access Enable	On-chip RAM Access Disable
Multiplication	MUL	reg8	31 to 40	31 to 40	—	—
		mem8	EA + 33 + T to EA + 42 + T	EA + 33 + T to EA + 42 + T	—	—
		reg16	—	—	39 to 48	39 to 48
		mem16	—	—	EA + 43 + 2·T to EA + 52 + 2·T	EA + 43 + 2·T to EA + 52 + 2·T
		reg16, (reg16,) imm8	—	—	39 to 49	39 to 49
		reg16, mem16, imm8	—	—	EA + 43 + 2·T to EA + 53 + 2·T	EA + 43 + 2·T to EA + 53 + 2·T
		reg16, (reg16,) imm16	—	—	40 to 50	40 to 50
		reg16, mem16, imm16	—	—	EA + 44 + 2·T to EA + 54 + 2·T	EA + 44 + 2·T to EA + 54 + 2·T
Unsigned division	DIVU	reg8	31	31	—	—
		mem8	EA + 33 + T	EA + 33 + T	—	—
		reg16	—	—	39	39
		mem16	—	—	EA + 43 + 2·T	EA + 43 + 2·T
Signed division	DIV	reg8	46 to 56	46 to 56	—	—
		mem8	EA + 48 + T to EA + 58 + T	EA + 48 + T to EA + 58 + T	—	—
		reg16	—	—	54 to 64	54 to 64
		mem16	—	—	EA + 58 + 2·T to EA + 68 + 2·T	EA + 58 + 2·T to EA + 68 + 2·T
BCD adjustment	ADJBA		17	17	—	—
	ADJ4A		9	9	—	—
	ADJBS		17	17	—	—
	ADJ4S		9	9	—	—
Data conversion	CVTBD		19	19	—	—
	CVTDB		20	20	—	—
	CVTBW		3	3	—	—
	CVTWL		—	—	8	8
Compare	CMP	reg, reg	2	2	2	2
		mem, reg	EA + 6 + T	EA + 6 + T	EA + 8 + 2·T	EA + 8 + 2·T
		reg, mem	EA + 6 + T	EA + 6 + T	EA + 8 + 2·T	EA + 8 + 2·T
		reg, imm	5	5	6	6
		mem, imm	EA + 7 + T	EA + 7 + T	EA + 10 + 2·T	EA + 10 + 2·T
		acc, imm	5	5	6	6

Table 2-8. Number of Clocks (5/10)

Group	Mnemonic	Operands	Byte Processing		Word Processing	
			On-chip RAM Access Enable	On-chip RAM Access Disable	On-chip RAM Access Enable	On-chip RAM Access Disable
Comple ment operation	NOT	reg	5	5	5	5
		mem	$EA + 11 + 2 \cdot T$	$EA + 9 + T$	$EA + 15 + 4 \cdot T$	$EA + 11 + 2 \cdot T$
	NEG	reg	5	5	5	5
		mem	$EA + 11 + 2 \cdot T$	$EA + 9 + T$	$EA + 15 + 4 \cdot T$	$EA + 11 + 2 \cdot T$
Logical operation	TEST	reg, reg	4	4	4	4
		mem, reg/ reg, mem	$EA + 8 + T$	$EA + 8 + T$	$EA + 10 + 2 \cdot T$	$EA + 10 + 2 \cdot T$
		reg, imm	7	7	8	8
		mem, imm	$EA + 11 + T$	$EA + 11 + T$	$EA + 11 + 2 \cdot T$	$EA + 11 + 2 \cdot T$
		acc, imm	5	5	6	6
	AND	reg, reg	2	2	2	2
		mem, reg	$EA + 8 + 2 \cdot T$	$EA + 6 + T$	$EA + 12 + 4 \cdot T$	$EA + 8 + 2 \cdot T$
		reg, mem	$EA + 6 + T$	$EA + 6 + T$	$EA + 8 + 2 \cdot T$	$EA + 8 + 2 \cdot T$
		reg, imm	5	5	6	6
		mem, imm	$EA + 9 + T$	$EA + 7 + T$	$EA + 14 + 4 \cdot T$	$EA + 10 + 4 \cdot T$
		acc, imm	5	5	6	6
	OR	reg, reg	2	2	2	2
		mem, reg	$EA + 8 + 2 \cdot T$	$EA + 6 + T$	$EA + 12 + 4 \cdot T$	$EA + 8 + 2 \cdot T$
		reg, mem	$EA + 6 + T$	$EA + 6 + T$	$EA + 8 + 2 \cdot T$	$EA + 8 + 2 \cdot T$
		reg, imm	5	5	6	6
		mem, imm	$EA + 9 + T$	$EA + 7 + T$	$EA + 14 + 4 \cdot T$	$EA + 10 + 4 \cdot T$
		acc, imm	5	5	6	6
	XOR	reg, reg	2	2	2	2
		mem, reg	$EA + 8 + 2 \cdot T$	$EA + 6 + T$	$EA + 12 + 4 \cdot T$	$EA + 8 + 2 \cdot T$
		reg, mem	$EA + 6 + T$	$EA + 6 + T$	$EA + 8 + 2 \cdot T$	$EA + 8 + 2 \cdot T$
		reg, imm	5	5	6	6
		mem, imm	$EA + 9 + T$	$EA + 7 + T$	$EA + 14 + 4 \cdot T$	$EA + 10 + 4 \cdot T$
		acc, imm	5	5	6	6
Bit manipula- tion	TEST1	reg8, CL	7	7	—	—
		mem8, CL	$EA + 11 + T$	$EA + 11 + T$	—	—
		reg16, CL	—	—	7	7
		mem16, CL	—	—	$EA + 13 + 2 \cdot T$	$EA + 13 + 2 \cdot T$
		reg8, imm3	6	6	—	—
		mem8, imm3	$EA + 8 + T$	$EA + 8 + T$	—	—
		reg16, imm4	—	—	6	6
		mem16, imm4	—	—	$EA + 10 + 2 \cdot T$	$EA + 10 + 2 \cdot T$
	NOT1	reg8, CL	7	7	—	—
		mem8, CL	$EA + 13 + 2 \cdot T$	$EA + 11 + T$	—	—
		reg16, CL	—	—	7	7

Table 2-8. Number of Clocks (6/10)

Group	Mnemonic	Operands	Byte Processing		Word Processing	
			On-chip RAM Access Enable	On-chip RAM Access Disable	On-chip RAM Access Enable	On-chip RAM Access Disable
Bit manipula- tion	NOT1	mem16, CL	—	—	EA + 17 + 4·T	EA + 13 + 2·T
		reg8, imm3	6	6	—	—
		mem8, imm3	EA + 10 + 2·T	EA + 8 + T	—	—
		reg16, imm4	—	—	6	6
		mem16, imm4	—	—	EA + 14 + 4·T	EA + 10 + 2·T
	NOT1	CY	2	2	2	2
Bit manipula- tion	CLR1	reg8, CL	8	8	—	—
		mem8, CL	EA + 14 + 2·T	EA + 12 + T	—	—
		reg16, CL	—	—	8	8
		mem16, CL	—	—	EA + 18 + 4·T	EA + 14 + 2·T
		reg8, imm3	7	7	—	—
		mem8, imm3	EA + 11 + 2·T	EA + 9 + T	—	—
		reg16, imm4	—	—	7	7
		mem16, imm4	—	—	EA + 15 + 4·T	EA + 10 + 2·T
	SET1	reg8, CL	7	7	—	—
		mem8, CL	EA + 13 + 2·T	EA + 11 + T	—	—
		reg16, CL	—	—	7	7
		mem16, CL	—	—	EA + 17 + 4·T	EA + 13 + 2·T
		reg8, imm3	6	6	—	—
		mem8, imm3	EA + 10 + 2·T	EA + 8 + T	—	—
		reg16, imm4	—	—	6	6
		mem16, imm4	—	—	EA + 14 + 4·T	EA + 10 + 2·T
	CLR1	CY	2	2	2	2
		DIR	2	2	2	2
	SET1	CY	2	2	2	2
		DIR	2	2	2	2
Shift	SHL	reg,1	8	8	8	8
		mem, 1	EA + 14 + 2·T	EA + 12 + T	EA + 18 + 4·T	EA + 14 + 2·T
		reg, CL	11 + 2·n	11 + 2·n	11 + 2·n	11 + 2·n
		mem, CL	EA + 17 + 2·T + 2·n	EA + 15 + T + 2·n	EA + 21 + 4·T + 2·n	EA + 17 + 2·T + 2·n
		reg, imm8	9 + 2·n	9 + 2·n	9 + 2·n	9 + 2·n
		mem, imm8	EA + 13 + 2·T + 2·n	EA + 11 + T + 2·n	EA + 17 + 4·T + 2·n	EA + 13 + 2·T + 2·n
	SHR	reg, 1	8	8	8	8
		mem, 1	EA + 14 + 2·T	EA + 12 + T	EA + 18 + 4·T	EA + 14 + 2·T

Note n: Shift count

Table 2-8. Number of Clocks (7/10)

Group	Mnemonic	Operands	Byte Processing		Word Processing	
			On-chip RAM Access Enable	On-chip RAM Access Disable	On-chip RAM Access Enable	On-chip RAM Access Disable
Shift	SHR	reg, CL	$11 + 2 \cdot n$	$11 + 2 \cdot n$	$11 + 2 \cdot n$	$11 + 2 \cdot n$
		Note mem, CL	$EA + 17 + 2 \cdot T + 2 \cdot n$	$EA + 15 + T + 2 \cdot n$	$EA + 21 + 4 \cdot T + 2 \cdot n$	$EA + 17 + 2 \cdot T + 2 \cdot n$
		reg, imm8	$9 + 2 \cdot n$	$9 + 2 \cdot n$	$9 + 2 \cdot n$	$9 + 2 \cdot n$
		mem, imm8	$EA + 13 + 2 \cdot T + 2 \cdot n$	$EA + 11 + T + 2 \cdot n$	$EA + 17 + 4 \cdot T + 2 \cdot n$	$EA + 13 + 2 \cdot T + 2 \cdot n$
	SHRA	reg, 1	8	8	8	8
		Note mem, 1	$EA + 14 + 2 \cdot T$	$EA + 12 + T$	$EA + 18 + 4 \cdot T$	$EA + 14 + 2 \cdot T$
		reg, CL	$11 + 2 \cdot n$	$11 + 2 \cdot n$	$11 + 2 \cdot n$	$11 + 2 \cdot n$
		mem, CL	$EA + 17 + 2 \cdot T + 2 \cdot n$	$EA + 15 + T + 2 \cdot n$	$EA + 21 + 4 \cdot T + 2 \cdot n$	$EA + 17 + 2 \cdot T + 2 \cdot n$
		reg, imm8	$9 + 2 \cdot n$	$9 + 2 \cdot n$	$9 + 2 \cdot n$	$9 + 2 \cdot n$
		mem, imm8	$EA + 13 + 2 \cdot T + 2 \cdot n$	$EA + 11 + T + 2 \cdot n$	$EA + 17 + 4 \cdot T + 2 \cdot n$	$EA + 13 + 2 \cdot T + 2 \cdot n$
Rotate	ROL	reg, 1	8	8	8	8
		Note mem, 1	$EA + 14 + 2 \cdot T$	$EA + 12 + T$	$EA + 18 + 4 \cdot T$	$EA + 14 + 2 \cdot T$
		reg, CL	$11 + 2 \cdot n$	$11 + 2 \cdot n$	$11 + 2 \cdot n$	$11 + 2 \cdot n$
		mem, CL	$EA + 17 + 2 \cdot T + 2 \cdot n$	$EA + 15 + T + 2 \cdot n$	$EA + 21 + 4 \cdot T + 2 \cdot n$	$EA + 17 + 2 \cdot T + 2 \cdot n$
		reg, imm8	$9 + 2 \cdot n$	$9 + 2 \cdot n$	$9 + 2 \cdot n$	$9 + 2 \cdot n$
		mem, imm8	$EA + 13 + 2 \cdot T + 2 \cdot n$	$EA + 11 + T + 2 \cdot n$	$EA + 17 + 4 \cdot T + 2 \cdot n$	$EA + 13 + 2 \cdot T + 2 \cdot n$
	ROR	reg, 1	8	8	8	8
		Note mem, 1	$EA + 14 + 2 \cdot T$	$EA + 12 + T$	$EA + 18 + 4 \cdot T$	$EA + 14 + 2 \cdot T$
		reg, CL	$11 + 2 \cdot n$	$11 + 2 \cdot n$	$11 + 2 \cdot n$	$11 + 2 \cdot n$
		mem, CL	$EA + 17 + 2 \cdot T + 2 \cdot n$	$EA + 15 + T + 2 \cdot n$	$EA + 21 + 4 \cdot T + 2 \cdot n$	$EA + 17 + 2 \cdot T + 2 \cdot n$
		reg, imm8	$9 + 2 \cdot n$	$9 + 2 \cdot n$	$9 + 2 \cdot n$	$9 + 2 \cdot n$
		mem, imm8	$EA + 13 + 2 \cdot T + 2 \cdot n$	$EA + 11 + T + 2 \cdot n$	$EA + 17 + 4 \cdot T + 2 \cdot n$	$EA + 13 + 2 \cdot T + 2 \cdot n$
	ROLC	reg, 1	8	8	8	8
		Note mem, 1	$EA + 14 + 2 \cdot T$	$EA + 12 + T$	$EA + 18 + 4 \cdot T$	$EA + 14 + 2 \cdot T$
		reg, CL	$11 + 2 \cdot n$	$11 + 2 \cdot n$	$11 + 2 \cdot n$	$11 + 2 \cdot n$
		mem, CL	$EA + 17 + 2 \cdot T + 2 \cdot n$	$EA + 15 + T + 2 \cdot n$	$EA + 21 + 4 \cdot T + 2 \cdot n$	$EA + 17 + 2 \cdot T + 2 \cdot n$
		reg, imm8	$9 + 2 \cdot n$	$9 + 2 \cdot n$	$9 + 2 \cdot n$	$9 + 2 \cdot n$
		mem, imm8	$EA + 13 + 2 \cdot T + 2 \cdot n$	$EA + 11 + T + 2 \cdot n$	$EA + 17 + 4 \cdot T + 2 \cdot n$	$EA + 13 + 2 \cdot T + 2 \cdot n$
	RORC	reg, 1	8	8	8	8
		mem, 1	$EA + 14 + 2 \cdot T$	$EA + 12 + T$	$EA + 18 + 4 \cdot T$	$EA + 14 + 2 \cdot T$

Note n: Shift count

Table 2-8. Number of Clocks (8/10)

Group	Mnemonic	Operands	Byte Processing		Word Processing	
			On-chip RAM Access Enable	On-chip RAM Access Disable	On-chip RAM Access Enable	On-chip RAM Access Disable
Rotate	RORC	reg, CL	$11 + 2 \cdot n$	$11 + 2 \cdot n$	$11 + 2 \cdot n$	$11 + 2 \cdot n$
		mem, CL	$EA + 17 + 2 \cdot T + 2 \cdot n$	$EA + 15 + T + 2 \cdot n$	$EA + 21 + 4 \cdot T + 2 \cdot n$	$EA + 17 + 2 \cdot T + 2 \cdot n$
		reg, imm8	$9 + 2 \cdot n$	$9 + 2 \cdot n$	$9 + 2 \cdot n$	$9 + 2 \cdot n$
		mem, imm8	$EA + 13 + 2 \cdot T + 2 \cdot n$	$EA + 11 + T + 2 \cdot n$	$EA + 17 + 4 \cdot T + 2 \cdot n$	$EA + 13 + 2 \cdot T + 2 \cdot n$
Subroutine control	CALL	near-proc	—	—	$22 + 2 \cdot T$	$18 + 2 \cdot T$
		regptr16	—	—	$22 + 2 \cdot T$	$18 + 2 \cdot T$
		memptr16	—	—	$EA + 26 + 4 \cdot T$	$EA + 24 + 4 \cdot T$
		far-proc	—	—	$38 + 4 \cdot T$	$34 + 4 \cdot T$
		memptr32	—	—	$EA + 36 + 8 \cdot T$	$EA + 24 + 8 \cdot T$
	RET		—	—	$20 + 2 \cdot T$	$20 + 2 \cdot T$
		pop-value	—	—	$20 + 2 \cdot T$	$20 + 2 \cdot T$
			—	—	$29 + 4 \cdot T$	$29 + 4 \cdot T$
		pop-value	—	—	$30 + 4 \cdot T$	$30 + 4 \cdot T$
Stack manipula- tion	PUSH	mem16	—	—	$EA + 18 + 4 \cdot T$	$EA + 14 + 4 \cdot T$
		reg16	—	—	$10 + 2 \cdot T$	6
		sreg	—	—	$11 + 2 \cdot T$	7
		PSW	—	—	$10 + 2 \cdot T$	6
		R	—	—	$82 + 16 \cdot T$	50
		imm8	—	—	$13 + 2 \cdot T$	9
		imm16	—	—	$14 + 2 \cdot T$	10
	POP	mem16	—	—	$EA + 16 + 4 \cdot T$	$EA + 12 + 2 \cdot T$
		reg16	—	—	$12 + 2 \cdot T$	$12 + 2 \cdot T$
		sreg	—	—	$13 + 2 \cdot T$	$13 + 2 \cdot T$
		PSW	—	—	$14 + 2 \cdot T$	$14 + 2 \cdot T$
		R	—	—	$82 + 16 \cdot T$	58
	PREPARE	imm16, imm8	When imm8 = 0, $27 + 2 \cdot T$ When imm8 = 1, $39 + 4 \cdot T$ When imm8 = n, $n > 1$, $46 + 19(n - 1) + 4 \cdot T$			
	DISPOSE		—	—	$12 + 2 \cdot T$	$12 + 2 \cdot T$

Note n: Shift count

Table 2-8. Number of Clocks (9/10)

Group	Mnemonic	Operands	Byte Processing		Word Processing	
			On-chip RAM Access Enable	On-chip RAM Access Disable	On-chip RAM Access Enable	On-chip RAM Access Disable
Branch	BR	near-label	—	—	12	12
		short-label	—	—	12	12
		regptr16	—	—	13	13
		memptr16	—	—	EA + 17 + 2·T	EA + 17 + 2·T
		far-label	—	—	15	15
		memptr32	—	—	EA + 25 + 4·T	EA + 25 + 4·T
Conditional branch	BV	short-label	—	—	15/8	15/8
	BNV	short-label	—	—	15/8	15/8
	BC/BL	short-label	—	—	15/8	15/8
	BNC/BNL	short-label	—	—	15/8	15/8
	BE/BZ	short-label	—	—	15/8	15/8
	BNE/BNZ	short-label	—	—	15/8	15/8
	BNH	short-label	—	—	15/8	15/8
	BH	short-label	—	—	15/8	15/8
	BN	short-label	—	—	15/8	15/8
	BP	short-label	—	—	15/8	15/8
	BPE	short-label	—	—	15/8	15/8
	BPO	short-label	—	—	15/8	15/8
	BLT	short-label	—	—	15/8	15/8
	BGE	short-label	—	—	15/8	15/8
	BLE	short-label	—	—	15/8	15/8
	BGT	short-label	—	—	15/8	15/8
	DBNZNE	short-label	—	—	17/8	17/8
	DBNZE	short-label	—	—	17/8	17/8
	DBNZ	short-label	—	—	17/8	17/8
	BCWZ	short-label	—	—	15/8	15/8
	BTCLR	sfr, imm3, short-label	29/21	29/21	—	—
Interrupt	BRK	3	—	—	55 + 10·T	43 + 10·T
		imm8 (≠3)	—	—	56 + 10·T	44 + 10·T
	BRKV		—	—	55 + 10·T	43 + 10·T
	RETI		—	—	45 + 6·T	37 + 2·T
	RETRBI		—	—	12	12
	FINT		2	2	2	2
	CHKIND	reg16, mem32	—	—	EA + 26 + 4·T	EA + 26 + 4·T

Table 2-8. Number of Clocks (10/10)

Group	Mnemonic	Operands	Byte Processing		Word Processing	
			On-chip RAM Access Enable	On-chip RAM Access Disable	On-chip RAM Access Enable	On-chip RAM Access Disable
Register bank switch	BRKCS	reg16	—	—	15	15
	TSKSW	reg16	—	—	20	20
CPU control	HALT		—	—	—	—
	STOP		—	—	—	—
	POLL		—	—	—	—
	DI		4	4	4	4
	EI		12	12	12	12
	BUSLOCK		2	2	2	2
	FPO1	fp-op	—	—	60 + 10·T	48 + 10·T
		fp-op, mem	—	—	60 + 10·T	48 + 10·T
	FPO2	fp-op	—	—	60 + 10·T	48 + 10·T
		fp-op, mem	—	—	60 + 10·T	48 + 10·T
	NOP		4	4	4	4
Segment override prefix (DS0:, DS1:, PS: and SS:)			2	2	2	2

3. ELECTRICAL SPECIFICATIONS

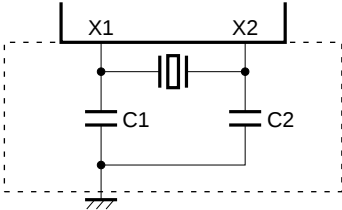
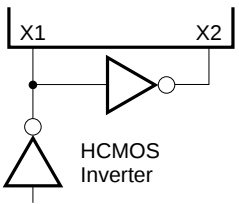
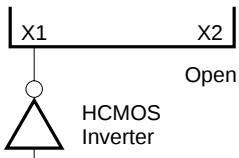
ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$)

Parameter	Symbol	Test Conditions	Rating	Unit
Supply Voltage	V_{DD}		- 0.5 to +7.0	V
Input Voltage	V_{TH}		- 0.5 to $V_{DD} + 0.5$	V
	V_I		- 0.5 to $V_{DD} + 0.5$	V
Output Voltage	V_O		- 0.5 to $V_{DD} + 0.5$	V
Output Current Low	I_{OL}	Each output pin	4.0	mA
		Total	50	mA
Output Current High	I_{OH}	Each output pin	-2.0	mA
		Total	-20	mA
Operating Ambient Temperature	T_A		-40 to +85	$^\circ\text{C}$
Storage Temperature	T_{stg}		- 65 to +150	$^\circ\text{C}$

- Cautions**
1. Do not make direct connections of the output (or input/output) pins of the IC product with each other, and also avoid direct connections to V_{DD} , V_{CC} or GND. However, the open drain pins or the open collector pins can be directly connected with each other. For the external circuit designed with the timing specifications so that any collision of the outputs from the pins subject to high-impedance state may be prevented, direct connection can be also made.
 2. Product quality may suffer if the absolute maximum ratings are exceeded for even a single parameter, or even momentarily. In other words, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions which ensure that the absolute maximum ratings are not exceeded. The normal operation and reliability of the product can be only assured with the specifications and the conditions indicated as the DC and AC characteristics.

★ OSCILLATOR CHARACTERISTICS

($T_A = -40$ to $+85^{\circ}\text{C}$, $V_{DD} = +5.0\text{ V} \pm 10\%$, $V_{SS} = 0\text{ V}$, $0\text{ V} \leq V_{TH} \leq V_{DD} + 0.1\text{ V}$)

Resonator	Recommended Circuit	Parameter	μPD70320		μPD70320-8		Unit
			MIN.	MAX.	MIN.	MAX.	
Ceramic or Crystal Resonator		Oscillation frequency (f_{xx})	4	10	4	16	MHz
External Clock	①  or ② 	X1 input frequency (f_x)	4	10	4	16	MHz
		X1 rise/fall time (t_{xR} , t_{xF})	0	20	0	20	ns
		X1 input high-/low-level width (t_{wxH} , t_{wxL})	35	250	20	250	ns

- Cautions**
1. Mount the oscillation circuit as close to pins X1 and X2 as possible.
 2. Do not route other signal lines through the area within the dotted line.

RECOMMENDED OSCILLATOR CONSTANT

Ceramic resonator

Manufacturer	Part Number	Recommended Constants	
		C1 [pF]	C2 [pF]
Kyocera Corp.	KBR-10.0M ^{Note 1}	33	33
Murata Mfg. Co., Ltd.	CSA7.37MT040 ^{Note 2}	100	100
	CSA10.0MT ^{Note 1}	47	47
	CSA11.0MT ^{Note 2}		
	CSA16.0MX040 ^{Note 1}	30	30
TDK	FCR10.0M2S ^{Note 2}	30	30
	FCR16.0M2S ^{Note 2}	15	6
	FCR16.0M2G ^{Note 2}	22	10

- Notes**
1. The operating ambient temperature (T_A) is –10°C to +70°C when this resonator is used.
 2. The operating ambient temperature (T_A) is –20°C to +80°C when this resonator is used.

Crystal resonator

Manufacturer	Part Number	Recommended Constants	
		C1 [pF]	C2 [pF]
Kinseki Co., Ltd.	HC-49/U(KR-100)	22	22
	HC-49/U(KR-160)	22	22

Remark For more details on the characteristics of the resonators, please contact the manufacturer.

CAPACITANCE ($T_A = 25^\circ\text{C}$, $V_{DD} = 0\text{ V}$)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Input Capacitance	C_i	$f_c = 1\text{ MHz}$ Unmeasured pins returned to 0 V.			10	pF
Output Capacitance	C_o				20	pF
Input/output Capacitance	C_{io}				20	pF

DC CHARACTERISTICS ($T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$, $V_{DD} = +5.0\text{ V} \pm 10\%$)

Parameter	Symbol	Test Conditions		MIN.	TYP.	MAX.	Unit
Input Voltage Low	V _{IL}			0		0.8	V
Input Voltage High	V _{IH1}	Except $\overline{\text{RESET}}$, P10/NMI, X1, X2		2.2		V _{DD}	V
	V _{IH2}	$\overline{\text{RESET}}$, P10/NMI, X1, X2		0.8V _{DD}		V _{DD}	V
Output Voltage Low	V _{OL}	I _{OL} = 1.6 mA				0.45	V
Output Voltage High	V _{OH}	I _{OH} = −0.4 mA		V _{DD} − 1.0			V
Input Current	I _I	$\overline{\text{EA}}$, P10/NMI; 0 ≤ V _I ≤ V _{DD}				±20	μA
Input Leakage Current	I _{LI}	Except $\overline{\text{EA}}$, P10/NMI; 0 ≤ V _I ≤ V _{DD}				±10	μA
Output Leakage Current	I _{LO}	0 ≤ V _O ≤ V _{DD}				±10	μA
V _{TH} Current	I _{TH}	0 V ≤ V _{TH} ≤ V _{DD}			0.5	1.0	mA
V _{DD} Supply Current	I _{DD1}	Operating mode	μPD70320		50	100	mA
			μPD70320-8		65	120	mA
	I _{DD2}	HALT mode	μPD70320		20	40	mA
			μPD70320-8		25	50	mA
	I _{DD3}	STOP mode			10	30	μA

★ **AC CHARACTERISTICS** ($T_A = -40$ to $+85^\circ\text{C}$, $V_{DD} = +5.0\text{ V} \pm 10\%$)

Parameter	Symbol	Test Conditions	$\mu\text{PD70320}$		$\mu\text{PD70320-8}$		Unit
			MIN.	MAX.	MIN.	MAX.	
X1 Input Cycle Time	t_{CYX}		98	250	62	250	ns
X1 Input High-/Low-Level Width	t_{WXH} , t_{WXL}		35		20		ns
X1 Input Rise/Fall Time	t_{XR} , t_{XF}			20		20	ns
CLKOUT Output Cycle Time	t_{CYK}	$f_x/2$, $T = t_{CYK}$	200	2000	125	2000	ns
CLKOUT Output High-/Low-Level Width	t_{WKH} , t_{WKL}		$0.5T - 15$		$0.5T - 15$		ns
CLKOUT Output Rise/Fall Time	t_{KR} , t_{KF}			15		15	ns
Input Rise/Fall Time	t_{iR} , t_{iF}	Except $\overline{\text{RESET}}$, NMI, X1 and X2		20		20	ns
	t_{iRS} , t_{iFS}	$\overline{\text{RESET}}$, NMI		30		30	ns
Output Rise/Fall Time	t_{oR} , t_{oF}	Except CLKOUT		20		20	ns

Parameter	Symbol	Test Conditions	MIN.	MAX.	Unit
Address Delay Time from CLKOUT	t _{DKA}			90	ns
Data Input Delay Time from Address	t _{DADR}			(n + 1.5)T – 90	ns
Data Delay Time from $\overline{\text{MREQ}} \downarrow$	t _{DMRD}			(n + 1)T – 75	ns
Data Delay Time from $\overline{\text{MSTB}} \downarrow$	t _{DMSD}			(n + 0.5)T – 75	ns
$\overline{\text{MSTB}} \downarrow$ Delay Time from $\overline{\text{MREQ}} \downarrow$	t _{DMRMS}		0.5T – 35	0.5T + 35	ns
$\overline{\text{MREQ}}$ Low-Level Width	t _{WMRL}		(n + 1)T – 30	(n + 1)T + 30	ns
Address Hold Time (from $\overline{\text{MREQ}} \uparrow$)	t _{HMA}		0.5T – 30		ns
Data Input Hold Time (from $\overline{\text{MREQ}} \uparrow$)	t _{HMDR}		0		ns
Control Signal Recovery Time	t _{RVC}		T – 25		ns
Data Output Delay Time from Address	t _{DADW}			0.5T + 50	ns
Address Setup Time (to $\overline{\text{MREQ}} \downarrow$)	t _{DAMR}		0.5T – 30		ns
Address Setup Time (to $\overline{\text{MSTB}} \downarrow$)	t _{DAMS}		T – 30		ns
$\overline{\text{MSTB}}$ Low-Level Width	t _{WMSL}		(n + 0.5)T – 30	(n + 0.5)T + 30	ns
Data Output Setup Time (to $\overline{\text{MSTB}} \uparrow$)	t _{SDM}		(n + 1)T – 50		ns
Data Output Hold Time (from $\overline{\text{MSTB}} \uparrow$)	t _{HMDW}		0.5T – 30		ns
Address Setup Time (to $\overline{\text{IOSTB}} \downarrow$)	t _{DAIS}		0.5T – 30		ns
Data Delay Time from $\overline{\text{IOSTB}} \downarrow$	t _{DISD}			(n + 1)T – 90	ns
$\overline{\text{IOSTB}}$ Low-Level Width	t _{WISL}		(n + 1)T – 30		ns
Address Hold Time (from $\overline{\text{IOSTB}} \uparrow$)	t _{HISA}		0.5T – 30		ns
Data Input Hold Time (from $\overline{\text{IOREQ}} \uparrow$)	t _{HISDR}		0		ns
Data Output Setup Time (to $\overline{\text{IOSTB}} \uparrow$)	t _{SDIS}		(n + 1)T – 50		ns
Data Output Hold Time (from $\overline{\text{IOSTB}} \uparrow$)	t _{HISDW}		0.5T – 30		ns
$\overline{\text{DMARQ}}$ Setup Time (to $\overline{\text{MREQ}} \downarrow$)	t _{SDADQ}	Demand release mode		1T	ns
$\overline{\text{DMARQ}}$ Hold Time (from $\overline{\text{DMAAK}} \downarrow$)	t _{HDADQ}	Demand release mode	0		ns
$\overline{\text{DMAAK}}$ Output Low-Level Width	t _{WDMRL}	Read mode	(n + 1.5)T – 30		ns
$\overline{\text{TC}} \downarrow$ Delay Time from $\overline{\text{DMAAK}} \downarrow$	t _{DDATC}			0.5T + 50	ns
$\overline{\text{TC}}$ Low-Level Width	t _{WTCL}		2T – 30		ns
$\overline{\text{DMAAK}}$ Output Low-Level Width	t _{WDMWL}	Write mode	(n + 1)T – 30		ns
Address Setup Time (to $\overline{\text{REFRQ}} \downarrow$)	t _{DARF}		0.5T – 30		ns
$\overline{\text{REFRQ}}$ Low-Level Width	t _{WRFL}		(n + 1)T – 30		ns
Address Hold Time (from $\overline{\text{REFRQ}} \uparrow$)	t _{HRFA}		0.5T – 30		ns
$\overline{\text{RESET}}$ Low-Level Width	t _{WRSL1}	STOP mode release/ power-ON reset	30		ms
	t _{WRSL2}	System reset	5		μs
READY Setup Time (to $\overline{\text{MREQ}} \downarrow$, $\overline{\text{IOSTB}} \downarrow$)	t _{SCRY0}	n ≥ 2		T – 100	ns
	t _{SCRY}	n ≥ 3		(n – 1)T – 100	ns

Parameter	Symbol	Test Conditions	MIN.	MAX.	Unit
READY Hold Time (from $\overline{\text{MREQ}} \downarrow$, $\overline{\text{IOSTB}} \downarrow$)	t_{HCRY0}	$n = 2$	1T		ns
	t_{HCRY}	$n \geq 3$	$(n - 1)T$		ns
	t_{HCRY1}	$n \geq 3$	$(n - 2)T$		ns
HLDRQ Setup Time (to CLKOUT $\uparrow$)	t_{SHQK}		30		ns
$\overline{\text{HLD}}\overline{\text{AK}} \downarrow$ Delay Time from CLKOUT $\uparrow$	t_{DKHA}			80	ns
$\overline{\text{HLD}}\overline{\text{AK}} \downarrow$ Delay Time from Bus Float	t_{CFHA}		1T – 50		ns
Bus Output Delay Time from $\overline{\text{HLD}}\overline{\text{AK}} \uparrow$	t_{DHAC}		1T – 50		ns
$\overline{\text{HLD}}\overline{\text{AK}} \uparrow$ Delay Time from HLDRQ $\downarrow$	t_{DHQHA}			3T + 160	ns
Bus Output Delay Time from HLDRQ $\downarrow$	t_{DHQC}		3T + 30		ns
HLDRQ Low-Level Width	t_{WHQL}		1.5T		ns
$\overline{\text{HLD}}\overline{\text{AK}}$ Low-Level Width	t_{WHAL}		1T		ns
INT, DMARQ Setup Time (to CLKOUT $\uparrow$)	t_{SIQK}		30		ns
INT, DMARQ High-/Low-Level Width	$t_{\text{WIQH}}, t_{\text{WIQL}}$		8T		ns
$\overline{\text{POLL}}$ Setup Time (to CLKOUT $\uparrow$)	t_{SPLK}		30		ns
NMI High-/Low-Level Width	$t_{\text{WNIH}}, t_{\text{WNIL}}$		5		μs
$\overline{\text{CTS}}$ Low-Level Width	t_{WCTL}		2T		ns
INT Setup Time (to CLKOUT $\uparrow$)	t_{SIRK}		30		ns
$\overline{\text{INTAK}} \downarrow$ Delay Time from CLKOUT $\downarrow$	t_{DKIA}			80	ns
INT Hold Time (from $\overline{\text{INTAK}} \downarrow$)	t_{HIAIQ}		0		ns
$\overline{\text{INTAK}}$ Low-Level Width	t_{WIAL}		2T – 30		ns
$\overline{\text{INTAK}}$ High-Level Width	t_{WIAH}		1T – 30		ns
Data Delay Time from $\overline{\text{INTAK}} \downarrow$	t_{DIAD}			2T – 130	ns
Data Hold Time (from $\overline{\text{INTAK}} \uparrow$)	t_{HIAD}		0	0.5T	ns
$\overline{\text{SCK0}}$ Cycle Time	t_{CYTK}		1000		ns
$\overline{\text{SCK0}}$ High-/Low-Level Width	$t_{\text{WSTH}}, t_{\text{WSTL}}$		450		ns
TxD Delay Time from $\overline{\text{SCK0}} \downarrow$	t_{DTKD}			210	ns
TxD Hold Time (from $\overline{\text{SCK0}} \downarrow$)	t_{HTKD}		20		ns
$\overline{\text{CTS0}}$ Cycle Time	t_{CYRK}		1000		ns
$\overline{\text{CTS0}}$ High-/Low-Level Width	$t_{\text{WSRH}}, t_{\text{WSRL}}$		420		ns
RxD Setup/Hold Time (to/from $\overline{\text{CTS0}} \uparrow$)	$t_{\text{SRDK}}, t_{\text{HKRD}}$		80		ns

Remark n indicates the number of wait states. No wait is “n = 0”.

COMPARATOR CHARACTERISTICS ($T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, $V_{DD} = +5.0\text{ V} \pm 10\%$)

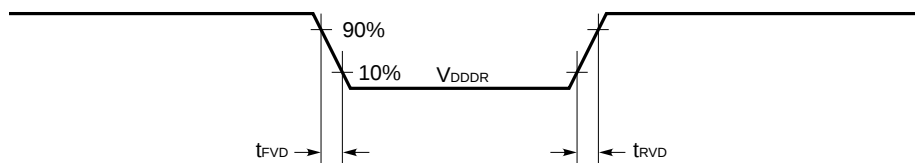
Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Comparator Accuracy	V_{ACOMP}				± 100	mV
Threshold Voltage	V_{TH}		0		$V_{DD} + 0.1$	V
Compare Time	t_{COMP}		64		65	t_{CYK}
PT Input Voltage	V_{IPT}		0		V_{DD}	V

DATA MEMORY STOP MODE LOW SUPPLY VOLTAGE DATA HOLDING CHARACTERISTICS

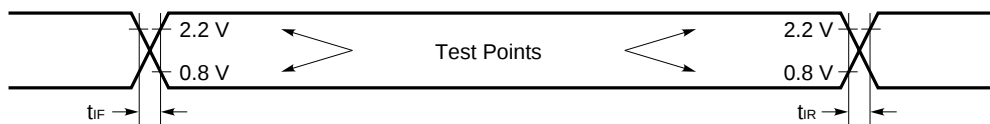
($T_A = -40$ to $+85^{\circ}\text{C}$)

Parameter	Symbol	Test Conditions	MIN.	MAX.	Unit
Data Hold Supply Voltage	V_{DDDR}		2.5	5.5	V
V_{DD} Rise/Fall Time	t_{RVD} , t_{FVD}		200		μs

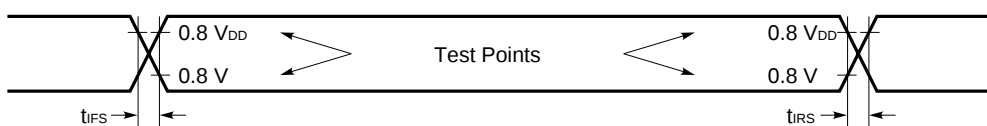
DATA HOLDING TIMING



AC TEST INPUT WAVEFORM (Except RESET, NMI, X1 and X2)

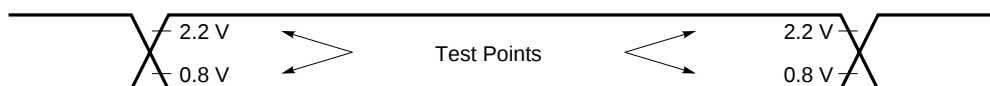


AC TEST INPUT WAVEFORM (RESET, NMI, X1 and X2)

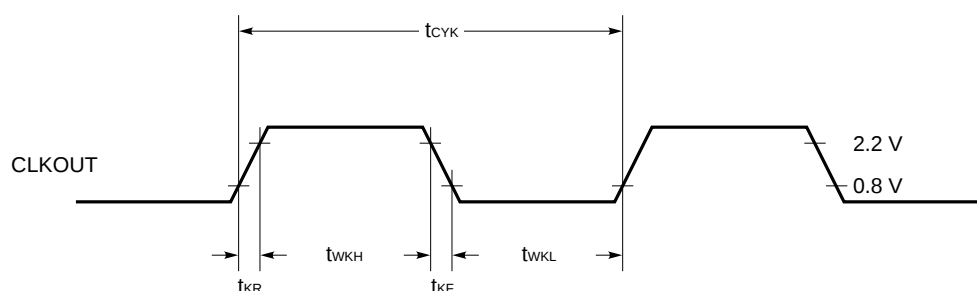
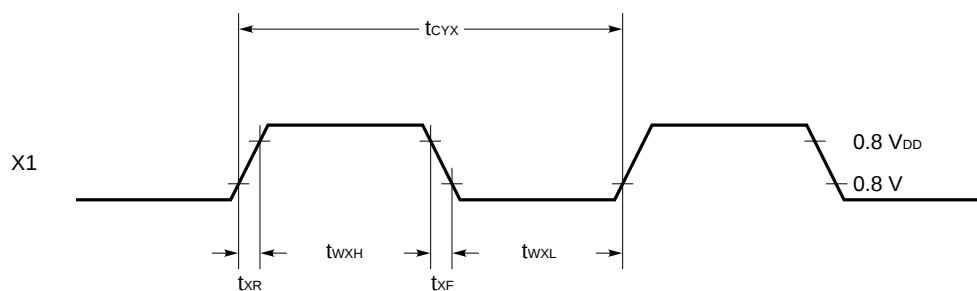


AC TEST OUTPUT TEST POINTS

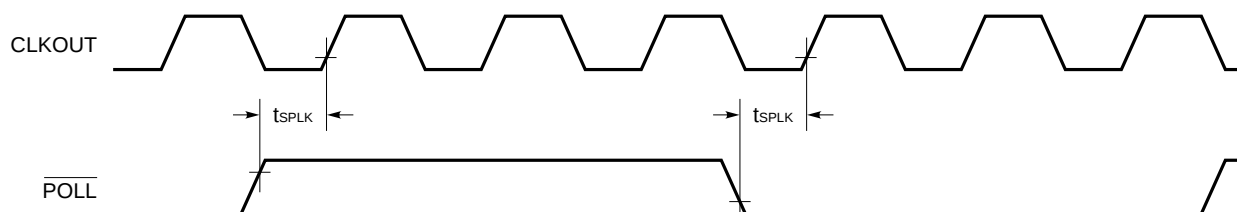
Output load condition: 100 pF



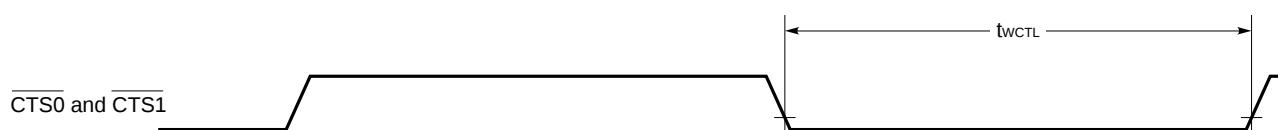
CLOCK TIMING



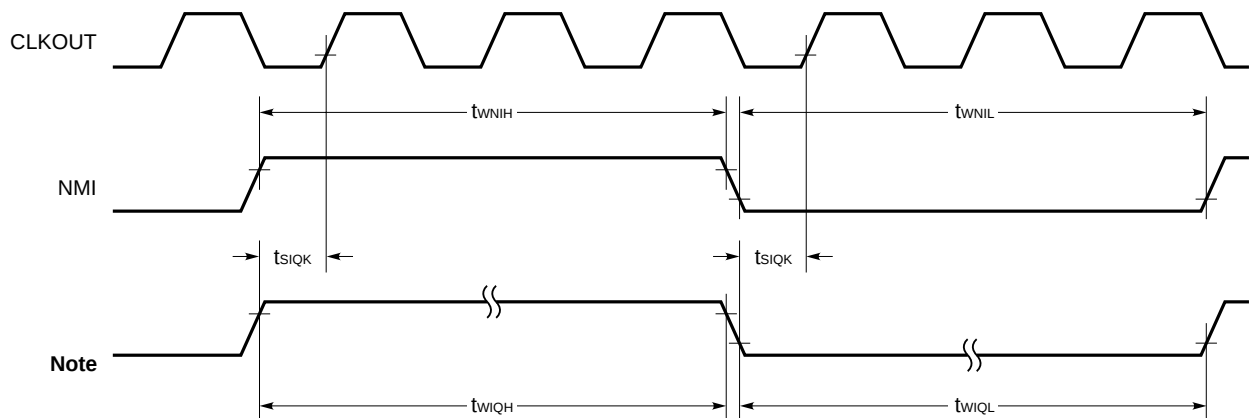
POLL INPUT TIMING



CTS0 AND CTS1 INPUT TIMING



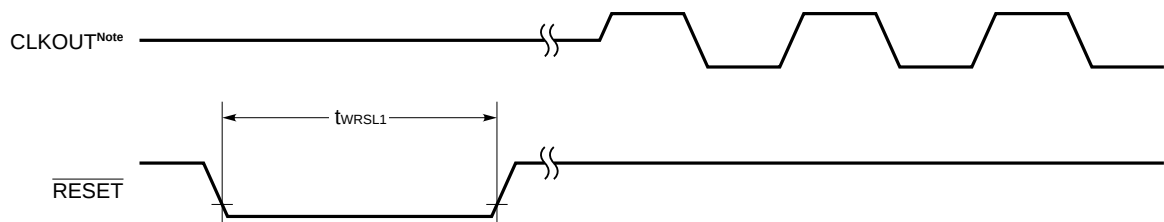
INTERRUPT INPUT/DMA INPUT TIMING



Note $\overline{\text{INTP0}}$ to $\overline{\text{INTP2}}$, $\overline{\text{DMARQ0}}$ to $\overline{\text{DMARQ1}}$

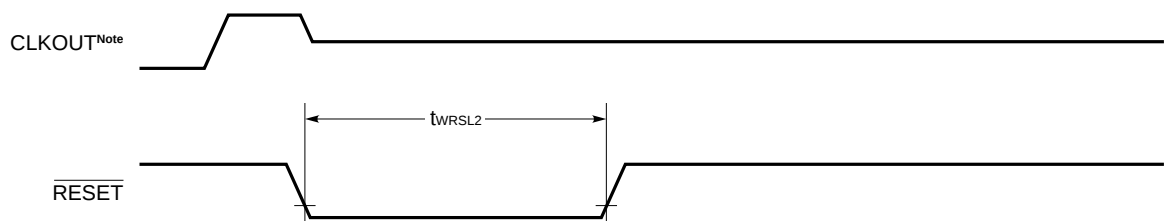
$\overline{\text{RESET}}$ INPUT TIMING

When STOP mode is released/at power-on reset:



Note CLKOUT signal is output after CLKOUT output is set.

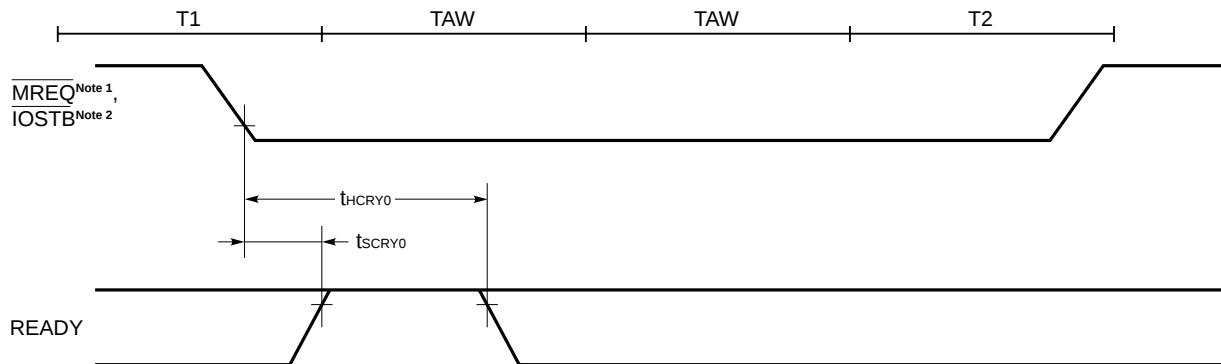
★ When system is reset:



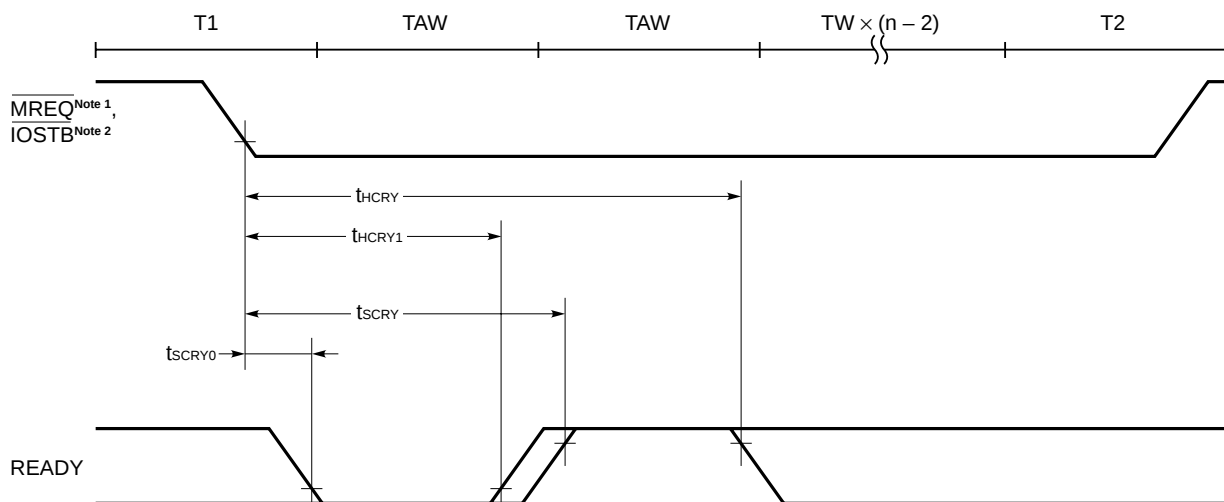
Note CLKOUT output is set to input port by $\overline{\text{RESET}}$ input.

READY TIMING

When 2 wait states are inserted:



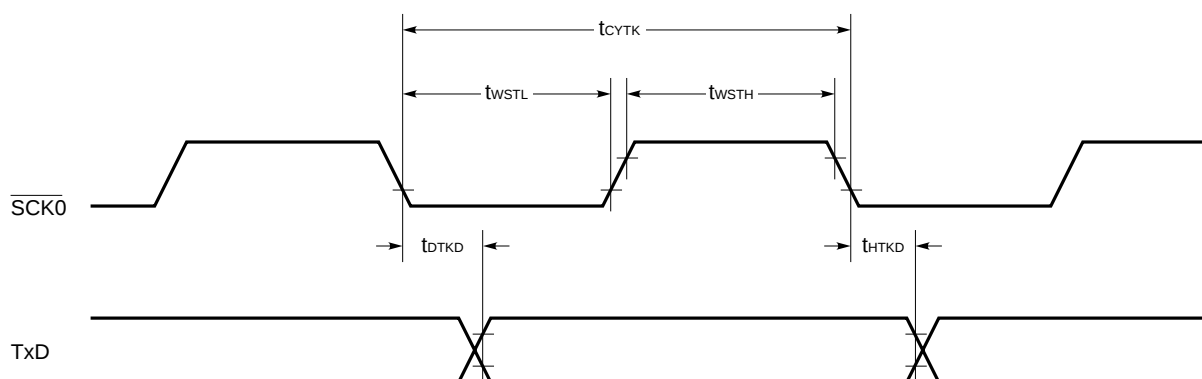
When $(n - 2)$ extra wait states are inserted [$n \geq 3$]:



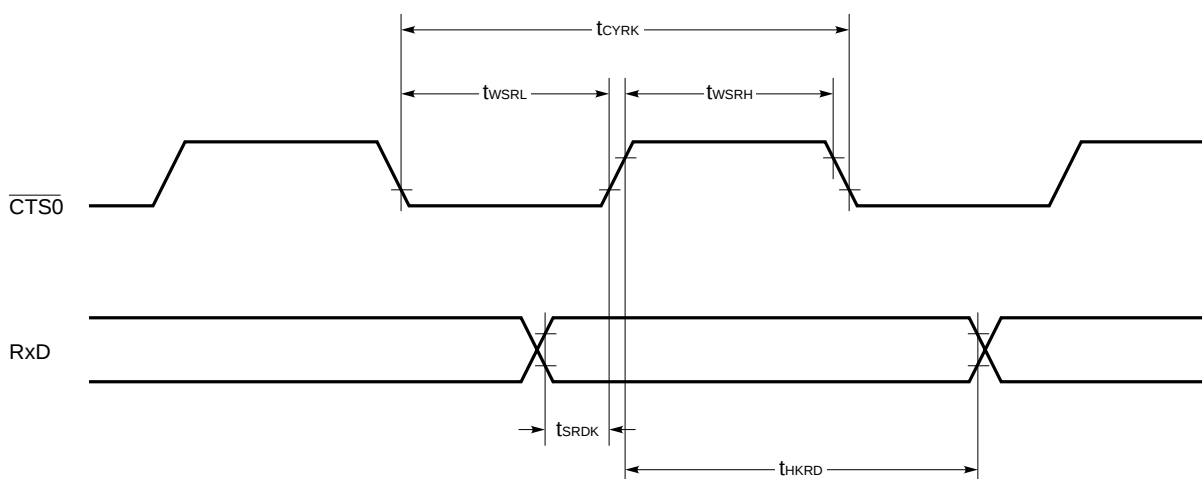
- Notes**
1. In case of memory cycle
 2. In case of I/O cycle

SERIAL OPERATION

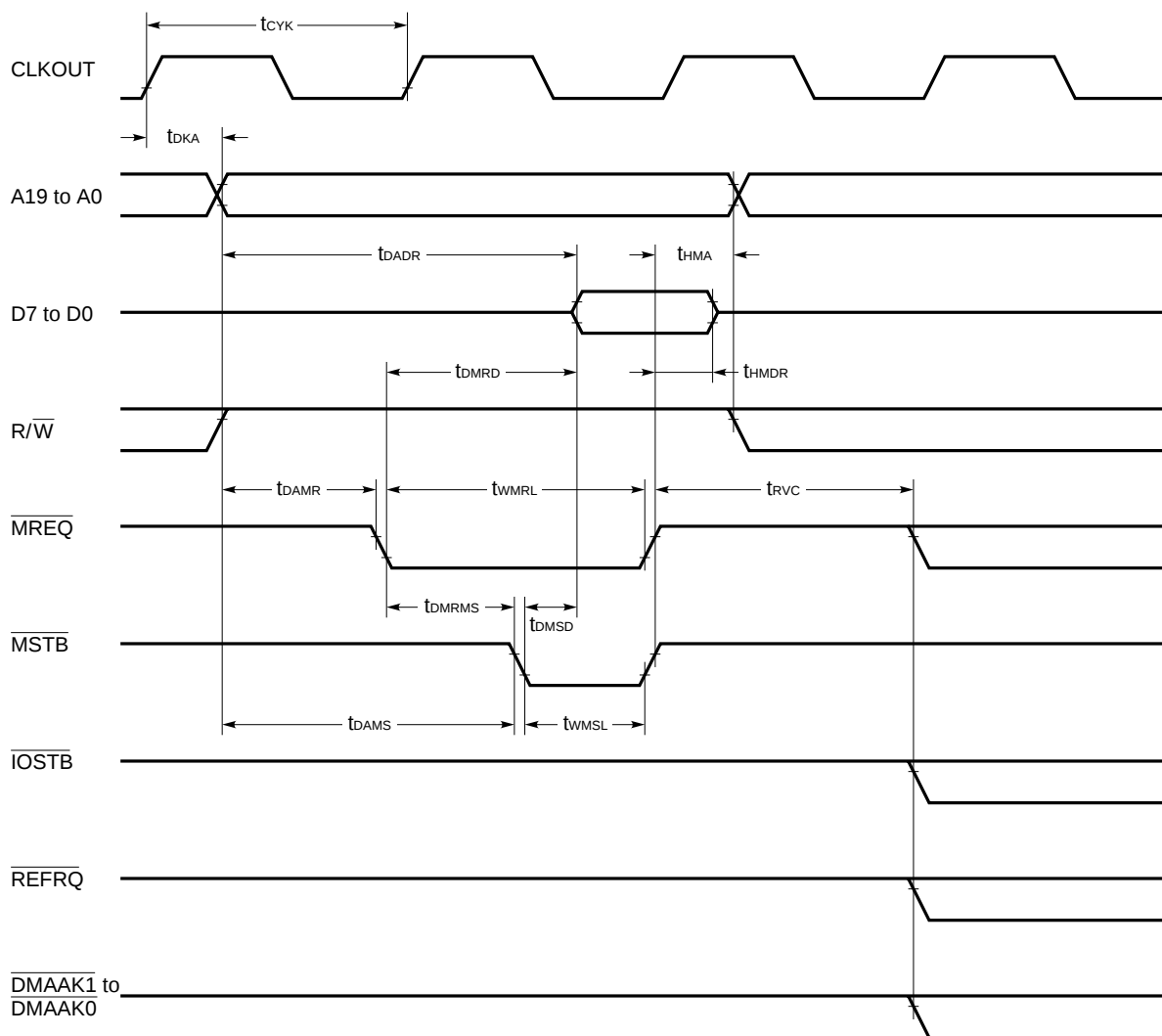
When transmitting data in I/O interface mode



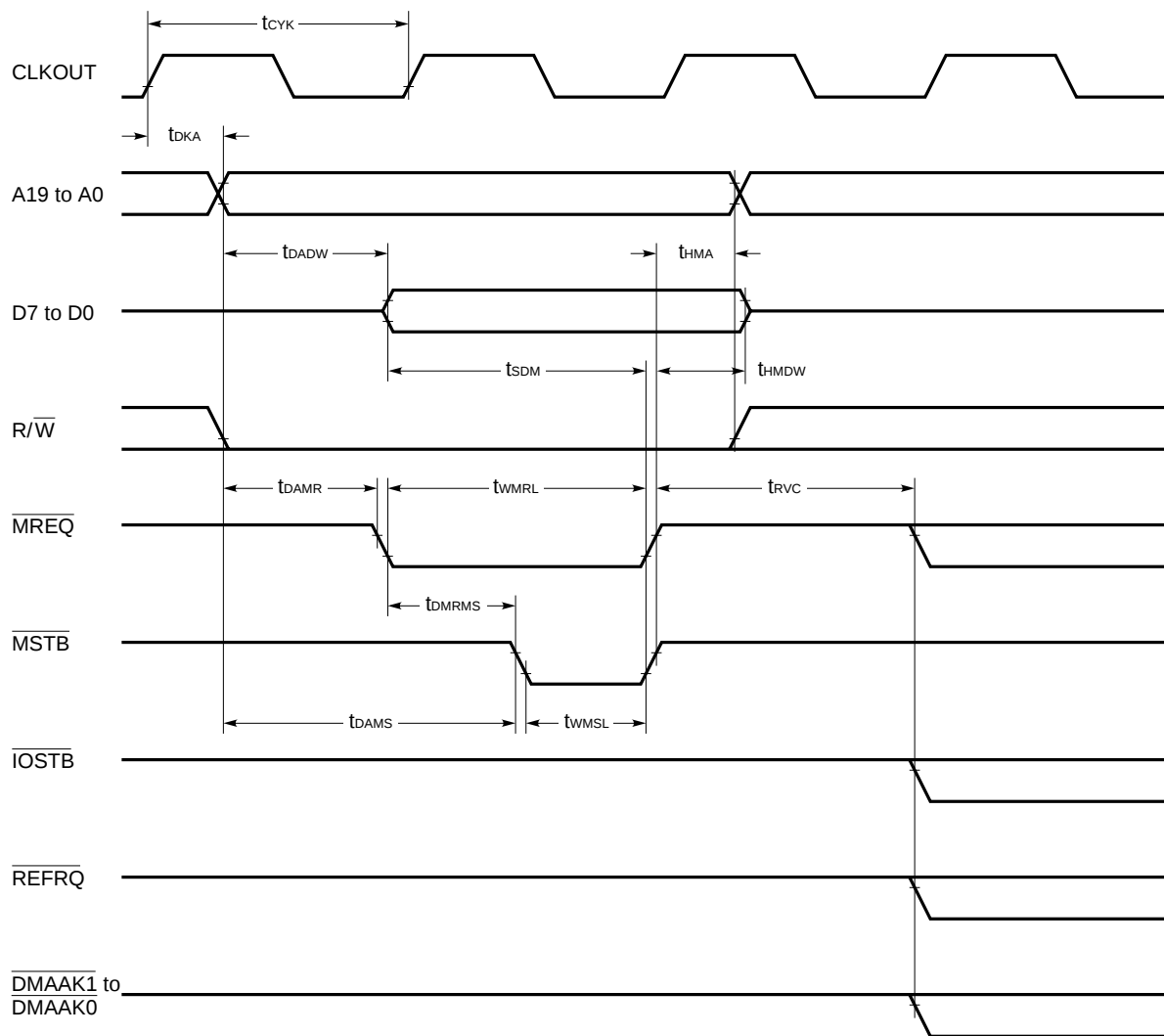
When receiving data in I/O interface mode



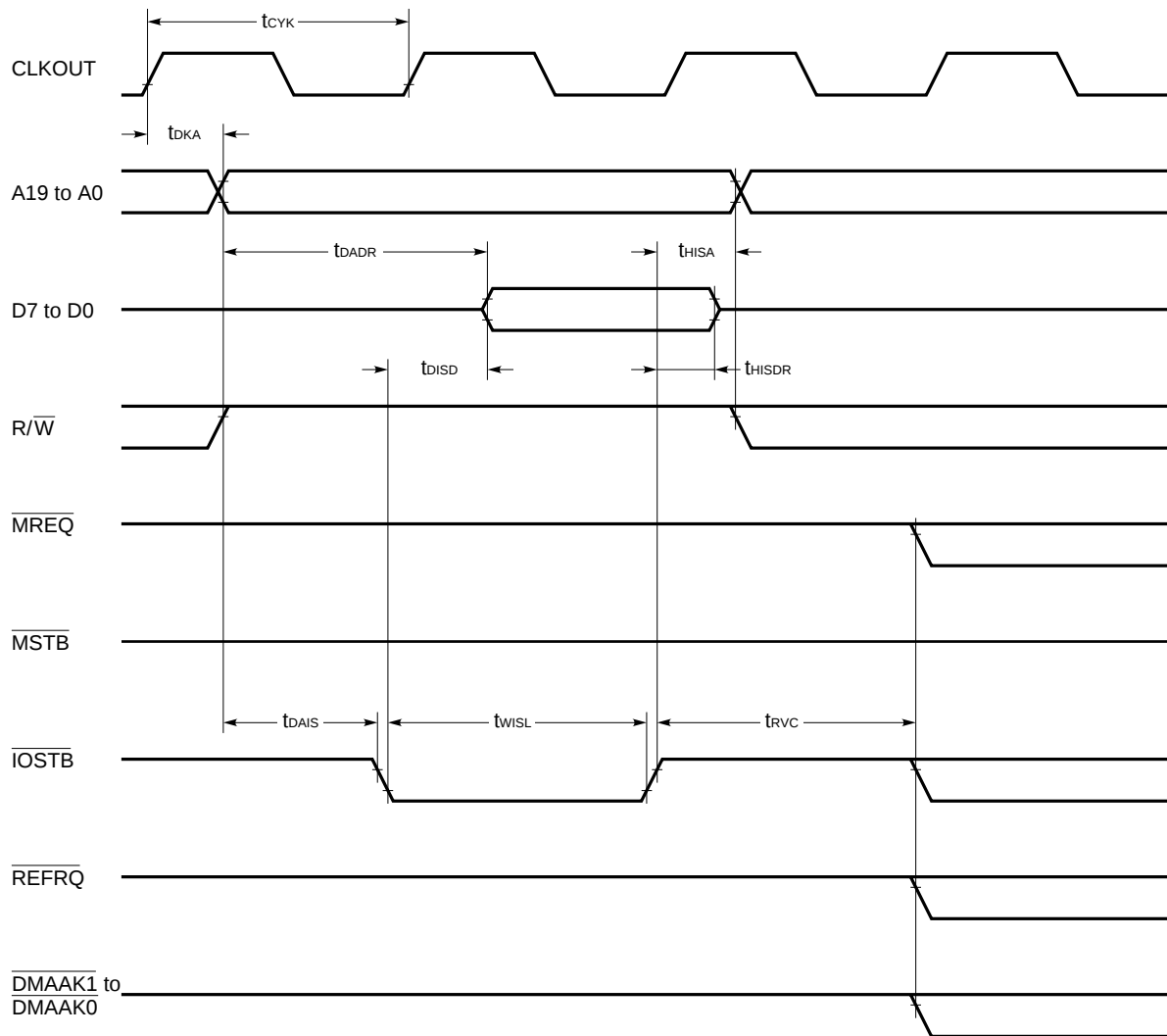
READ OPERATION



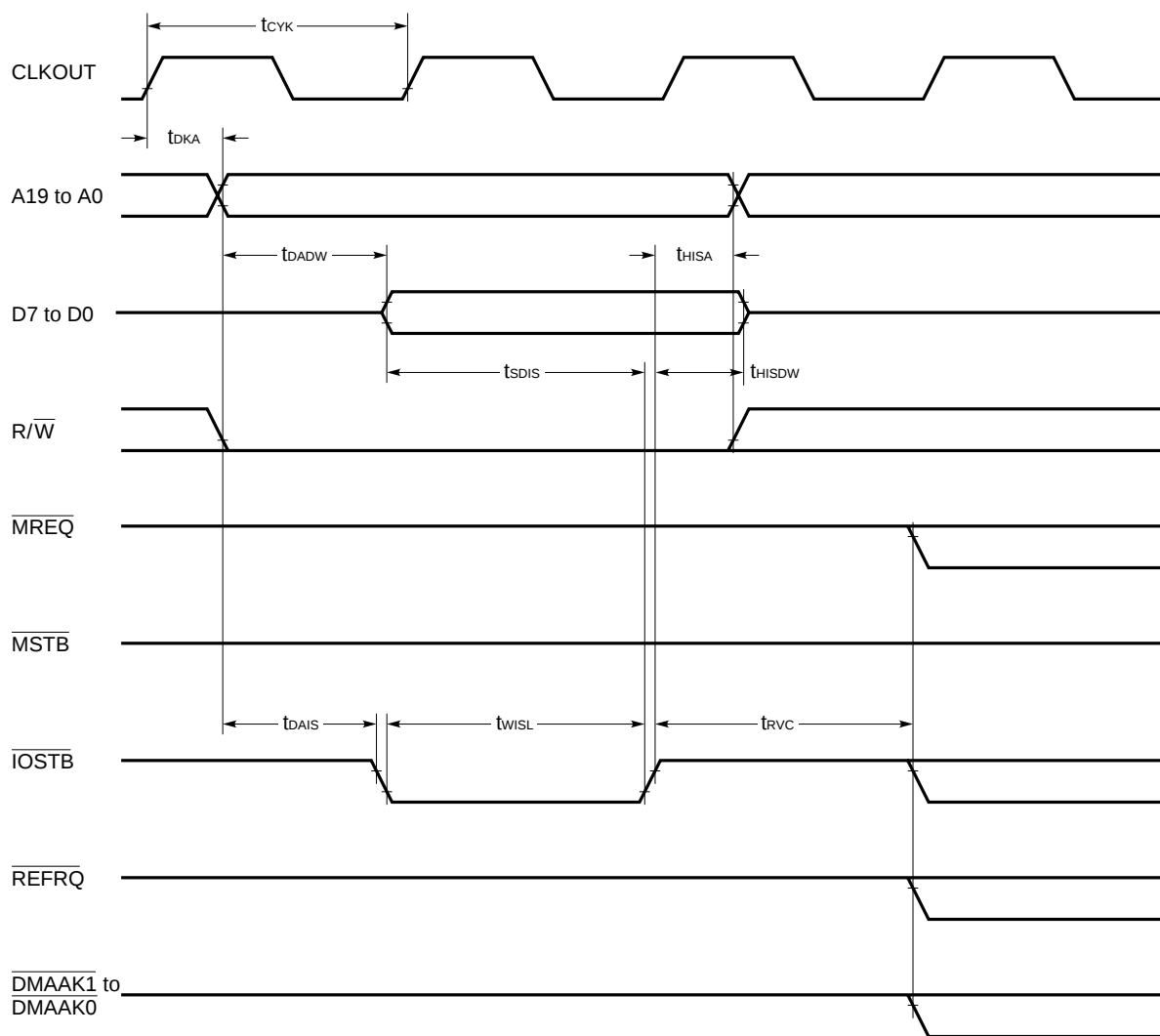
WRITE OPERATION



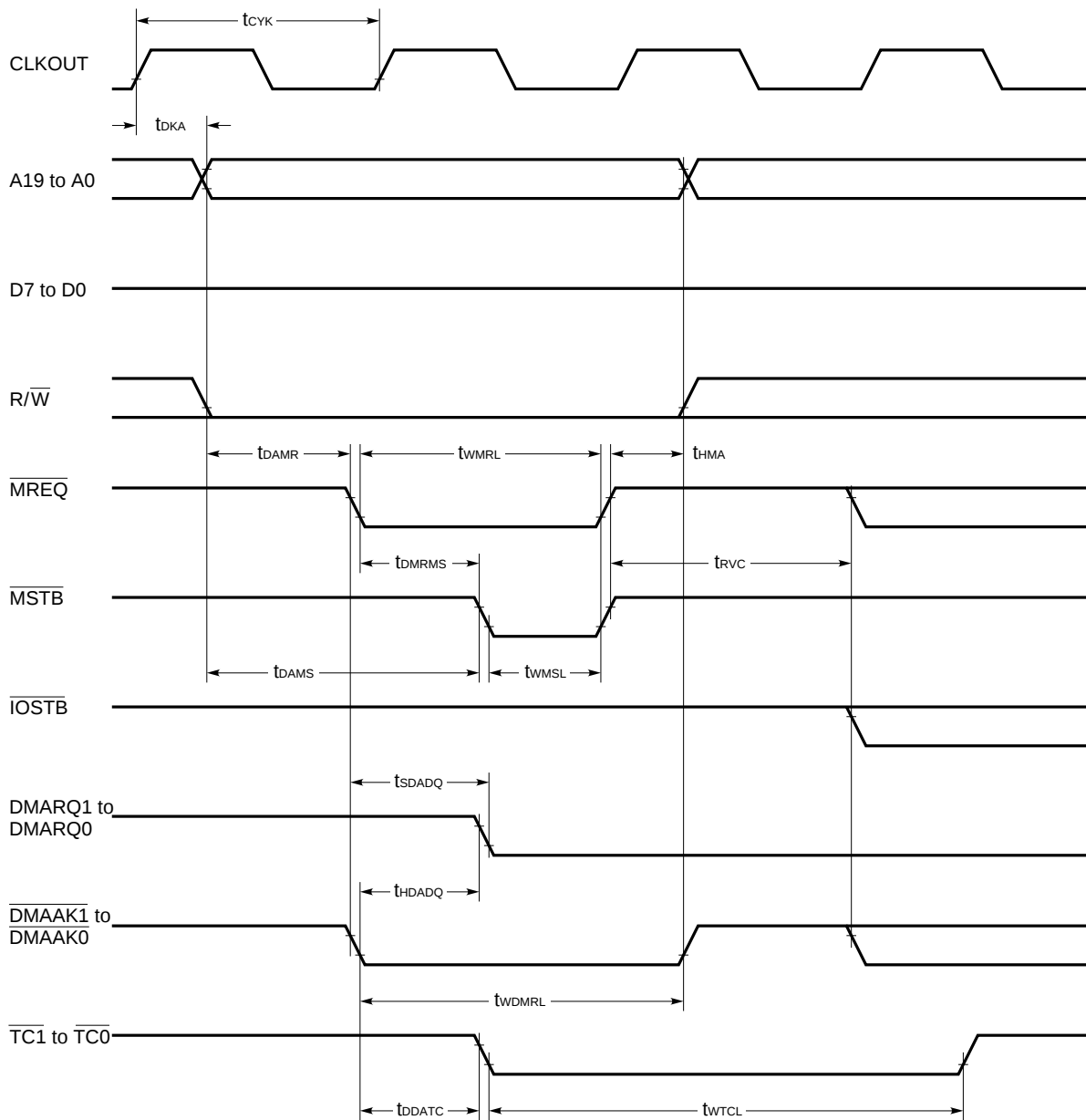
I/O READ TIMING



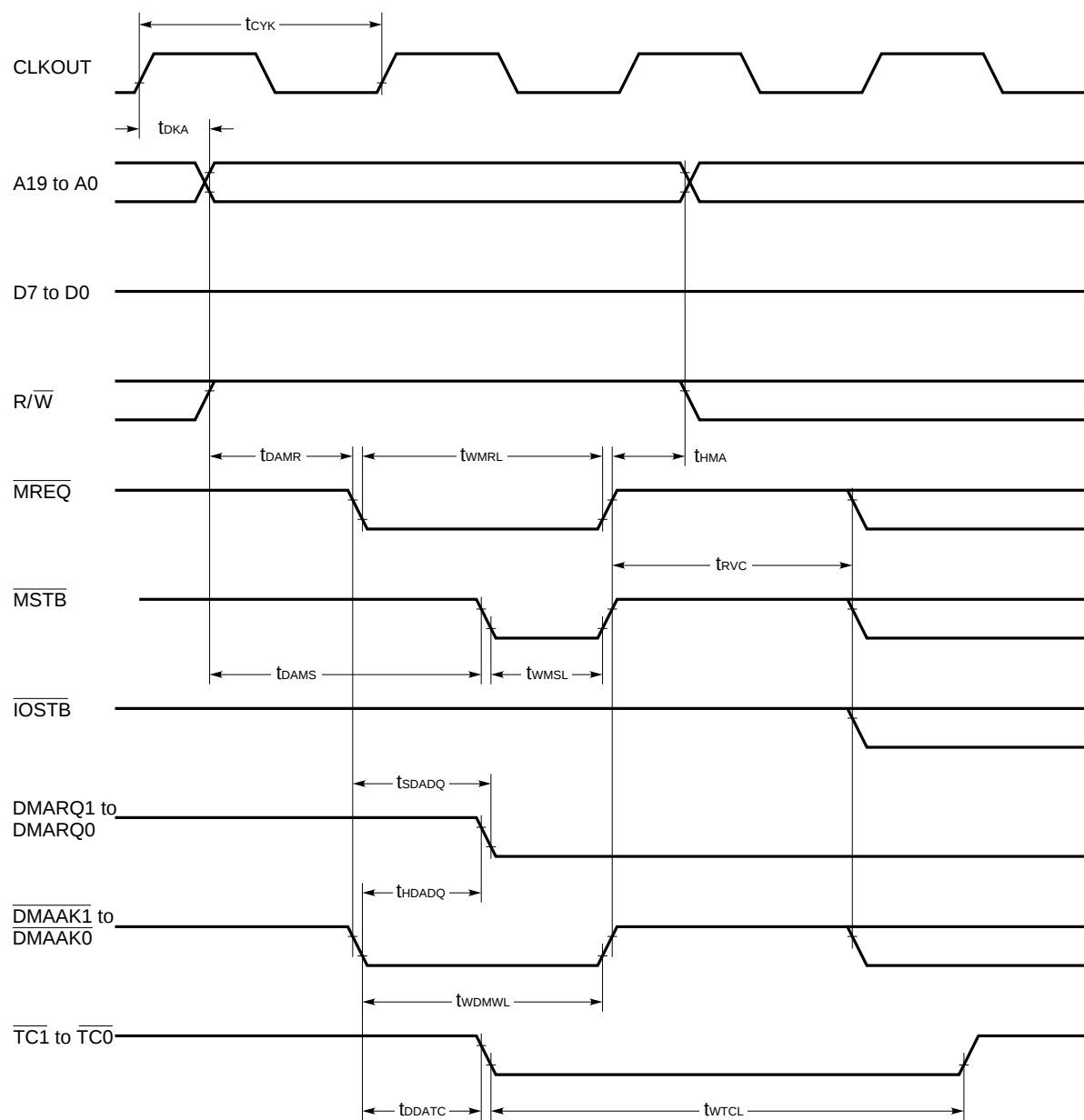
I/O WRITE TIMING



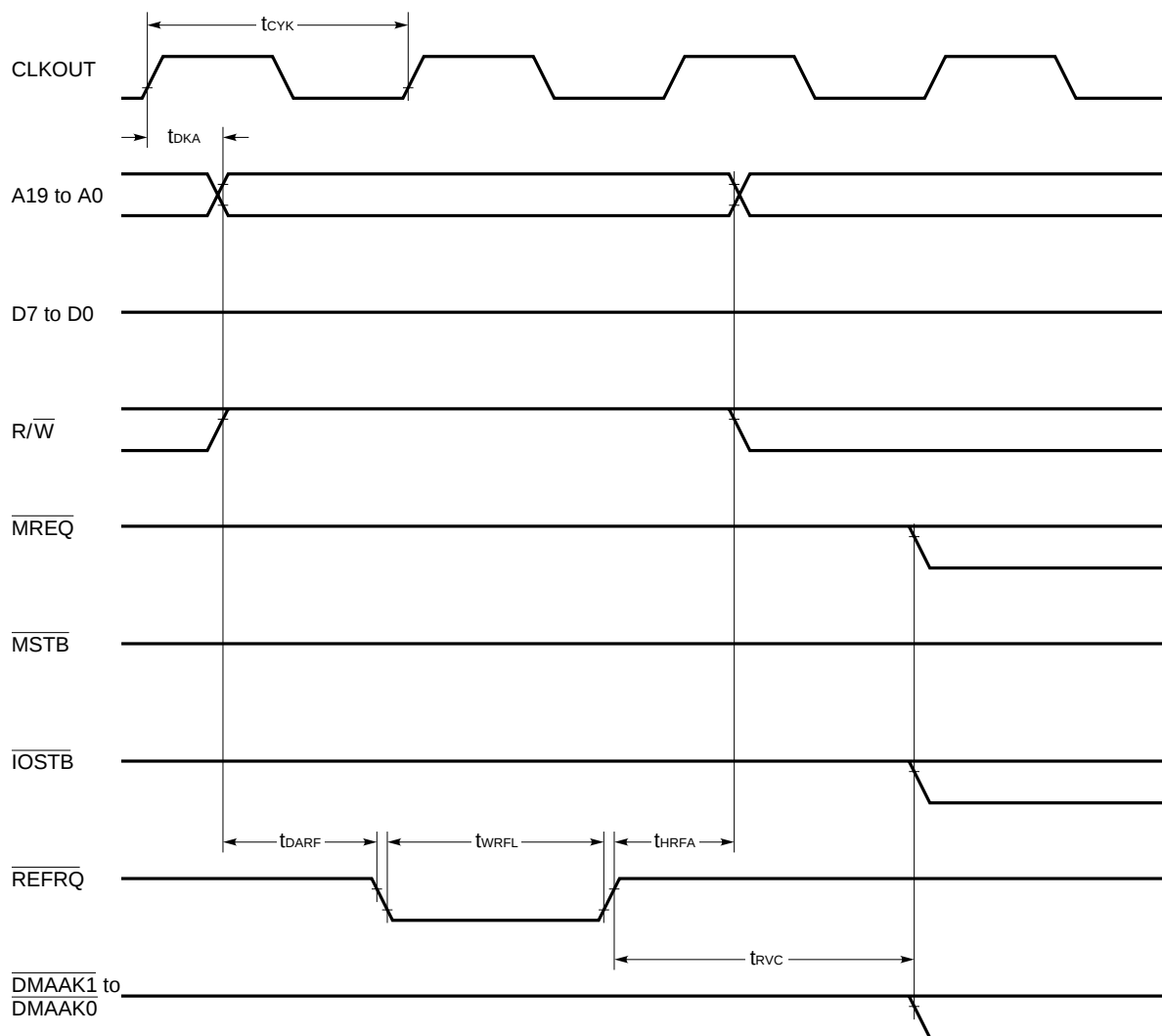
DMA (I/O → MEMORY) TIMING



DMA (MEMORY → I/O) TIMING

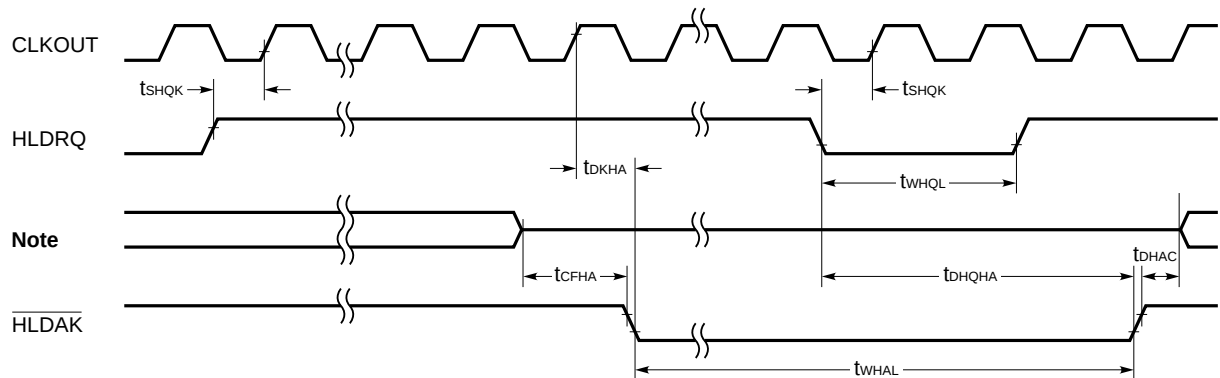


REFRESH TIMING

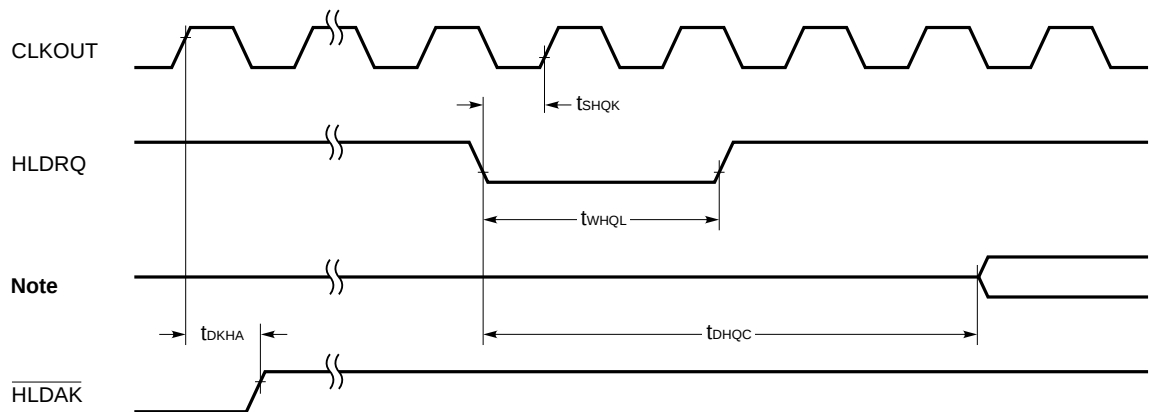


HOLD REQUEST/ACKNOWLEDGE TIMING

Normal mode

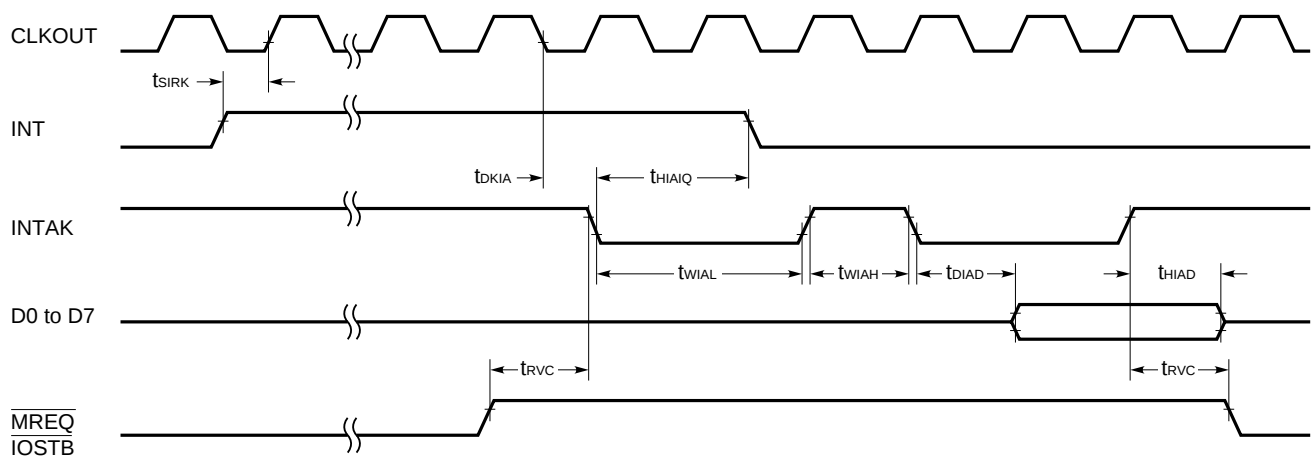


Releasing HOLD mode at refreshing time

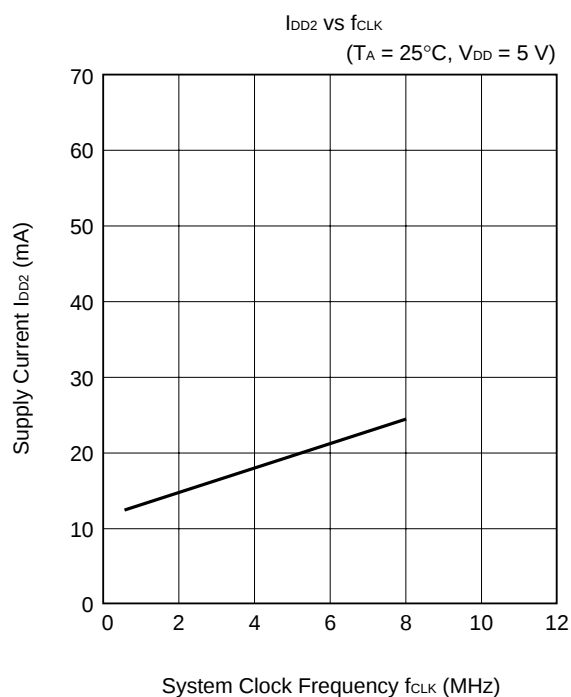
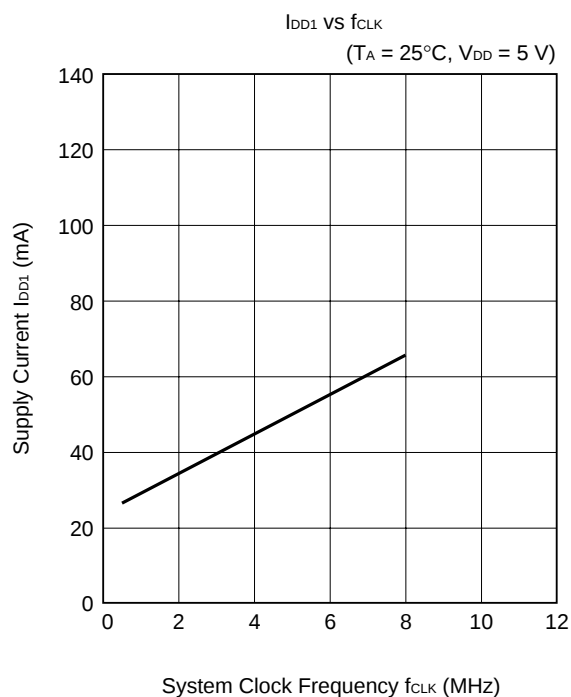


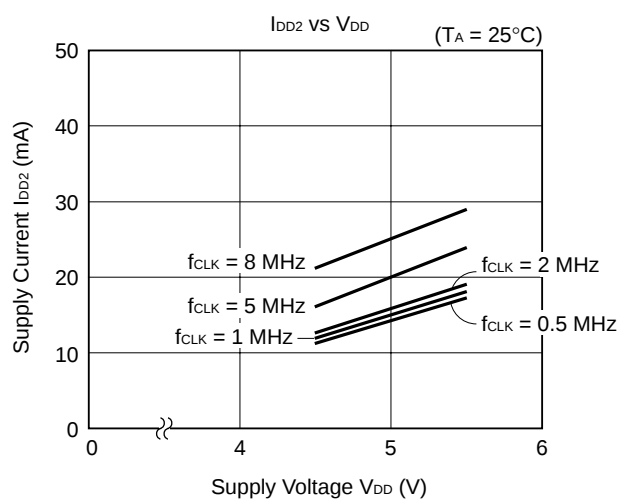
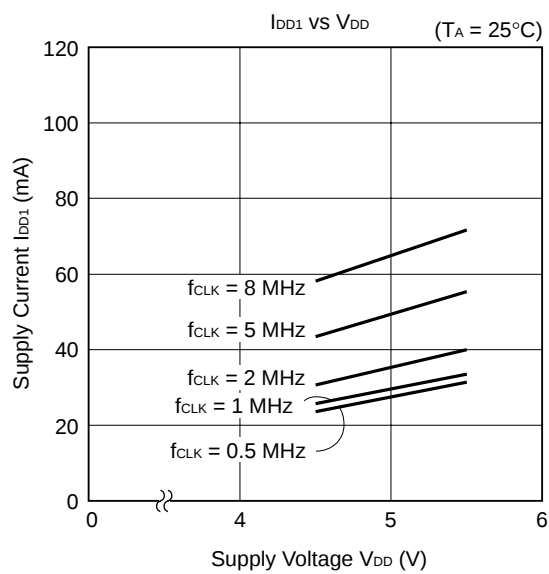
Note A19 to A0, D7 to D0, $\overline{MREQ}$, $\overline{MSTB}$, $\overline{IOSTB}$, R/W

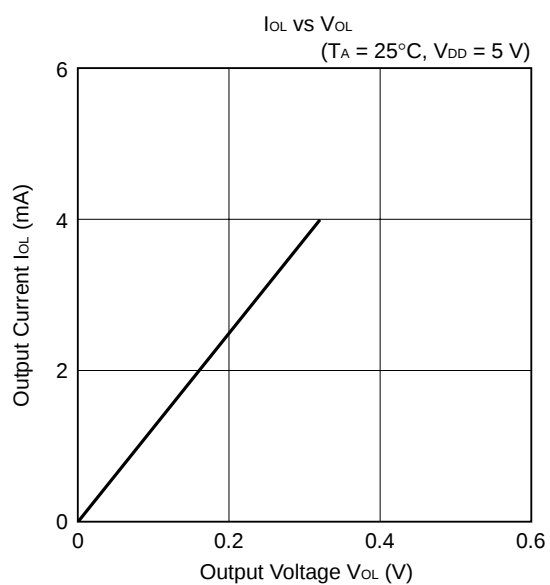
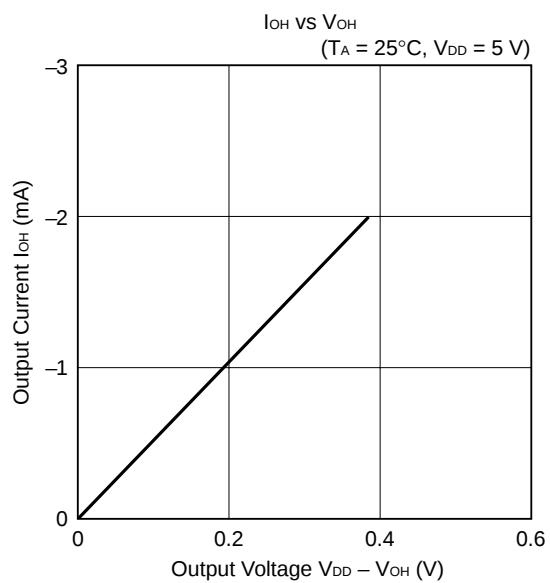
EXTERNAL INTERRUPT REQUEST/ACKNOWLEDGE TIMING



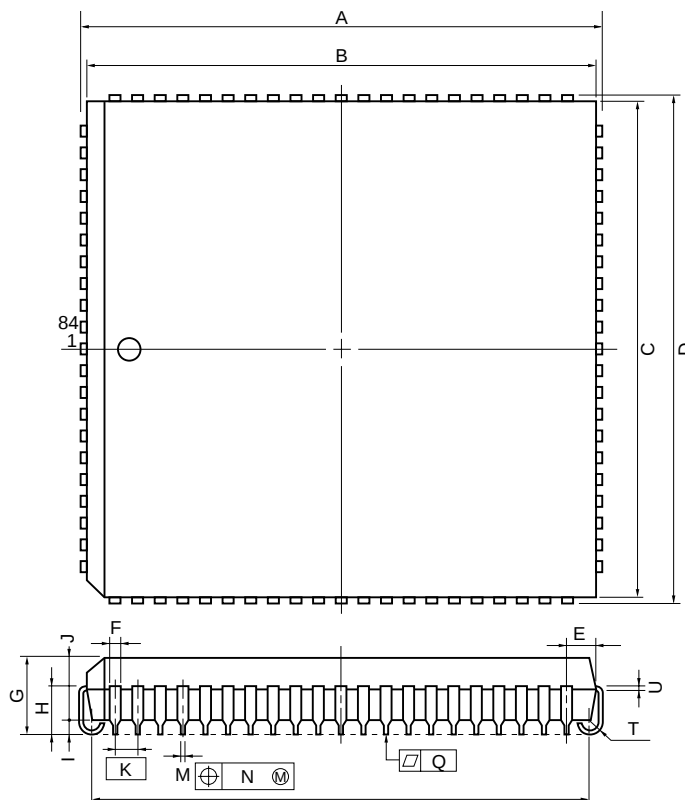
4. CHARACTERISTIC CURVES







5. PACKAGE DRAWINGS

84 PIN PLASTIC QFJ ($\square$ 1150 mil)

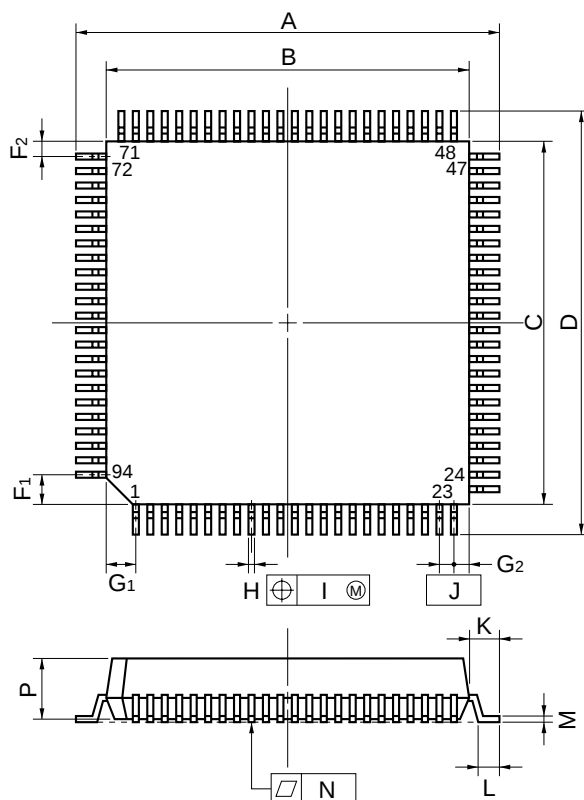
NOTE

Each lead centerline is located within 0.12 mm (0.005 inch) of its true position (T.P.) at maximum material condition.

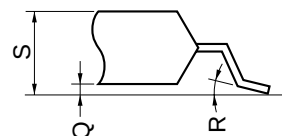
P84L-50A3-2

ITEM	MILLIMETERS	INCHES
A	30.2 $\pm$ 0.2	1.189 $\pm$ 0.008
B	29.28	1.153
C	29.28	1.153
D	30.2 $\pm$ 0.2	1.189 $\pm$ 0.008
E	1.94 $\pm$ 0.15	0.076 ^{+0.007} _{-0.006}
F	0.6	0.024
G	4.4 $\pm$ 0.2	0.173 ^{+0.009} _{-0.008}
H	2.8 $\pm$ 0.2	0.110 ^{+0.009} _{-0.008}
I	0.9 MIN.	0.035 MIN.
J	3.4	0.134
K	1.27 (T.P.)	0.050 (T.P.)
M	0.40 $\pm$ 0.10	0.016 ^{+0.004} _{-0.005}
N	0.12	0.005
P	28.20 $\pm$ 0.20	1.110 ^{+0.009} _{-0.008}
Q	0.15	0.006
T	R 0.8	R 0.031
U	0.20 ^{+0.10} _{-0.05}	0.008 ^{+0.004} _{-0.002}

94 PIN PLASTIC QFP (□ 20)



detail of lead end



NOTE

Each lead centerline is located within 0.15 mm (0.006 inch) of its true position (T.P.) at maximum material condition.

ITEM	MILLIMETERS	INCHES
A	23.2±0.4	0.913 ^{+0.017} _{-0.016}
B	20.0±0.2	0.787 ^{+0.009} _{-0.008}
C	20.0±0.2	0.787 ^{+0.009} _{-0.008}
D	23.2±0.4	0.913 ^{+0.017} _{-0.016}
F1	1.6	0.063
F2	0.8	0.031
G1	1.6	0.063
G2	0.8	0.031
H	0.35±0.10	0.014 ^{+0.004} _{-0.005}
I	0.15	0.006
J	0.8 (T.P.)	0.031 (T.P.)
K	1.6±0.2	0.063±0.008
L	0.8±0.2	0.031 ^{+0.009} _{-0.008}
M	0.15 ^{+0.10} _{-0.05}	0.006 ^{+0.004} _{-0.003}
N	0.10	0.004
P	3.7	0.146
Q	0.1±0.1	0.004±0.004
R	5°±5°	5°±5°
S	4.0 MAX.	0.158 MAX.

S94GJ-80-5BG-3

★ 6. RECOMMENDED SOLDERING CONDITIONS

The following conditions must be met when soldering this product.

For more details, refer to our document “SEMICONDUCTOR DEVICE MOUNTING TECHNOLOGY MANUAL” (C10535E).

Please consult with our sales office when using other soldering process or under different soldering conditions.

Table 6-1. Surface Mount Type Soldering Conditions

(1) μPD70320L : 84-pin plastic QFJ (1150 × 1150 mils)

μPD70320L-8 : 84-pin plastic QFJ (1150 × 1150 mils)

Soldering Process	Soldering Conditions	Symbol
VPS	Package peak temperature: 215°C, Reflow time: 40 seconds or less, Number of reflow processes: 1 Exposure limit: 2 days ^{Note} (16 hours pre-baking is required at 125°C afterwards)	VP15-162-1
Partial heating method	Pin temperature: 300°C or below, Flow time: 3 seconds or less (per side of device)	—

Note Exposure limit before soldering after dry-pack package is opened. Storage conditions: 25°C and relative humidity at 65% or less.

(2) μPD70320GJ-5BG : 94-pin plastic QFP (20 × 20 mm)

μPD70320GJ-8-5BG : 94-pin plastic QFP (20 × 20 mm)

Soldering Process	Soldering Conditions	Symbol
Infrared ray reflow	Package peak temperature: 235°C, Reflow time: 30 seconds or less, Number of reflow processes: 3 or less Exposure limit: 7 days ^{Note} (36 hours pre-baking is required at 125°C afterwards)	IR35-367-3
VPS	Package peak temperature: 215°C, Reflow time: 40 seconds or less, Number of reflow processes: 3 or less Exposure limit: 7 days ^{Note} (36 hours pre-baking is required at 125°C afterwards)	VP15-367-3
Wave soldering	Package peak temperature: 260°C, Reflow time: 10 seconds or less, Number of reflow processes: 1 Pre-heating temperature: 120°C max. (package surface temperature) Exposure limit: 7 days ^{Note} (36 hours pre-baking is required at 125°C afterwards)	WS60-367-1
Partial heating method	Pin temperature: 300°C or below, Flow time: 3 seconds or less (per side of device)	—

Note Exposure limit before soldering after dry-pack package is opened. Storage conditions: 25°C and relative humidity at 65% or less.

Caution Use of more than one soldering process should be avoided (except for partial heating method).

NOTES FOR CMOS DEVICES

① PRECAUTION AGAINST ESD FOR SEMICONDUCTORS

Note: Strong electric field, when exposed to a MOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred. Environmental control must be adequate. When it is dry, humidifier should be used. It is recommended to avoid using insulators that easily build static electricity. Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work bench and floor should be grounded. The operator should be grounded using wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions need to be taken for PW boards with semiconductor devices on it.

② HANDLING OF UNUSED INPUT PINS FOR CMOS

Note: No connection for CMOS device inputs can be cause of malfunction. If no connection is provided to the input pins, it is possible that an internal input level may be generated due to noise, etc., hence causing malfunction. CMOS devices behave differently than Bipolar or NMOS devices. Input levels of CMOS devices must be fixed high or low by using a pull-up or pull-down circuitry. Each unused pin should be connected to V_{DD} or GND with a resistor, if it is considered to have a possibility of being an output pin. All handling related to the unused pins must be judged device by device and related specifications governing the devices.

③ STATUS BEFORE INITIALIZATION OF MOS DEVICES

Note: Power-on does not necessarily define initial status of MOS device. Production process of MOS does not define the initial operation status of the device. Immediately after the power source is turned ON, the devices with reset function have not yet been initialized. Hence, power-on does not guarantee out-pin levels, I/O settings or contents of registers. Device is not initialized until the reset signal is received. Reset operation must be executed immediately after power-on for devices having reset function.

Regional Information

Some information contained in this document may vary from country to country. Before using any NEC product in your application, please contact the NEC office in your country to obtain a list of authorized representatives and distributors. They will verify:

- Device availability
- Ordering information
- Product release schedule
- Availability of related technical literature
- Development environment specifications (for example, specifications for third-party tools and components, host computers, power plugs, AC supply voltages, and so forth)
- Network requirements

In addition, trademarks, registered trademarks, export restrictions, and other legal issues may also vary from country to country.

NEC Electronics Inc. (U.S.)

Santa Clara, California
Tel: 408-588-6000
800-366-9782
Fax: 408-588-6130
800-729-9288

NEC Electronics (Germany) GmbH

Duesseldorf, Germany
Tel: 0211-65 03 02
Fax: 0211-65 03 490

NEC Electronics (UK) Ltd.

Milton Keynes, UK
Tel: 01908-691-133
Fax: 01908-670-290

NEC Electronics Italiana s.r.l.

Milano, Italy
Tel: 02-66 75 41
Fax: 02-66 75 42 99

NEC Electronics (Germany) GmbH

Benelux Office
Eindhoven, The Netherlands
Tel: 040-2445845
Fax: 040-2444580

NEC Electronics (France) S.A.

Velizy-Villacoublay, France
Tel: 01-30-67 58 00
Fax: 01-30-67 58 99

NEC Electronics (France) S.A.

Spain Office
Madrid, Spain
Tel: 01-504-2787
Fax: 01-504-2860

NEC Electronics (Germany) GmbH

Scandinavia Office
Taeby, Sweden
Tel: 08-63 80 820
Fax: 08-63 80 388

NEC Electronics Hong Kong Ltd.

Hong Kong
Tel: 2886-9318
Fax: 2886-9022/9044

NEC Electronics Hong Kong Ltd.

Seoul Branch
Seoul, Korea
Tel: 02-528-0303
Fax: 02-528-4411

NEC Electronics Singapore Pte. Ltd.

United Square, Singapore 1130
Tel: 253-8311
Fax: 250-3583

NEC Electronics Taiwan Ltd.

Taipei, Taiwan
Tel: 02-719-2377
Fax: 02-719-5951

NEC do Brasil S.A.

Cumbica-Guarulhos-SP, Brasil
Tel: 011-6465-6810
Fax: 011-6465-6829

Related documents V25, V35 User's Manual — Hardware IEM-1220
 V25, V35 Family User's Manual — Instructions U12120J (Japanese version)

The related documents indicated in this publication may include preliminary versions. However, preliminary versions are not marked as such.

V20, V25, V30, and V35 are trademarks of NEC Corporation.

No part of this document may be copied or reproduced in any form or by any means without the prior written consent of NEC Corporation. NEC Corporation assumes no responsibility for any errors which may appear in this document.

NEC Corporation does not assume any liability for infringement of patents, copyrights or other intellectual property rights of third parties by or arising from use of a device described herein or any other liability arising from use of such device. No license, either express, implied or otherwise, is granted under any patents, copyrights or other intellectual property rights of NEC Corporation or others.

While NEC Corporation has been making continuous effort to enhance the reliability of its semiconductor devices, the possibility of defects cannot be eliminated entirely. To minimize risks of damage or injury to persons or property arising from a defect in an NEC semiconductor device, customers must incorporate sufficient safety measures in its design, such as redundancy, fire-containment, and anti-failure features.

NEC devices are classified into the following three quality grades:

"Standard", "Special", and "Specific". The Specific quality grade applies only to devices developed based on a customer designated "quality assurance program" for a specific application. The recommended applications of a device depend on its quality grade, as indicated below. Customers must check the quality grade of each device before using it in a particular application.

Standard: Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots

Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)

Specific: Aircrafts, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.

The quality grade of NEC devices is "Standard" unless otherwise specified in NEC's Data Sheets or Data Books. If customers intend to use NEC devices for applications other than those specified for Standard quality grade, they should contact an NEC sales representative in advance.

Anti-radioactive design is not implemented in this product.